

TEST REPORT

FCC LTE B25(2) Test for SM-S721U
Certification

APPLICANT

SAMSUNG Electronics Co., Ltd.

REPORT NO.

HCT-RF-2407-FC025

DATE OF ISSUE

July 19, 2024

Tested by
Jae Ryang Do



Technical Manager
Jong Seok Lee



HCT CO., LTD.
Bongjai Huh
BongJai Huh / CEO



HCT CO.,LTD.

2-6, 73, 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, 17383 KOREA
Tel. +82 31 645 6300 Fax. +82 31 645 6401

TEST REPORT

REPORT NO.
HCT-RF-2407-FC025

DATE OF ISSUE
July 19, 2024

Additional Model
SM-S721U1

Applicant	SAMSUNG Electronics Co., Ltd. 129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea
Product Name	Mobile Phone
Model Name	SM-S721U
Date of Test	May 16, 2024 ~ July 19, 2024
FCC ID	A3LSMS721U
Location of Test	<input checked="" type="checkbox"/> Permanent Testing Lab <input type="checkbox"/> On Site Testing (Address: 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, 17383 Republic of Korea)
FCC Classification:	PCS Licensed Transmitter Held to Ear (PCE)
Test Standard Used	FCC Rule Part: § 24
Test Results	PASS

REVISION HISTORY

The revision history for this test report is shown in table.

Revision No.	Date of Issue	Description
0	July 19, 2024	Initial Release

Notice

Content

The measurements shown in this report were made in accordance with the procedures specified in CFR47 section § 2.947. I assume full responsibility for the accuracy and completeness of these measurements, and for the qualifications of all persons taking them.

HCT CO., LTD. Certifies that no party to this application has subject to a denial of Federal benefits that includes FCC benefits pursuant to section 5301 of the Anti-Drug Abuse Act of 1998,21 U.S. C.853(a)

The results shown in this test report only apply to the sample(s), as received, provided by the applicant, unless otherwise stated.

The test results have only been applied with the test methods required by the standard(s).

The laboratory is not accredited for the test results marked *.

Information provided by the applicant is marked **.

Test results provided by external providers are marked ***.

When confirmation of authenticity of this test report is required, please contact www.hct.co.kr

The test results in this test report are not associated with the ((KS Q) ISO/IEC 17025) accreditation by KOLAS (Korea Laboratory Accreditation Scheme) / A2LA (American Association for Laboratory Accreditation) that are under the ILAC (International Laboratory Accreditation Cooperation) Mutual Recognition Agreement (MRA).

CONTENTS

1. GENERAL INFORMATION	5
1.1. MAXIMUM OUTPUT POWER	6
2. INTRODUCTION	8
2.1. DESCRIPTION OF EUT.....	8
2.2. MEASURING INSTRUMENT CALIBRATION	8
2.3. TEST FACILITY	8
3. DESCRIPTION OF TESTS	9
3.1 TEST PROCEDURE	9
3.2 RADIATED POWER.....	10
3.3 RADIATED SPURIOUS EMISSIONS.....	11
3.4 PEAK- TO- AVERAGE RATIO	12
3.5 OCCUPIED BANDWIDTH.....	14
3.6 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL.....	15
3.7 BAND EDGE	16
3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE	18
3.9 WORST CASE(RADIATED TEST)	19
3.10 WORST CASE(CONDUCTED TEST).....	20
4. LIST OF TEST EQUIPMENT.....	21
5. MEASUREMENT UNCERTAINTY.....	22
6. SUMMARY OF TEST RESULTS	23
7. SAMPLE CALCULATION	24
8. TEST DATA(Main 1 Ant).....	26
8.1 EQUIVALENT ISOTROPIC RADIATED POWER.....	26
8.2 RADIATED SPURIOUS EMISSIONS.....	29
8.3 PEAK-TO-AVERAGE RATIO	30
8.4 OCCUPIED BANDWIDTH.....	31
8.5 CONDUCTED SPURIOUS EMISSIONS	32
8.6 BAND EDGE	32
8.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE	33
9. TEST DATA(Sub 5 Ant)	51
9.1 EQUIVALENT ISOTROPIC RADIATED POWER.....	51
9.2 RADIATED SPURIOUS EMISSIONS.....	54
9.3 PEAK-TO-AVERAGE RATIO	55
9.4 OCCUPIED BANDWIDTH.....	56
9.5 CONDUCTED SPURIOUS EMISSIONS	57
9.6 BAND EDGE	57
9.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE	58
10. TEST PLOTS(Main 1 Ant).....	76
11. TEST PLOTS(Sub 5 Ant)	197
12. ANNEX A_ TEST SETUP PHOTO	318

MEASUREMENT REPORT**1. GENERAL INFORMATION**

Applicant Name:	SAMSUNG Electronics Co., Ltd.
Address:	129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea
FCC ID:	A3LSMS721U
Application Type:	Certification
FCC Classification:	PCS Licensed Transmitter Held to Ear (PCE)
FCC Rule Part(s):	§ 24
EUT Type:	Mobile phone
Model(s):	SM-S721U
Additional Model(s)	SM-S721U1
Tx Frequency:	1850.7 MHz – 1914.3 MHz (LTE – Band25/2 (1.4 MHz)) 1851.5 MHz – 1913.5 MHz (LTE – Band25/2 (3 MHz)) 1852.5 MHz – 1912.5 MHz (LTE – Band25/2 (5 MHz)) 1855.0 MHz – 1910.0 MHz (LTE – Band25/2 (10 MHz)) 1857.5 MHz – 1907.5 MHz (LTE – Band25/2 (15 MHz)) 1860.0 MHz – 1905.0 MHz (LTE – Band25/2 (20 MHz))
Date(s) of Tests:	May 16, 2024 ~ July 19, 2024
Serial number:	Radiated : R3CX506M1WK(ANT A), 67d50ecc63197ece(ANT F) Conducted : R3CX40SV75R

1.1. MAXIMUM OUTPUT POWER

Main 1 Ant (Antenna A)

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band25/2 (1.4)	1850.7 - 1914.3	1M09G7D	QPSK	0.111	20.46
		1M10W7D	16QAM	0.094	19.73
		1M10W7D	64QAM	0.074	18.70
		1M10W7D	256QAM	0.037	15.65
LTE – Band25/2 (3)	1851.5 - 1913.5	2M72G7D	QPSK	0.113	20.51
		2M71W7D	16QAM	0.095	19.79
		2M72W7D	64QAM	0.076	18.78
		2M71W7D	256QAM	0.038	15.75
LTE – Band25/2 (5)	1852.5 - 1912.5	4M52G7D	QPSK	0.114	20.57
		4M53W7D	16QAM	0.095	19.77
		4M53W7D	64QAM	0.076	18.83
		4M52W7D	256QAM	0.038	15.81
LTE – Band25/2 (10)	1855.0 - 1910.0	9M02G7D	QPSK	0.114	20.58
		9M04W7D	16QAM	0.093	19.67
		9M05W7D	64QAM	0.075	18.73
		9M01W7D	256QAM	0.038	15.77
LTE – Band25/2 (15)	1857.5 - 1907.5	13M5G7D	QPSK	0.116	20.66
		13M5W7D	16QAM	0.096	19.82
		13M5W7D	64QAM	0.077	18.85
		13M5W7D	256QAM	0.039	15.88
LTE – Band25/2 (20)	1860.0 - 1905.0	18M0G7D	QPSK	0.116	20.63
		18M0W7D	16QAM	0.095	19.79
		17M9W7D	64QAM	0.075	18.77
		18M0W7D	256QAM	0.039	15.89

Sub 5 Ant (Antenna F)

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band25/2 (1.4)	1850.7 - 1914.3	1M10G7D	QPSK	0.147	21.67
		1M10W7D	16QAM	0.121	20.82
		1M11W7D	64QAM	0.096	19.83
		1M10W7D	256QAM	0.045	16.56
LTE – Band25/2 (3)	1851.5 - 1913.5	2M72G7D	QPSK	0.147	21.68
		2M73W7D	16QAM	0.121	20.83
		2M71W7D	64QAM	0.098	19.90
		2M72W7D	256QAM	0.047	16.72
LTE – Band25/2 (5)	1852.5 - 1912.5	4M54G7D	QPSK	0.150	21.75
		4M54W7D	16QAM	0.125	20.97
		4M52W7D	64QAM	0.099	19.94
		4M51W7D	256QAM	0.046	16.67
LTE – Band25/2 (10)	1855.0 - 1910.0	9M04G7D	QPSK	0.146	21.63
		9M04W7D	16QAM	0.118	20.72
		9M03W7D	64QAM	0.093	19.70
		9M02W7D	256QAM	0.045	16.55
LTE – Band25/2 (15)	1857.5 - 1907.5	13M5G7D	QPSK	0.151	21.78
		13M5W7D	16QAM	0.126	21.02
		13M5W7D	64QAM	0.098	19.90
		13M5W7D	256QAM	0.047	16.76
LTE – Band25/2 (20)	1860.0 - 1905.0	18M0G7D	QPSK	0.149	21.73
		18M0W7D	16QAM	0.122	20.86
		18M0W7D	64QAM	0.095	19.78
		18M0W7D	256QAM	0.047	16.73

2. INTRODUCTION

2.1. DESCRIPTION OF EUT

The EUT was a Mobile Phone with GSM/GPRS/EGPRS/UMTS and LTE, Sub 6, mmWave. It also supports IEEE 802.11 a/b/g/n/ac/ax (20/40/80/160 MHz), Bluetooth(iPA, ePA), BT LE(iPA, ePA), NFC, WPT, WIFI 6E.

2.2. MEASURING INSTRUMENT CALIBRATION

The measuring equipment, which was utilized in performing the tests documented herein, has been calibrated in accordance with the manufacturer's recommendations for utilizing calibration equipment, which is traceable to recognized national standards.

2.3. TEST FACILITY

The Fully-anechoic chamber and conducted measurement facility used to collect the radiated data are located at the **74, Seocheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, 17383, Rep. of KOREA.**

3. DESCRIPTION OF TESTS

3.1 TEST PROCEDURE

Test Description	Test Procedure Used
Occupied Bandwidth	- KDB 971168 D01 v03r01 – Section 4.3 - ANSI C63.26-2015 – Section 5.4.4
Band Edge	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Spurious and Harmonic Emissions at Antenna Terminal	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Conducted Output Power	- N/A (See SAR Report)
Peak- to- Average Ratio	- KDB 971168 D01 v03r01 – Section 5.7 - ANSI C63.26-2015 – Section 5.2.3.4
Frequency stability	- ANSI C63.26-2015 – Section 5.6
Effective Radiated Power/ Effective Isotropic Radiated Power	- KDB 971168 D01 v03r01 – Section 5.2 & 5.8 - ANSI/TIA-603-E-2016 – Section 2.2.17
Radiated Spurious and Harmonic Emissions	- KDB 971168 D01 v03r01 – Section 6.2 - ANSI/TIA-603-E-2016 – Section 2.2.12

3.2 RADIATED POWER

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

The equipment under test is placed on a non-conductive table 3-meters away from the receive antenna in accordance with ANSI/TIA-603-E-2016 Clause 2.2.17.

Test Settings

1. Radiated power measurements are performed using the signal analyzer's "channel power" measurement capability for signals with continuous operation.
2. RBW = 1 – 5 % of the expected OBW, not to exceed 1 MHz
3. VBW \geq 3 x RBW
4. Span = 1.5 times the OBW
5. No. of sweep points > 2 x span / RBW
6. Detector = RMS
7. Trigger is set to "free run" for signals with continuous operation with the sweep times set to "auto".
8. The integration bandwidth was roughly set equal to the measured OBW of the signal for signals with continuous operation.
9. Trace mode = trace averaging (RMS) over 100 sweeps
10. The trace was allowed to stabilize

Test Note

1. The turntable is rotated through 360 degrees, and the receiving antenna scans in order to determine the level of the maximized emission.
2. A half wave dipole is then substituted in place of the EUT. For emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The power is calculated by the following formula;

$$P_d \text{ (dBm)} = P_g \text{ (dBm)} - \text{cable loss (dB)} + \text{antenna gain (dB)}$$

Where: P_d is the dipole equivalent power and P_g is the generator output power into the substitution antenna.

3. The maximum value is calculated by adding the forward power to the calibrated source plus its appropriate gain value.

These steps are repeated with the receiving antenna in both vertical and horizontal polarization. the difference between the gain of the horn and an isotropic antenna are taken into consideration

4. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
5. All measurements are performed as RMS average measurements while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies.

3.3 RADIATED SPURIOUS EMISSIONS

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

Radiated Spurious Emission Measurements at 3 meters by Substitution Method according to ANSI/TIA-603-E-2016.

Test Settings

1. RBW = 100 kHz for emissions below 1 GHz and 1 MHz for emissions above 1 GHz
2. VBW \geq 3 x RBW
3. Span = 1.5 times the OBW
4. No. of sweep points > 2 x span / RBW
5. Detector = Peak
6. Trace mode = Max Hold
7. The trace was allowed to stabilize
8. Test channel : Low/ Middle/ High
9. Frequency range : We are performed all frequency to 10th harmonics from 9 kHz.

Test Note

1. Measurements value show only up to 3 maximum emissions noted, or would be lesser if no specific emissions from the EUT are recorded (ie: margin > 20 dB from the applicable limit) and considered that's already beyond the background noise floor.
2. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning. The worst case emissions are reported with the EUT positioning, modulations, RB sizes and offsets, and channel bandwidth configurations shown in the test data
3. For spurious emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.
The spurious emissions is calculated by the following formula;

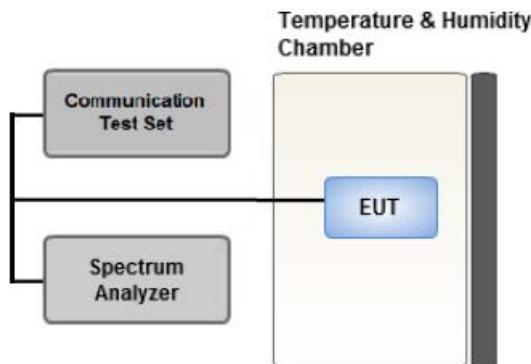
$$\text{Result } (\text{dBm}) = P_g \text{ (dBm)} - \text{cable loss } (\text{dB}) + \text{antenna gain } (\text{dBi})$$

Where: P_g is the generator output power into the substitution antenna.

If the fundamental frequency is below 1 GHz, RF output power has been converted to EIRP.

$$\text{EIRP } (\text{dBm}) = \text{ERP } (\text{dBm}) + 2.15$$

3.4 PEAK- TO- AVERAGE RATIO



Test setup

① CCDF Procedure for PAPR

Test Settings

1. Set resolution/measurement bandwidth \geq signal's occupied bandwidth;
2. Set the number of counts to a value that stabilizes the measured CCDF curve;
3. Set the measurement interval as follows:
 - .- for continuous transmissions, set to 1 ms,
 - .- or burst transmissions, employ an external trigger that is synchronized with the EUT burst timing sequence, or use the internal burst trigger with a trigger level that allows the burst to stabilize and set the measurement interval to a time that is less than or equal to the burst duration.
4. Record the maximum PAPR level associated with a probability of 0.1 %.

② Alternate Procedure for PAPR

Use one of the procedures presented in 5.2(ANSI C63.26-2015) to measure the total peak power and record as P_{Pk} .

Use one of the applicable procedures presented 5.2(ANSI C63.26-2015) to measure the total average power and record as P_{Avg} . Determine the P.A.R. from:

$$P.A.R \text{ (dB)} = P_{Pk \text{ (dBm)}} - P_{Avg \text{ (dBm)}} \quad (P_{Avg} = \text{Average Power} + \text{Duty cycle Factor})$$

Test Settings(Peak Power)

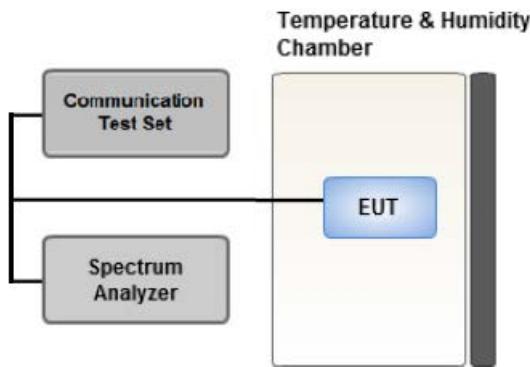
The measurement instrument must have a RBW that is greater than or equal to the OBW of the signal to be measured and a VBW $\geq 3 \times$ RBW.

1. Set the RBW \geq OBW.
2. Set VBW $\geq 3 \times$ RBW.
3. Set span $\geq 2 \times$ OBW.
4. Sweep time $\geq 10 \times (\text{number of points in sweep}) \times (\text{transmission symbol period})$.
5. Detector = peak.
6. Trace mode = max hold.
7. Allow trace to fully stabilize.
8. Use the peak marker function to determine the peak amplitude level.

Test Settings(Average Power)

1. Set span to $2 \times$ to $3 \times$ the OBW.
2. Set RBW \geq OBW.
3. Set VBW $\geq 3 \times$ RBW.
4. Set number of measurement points in sweep $\geq 2 \times$ span / RBW.
5. Sweep time:
Set $\geq [10 \times (\text{number of points in sweep}) \times (\text{transmission period})]$ for single sweep
(automation-compatible) measurement. The transmission period is the (on + off) time.
6. Detector = power averaging (rms).
7. Set sweep trigger to “free run.”
8. Trace average at least 100 traces in power averaging (rms) mode if sweep is set to auto-couple. (To accurately determine the average power over the on and off period of the transmitter, it can be necessary to increase the number of traces to be averaged above 100 or, if using a manually configured sweep time, increase the sweep time.)
9. Use the peak marker function to determine the maximum amplitude level.
10. Add $[10 \log (1/\text{duty cycle})]$ to the measured maximum power level to compute the average power during continuous transmission. For example, add $[10 \log (1/0.25)] = 6 \text{ dB}$ if the duty cycle is a constant 25 %.

3.5 OCCUPIED BANDWIDTH.



Test setup

The width of a frequency band such that, below the lower and above the upper frequency limits, the mean powers emitted are each equal to a specified percentage 0.5 % of the total mean power of a given emission.

The EUT makes a call to the communication simulator.

The conducted occupied bandwidth used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

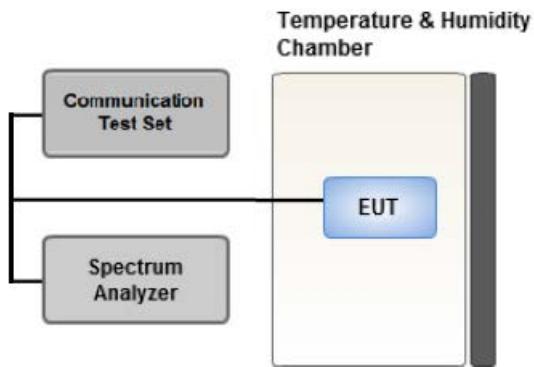
The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency.

Use OBW measurement function of Spectrum analyzer to measure 99 % occupied bandwidth

Test Settings

1. The signal analyzer's automatic bandwidth measurement capability was used to perform the 99 % occupied bandwidth and the 26 dB bandwidth. The bandwidth measurement was not influenced by any intermediate power nulls in the fundamental emission.
2. RBW = 1 – 5 % of the expected OBW
3. VBW \geq 3 x RBW
4. Detector = Peak
5. Trace mode = max hold
6. Sweep = auto couple
7. The trace was allowed to stabilize
8. If necessary, steps 2 – 7 were repeated after changing the RBW such that it would be within 1 – 5 % of the 99 % occupied bandwidth observed in Step 7

3.6 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL



Test setup

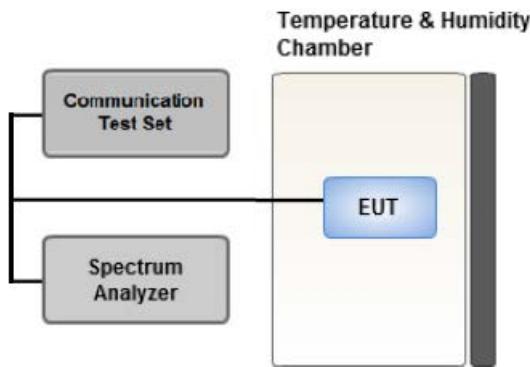
Test Overview

The level of the carrier and the various conducted spurious and harmonic frequencies is measured by means of a calibrated spectrum analyzer. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. RBW = 1 MHz
2. VBW \geq 3 MHz
3. Detector = RMS
4. Trace Mode = trace average
5. Sweep time = auto
6. Number of points in sweep \geq 2 x Span / RBW

3.7 BAND EDGE



Test setup

Test Overview

All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. Start and stop frequency were set such that the band edge would be placed in the center of the plot
2. Span was set large enough so as to capture all out of band emissions near the band edge
3. RBW > 1 % of the emission bandwidth
4. VBW > 3 x RBW
5. Detector = RMS
6. Number of sweep points $\geq 2 \times \text{Span}/\text{RBW}$
7. Trace mode = trace average
8. Sweep time = auto couple
9. The trace was allowed to stabilize

Test Notes

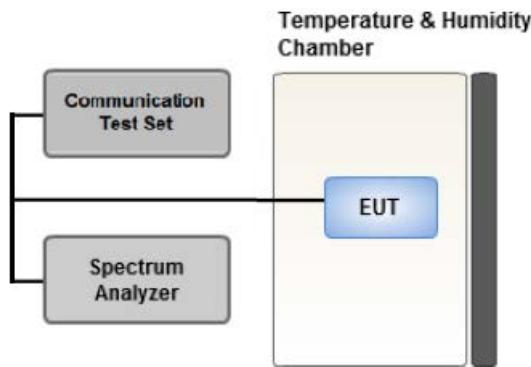
According to FCC 22.917, 24.238, 27.53 specified that power of any emission outside of The authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least $43 + 10 \log(P)$ dB. In the 1 MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed.

All measurements were done at 2 channels(low and high operational frequency range.)

The band edge measurement used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

Where Margin < 1 dB the emission level is either corrected by $10 \log(1 \text{ MHz} / \text{RB})$ or the emission is integrated over a 1 MHz bandwidth to determine the final result. When using the integration method the integration window is either centered on the emission or, for emissions at the band edge, centered by an offset of 500 kHz from the block edge so that the integration window is the 1 MHz adjacent to the block edge.

3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE



Test setup

Test Overview

Frequency stability testing is performed in accordance with the guidelines of ANSI C63.26-2015.

The frequency stability of the transmitter is measured by:

1. Temperature:

The temperature is varied from -30 °C to +50 °C in 10 °C increments using an environmental chamber.

2. Primary Supply Voltage:

- .- Unless otherwise specified, vary primary supply voltage from 85 % to 115 % of the nominal value for other than hand carried battery equipment.
- .- For hand carried, battery powered equipment, reduce the primary ac or dc supply voltage to the battery operating end point, which shall be specified by the manufacturer.

Test Settings

1. The carrier frequency of the transmitter is measured at room temperature (20 °C to provide a reference).

2. The equipment is turned on in a “standby” condition for fifteen minutes before applying power to the transmitter.

Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.

3. Frequency measurements are made at 10 °C intervals ranging from -30 °C to +50 °C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

3.9 WORST CASE(RADIATED TEST)

- The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
- In the case of radiated spurious emissions, all bandwidth of operation were investigated and the worst case bandwidth results are reported. (Worst case : 15 MHz(Main 1 Ant), 15 MHz(Sub 5 Ant))
- The worst case is reported with the EUT positioning, modulations, and paging service configurations shown in the test data.
- Please refer to the table below.
- LTE BAND 25 (1850 – 1915 MHz) overlaps the entire frequency range of LTE BAND 2 (1850 - 1910 MHz) and they have the same Tune-up power.

Therefore, test data provided in this report covers BAND 2 as well as BAND 25.

- All modes of operation were investigated and the worst case configuration results are reported.

Mode : Stand alone, Stand alone + External accessories (Earphone, AC adapter, etc)

Worst case : Stand alone

- All simultaneous transmission scenarios of operation were investigated, and the test results showed no additional significant emissions relative to the least restrictive limit were observed.

Therefore, only the worst case(stand-alone) results were reported.

- SM-S721U & additional models were tested and the worst case results are reported.

(Worst case : SM-S721U)

[Main 1 Ant Worst case] (ANT A)

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 8.1		Z
Radiated Spurious and Harmonic Emissions	QPSK	See Section 8.2		X

[Sub 5 Ant Worst case] (ANT F)

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 9.1		X
Radiated Spurious and Harmonic Emissions	QPSK	See Section 9.2		Y

3.10 WORST CASE(CONDUCTED TEST)

- All modes of operation were investigated and the worst case configuration results are reported.
- LTE BAND 25 (1850 – 1915 MHz) overlaps the entire frequency range of LTE BAND 2 (1850 - 1910 MHz) and they have the same Tune-up power.
Therefore, test data provided in this report covers BAND 2 as well as BAND 25.
- SM-S721U & additional models were tested and the worst case results are reported.
(Worst case : SM-S721U)

[Worst case]

Test Description	Modulation	Bandwidth (MHz)	Frequency	RB size	RB offset
Occupied Bandwidth	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Peak-To-Average Ratio	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Band Edge	QPSK	1.4	Low	1	0
		1.4	High	1	5
		3	Low	1	0
		3	High	1	14
		5	Low	1	0
		5	High	1	24
		10	Low	1	0
		10	High	1	49
		15	Low	1	0
		15	High	1	74
		20	Low	1	0
		20	High	1	99
		1.4, 3, 5, 10, 15, 20	Low, High	Full RB	0
Spurious and Harmonic Emissions at Antenna Terminal	QPSK	1.4, 3, 5, 10, 15, 20	Low, Mid, High	1	0

4. LIST OF TEST EQUIPMENT

Equipment	Model	Manufacture	Serial No.	Due to Calibration	Calibration Interval
RF Switching System	FBSR-02B(1.2G HPF+LNA)	T&M SYSTEM	F1L1	12/11/2024	Annual
RF Switching System	FBSR-02B(3.3G HPF+LNA)	T&M SYSTEM	F1L2	12/11/2024	Annual
Power Splitter(DC ~ 26.5 GHz)	11667B	Hewlett Packard	5001	04/17/2025	Annual
DC Power Supply	E3632A	Agilent	KR01009150	04/18/2025	Annual
Dipole Antenna	UHAP	Schwarzbeck	557	03/09/2025	Biennial
Dipole Antenna	UHAP	Schwarzbeck	558	03/09/2025	Biennial
Chamber	SU-642	ESPEC	93008124	02/19/2025	Annual
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	147	08/17/2025	Biennial
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	9120D-1298	09/11/2025	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170342	09/29/2024	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170124	03/28/2025	Biennial
Signal Analyzer(10 Hz ~ 26.5 GHz)	N9020A	Agilent	MY52090906	04/19/2025	Annual
ATTENUATOR(20 dB)	8493C	Hewlett Packard	17280	04/17/2025	Annual
Spectrum Analyzer(10 Hz ~ 40 GHz)	FSV40	REOHDE & SCHWARZ	100931	08/17/2024	Annual
Base Station	8960 (E5515C)	Agilent	MY48360800	08/10/2024	Annual
Loop Antenna(9 kHz ~ 30 MHz)	FMZB1513	Schwarzbeck	1513-333	03/07/2026	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	895	09/16/2024	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	1135	09/16/2024	Biennial
Wideband Radio Communication Tester	MT8821C	Anritsu Corp.	6262094331	11/17/2024	Annual
Wideband Radio Communication Tester	MT8820C	Anritsu Corp.	6201026545	12/11/2024	Annual
SIGNAL GENERATOR (100 kHz ~ 40 GHz)	SMW200A	REOHDE & SCHWARZ	100988	02/26/2025	Annual
Signal Analyzer(5 Hz ~ 40.0 GHz)	N9030B	KEYSIGHT	MY55480167	05/17/2025	Annual
FCC LTE Mobile Conducted RF Automation Test Software	-	HCT CO., LTD.,	-	-	-

Note:

1. Equipment listed above that has a calibration due date during the testing period, the testing is completed before equipment expiration date.
2. Especially, all antenna for measurement is calibrated in accordance with the requirements of C63.5 (Version : 2017).

5. MEASUREMENT UNCERTAINTY

The measurement uncertainties shown below were calculated in accordance with the requirements of ANSI C63.4:2014.

All measurement uncertainty values are shown with a coverage factor of $k=2$ to indicate a 95 % level of confidence. The measurement data shown herein meets or exceeds the U_{CISPR} measurement uncertainty values specified in CISPR 16-4-2 and, thus, can be compared directly to specified limits to determine compliance.

Parameter	Expanded Uncertainty (\pm dB)
Conducted Disturbance (150 kHz ~ 30 MHz)	1.98 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (9 kHz ~ 30 MHz)	4.36 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (30 MHz ~ 1 GHz)	5.70 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (1 GHz ~ 18 GHz)	5.52 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (18 GHz ~ 40 GHz)	5.66 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (Above 40 GHz)	5.58 (Confidence level about 95 %, $k=2$)

6. SUMMARY OF TEST RESULTS

6.1 Test Condition: Conducted Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Occupied Bandwidth	§ 2.1049	N/A	PASS
Band Edge / Spurious and Harmonic Emissions at Antenna Terminal.	§ 2.1051, § 24.238(a)	< 43 + 10log10 (P[Watts]) at Band Edge and for all out-of-band emissions	PASS
Conducted Output Power	§ 2.1046	N/A	<u>See Note1</u>
Peak- to- Average Ratio	§ 24.232(d)	< 13 dB	PASS
Frequency stability / variation of ambient temperature	§ 24.235	Emission must remain in band	PASS

Note:

1. See SAR Report

6.2 Test Condition: Radiated Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Equivalent Isotropic Radiated Power	§ 24.232(c)	< 2 Watts max. EIRP	PASS
Radiated Spurious and Harmonic Emissions	§ 2.1053, § 24.238(a)	< 43 + 10log10 (P[Watts]) for all out-of band emissions	PASS

7. SAMPLE CALCULATION

7.1 ERP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol.	ERP	
channel	Freq.(MHz)						W	dBm
128	824.20	-21.37	38.40	-10.61	0.95	H	0.483	26.84

$$\text{ERP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of effective radiated power.

7.2 EIRP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol.	EIRP	
channel	Freq.(MHz)						W	dBm
20175	1,732.50	-15.75	18.45	9.90	1.76	H	0.456	26.59

$$\text{EIRP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of equivalent isotropic radiated power.

7.3. Emission Designator

GSM Emission Designator

Emission Designator = 249KGXW

GSM BW = 249 kHz

G = Phase Modulation

X = Cases not otherwise covered

W = Combination (Audio/Data)

EDGE Emission Designator

Emission Designator = 249KG7W

GSM BW = 249 kHz

G = Phase Modulation

7 = Quantized/Digital Info

W = Combination (Audio/Data)

WCDMA Emission Designator

Emission Designator = 4M17F9W

WCDMA BW = 4.17 MHz

F = Frequency Modulation

9 = Composite Digital Info

W = Combination (Audio/Data)

QPSK Modulation

Emission Designator = 4M48G7D

LTE BW = 4.48 MHz

G = Phase Modulation

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

QAM Modulation

Emission Designator = 4M48W7D

LTE BW = 4.48 MHz

W = Amplitude/Angle Modulated

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

8. TEST DATA(Main 1 Ant)

8.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L.	Pol	Limit	EIRP		RB		
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset	
1850.7	LTE B25/B2 1.4 MHz	QPSK	-22.02	11.87	10.31	2.30	V	< 2.00	0.097	19.88	1	0	
		16-QAM	-22.88	11.01	10.31	2.30	V		0.080	19.02			
		64-QAM	-23.83	10.06	10.31	2.30	V		0.064	18.07			
		256-QAM	-26.85	7.04	10.31	2.30	V		0.032	15.05			
1882.5		QPSK	-22.26	12.44	10.35	2.33	V	< 2.00	0.111	20.46	1	0	
		16-QAM	-22.99	11.71	10.35	2.33	V		0.094	19.73			
		64-QAM	-24.02	10.68	10.35	2.33	V		0.074	18.70			
		256-QAM	-27.07	7.63	10.35	2.33	V		0.037	15.65			
1914.3		QPSK	-22.37	11.73	10.41	2.29	V	< 2.00	0.097	19.85	1	0	
		16-QAM	-23.25	10.85	10.41	2.29	V		0.079	18.97			
		64-QAM	-24.21	9.89	10.41	2.29	V		0.063	18.01			
		256-QAM	-27.14	6.96	10.41	2.29	V		0.032	15.08			

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L.	Pol	Limit	EIRP		RB		
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset	
1851.5	LTE B25/B2 3 MHz	QPSK	-22.09	11.80	10.31	2.30	V	< 2.00	0.096	19.81	1	0	
		16-QAM	-22.82	11.07	10.31	2.30	V		0.081	19.08			
		64-QAM	-23.79	10.10	10.31	2.30	V		0.065	18.11			
		256-QAM	-26.83	7.06	10.31	2.30	V		0.032	15.07			
1882.5		QPSK	-22.21	12.49	10.35	2.33	V	< 2.00	0.112	20.51	1	0	
		16-QAM	-22.93	11.77	10.35	2.33	V		0.095	19.79			
		64-QAM	-23.94	10.76	10.35	2.33	V		0.076	18.78			
		256-QAM	-26.97	7.73	10.35	2.33	V		0.038	15.75			
1913.5		QPSK	-22.22	11.88	10.41	2.29	V	< 2.00	0.100	20.00	1	0	
		16-QAM	-22.99	11.11	10.41	2.29	V		0.084	19.23			
		64-QAM	-23.97	10.13	10.41	2.29	V		0.067	18.25			
		256-QAM	-26.90	7.20	10.41	2.29	V		0.034	15.32			

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1852.5	LTE B25/B2 5 MHz	QPSK	-22.03	11.86	10.31	2.30	V	< 2.00	0.097	19.87	1	0
		16-QAM	-22.88	11.01	10.31	2.30	V		0.080	19.02		
		64-QAM	-23.87	10.02	10.31	2.30	V		0.064	18.03		
		256-QAM	-26.84	7.05	10.31	2.30	V		0.032	15.06		
		QPSK	-22.15	12.55	10.35	2.33	V	< 2.00	0.114	20.57	1	0
		16-QAM	-22.95	11.75	10.35	2.33	V		0.095	19.77		
		64-QAM	-23.89	10.81	10.35	2.33	V		0.076	18.83		
		256-QAM	-26.91	7.79	10.35	2.33	V		0.038	15.81		
		QPSK	-22.38	11.66	10.40	2.29	V	< 2.00	0.095	19.77	1	0
		16-QAM	-23.15	10.88	10.41	2.29	V		0.079	19.00		
		64-QAM	-24.26	9.77	10.41	2.29	V		0.062	17.89		
		256-QAM	-27.13	6.90	10.41	2.29	V		0.032	15.02		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1855.0	LTE B25/B2 10 MHz	QPSK	-22.15	11.71	10.41	2.29	V	< 2.00	0.096	19.83	1	0
		16-QAM	-22.99	10.92	10.32	2.25	V		0.079	18.99		
		64-QAM	-23.95	9.96	10.32	2.25	V		0.064	18.03		
		256-QAM	-26.94	6.97	10.32	2.25	V		0.032	15.04		
		QPSK	-22.14	12.56	10.35	2.33	V	< 2.00	0.114	20.58	1	0
		16-QAM	-23.05	11.65	10.35	2.33	V		0.093	19.67		
		64-QAM	-23.99	10.71	10.35	2.33	V		0.075	18.73		
		256-QAM	-26.95	7.75	10.35	2.33	V		0.038	15.77		
		QPSK	-21.99	12.04	10.41	2.29	V	< 2.00	0.104	20.16	1	0
		16-QAM	-22.88	11.15	10.41	2.29	V		0.085	19.27		
		64-QAM	-23.85	10.18	10.41	2.29	V		0.068	18.30		
		256-QAM	-26.76	7.27	10.41	2.29	V		0.035	15.39		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1857.5	LTE B25/B2 15 MHz	QPSK	-22.08	11.92	10.32	2.26	V	< 2.00	0.100	19.98	1	0
		16-QAM	-22.89	11.11	10.32	2.26	V		0.083	19.17		
		64-QAM	-23.92	10.08	10.32	2.26	V		0.065	18.14		
		256-QAM	-26.86	7.14	10.32	2.26	V		0.033	15.20		
		QPSK	-22.06	12.64	10.35	2.33	V	< 2.00	0.116	20.66	1	0
		16-QAM	-22.90	11.80	10.35	2.33	V		0.096	19.82		
		64-QAM	-23.87	10.83	10.35	2.33	V		0.077	18.85		
		256-QAM	-26.84	7.86	10.35	2.33	V		0.039	15.88		
		QPSK	-22.11	11.92	10.41	2.29	V	< 2.00	0.101	20.04	1	0
		16-QAM	-22.92	11.11	10.41	2.29	V		0.084	19.23		
		64-QAM	-23.93	10.10	10.41	2.29	V		0.066	18.22		
		256-QAM	-26.87	7.16	10.41	2.29	V		0.034	15.28		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1860.0	LTE B25/B2 20 MHz	QPSK	-22.11	11.89	10.32	2.26	V	< 2.00	0.099	19.95	1	0
		16-QAM	-22.95	11.05	10.32	2.26	V		0.081	19.11		
		64-QAM	-23.96	10.04	10.32	2.26	V		0.065	18.10		
		256-QAM	-26.85	7.15	10.32	2.26	V		0.033	15.21		
		QPSK	-22.09	12.61	10.35	2.33	V	< 2.00	0.116	20.63	1	0
		16-QAM	-22.93	11.77	10.35	2.33	V		0.095	19.79		
		64-QAM	-23.95	10.75	10.35	2.33	V		0.075	18.77		
		256-QAM	-26.83	7.87	10.35	2.33	V		0.039	15.89		
		QPSK	-22.28	11.87	10.39	2.30	V	< 2.00	0.099	19.97	1	0
		16-QAM	-23.09	11.06	10.39	2.30	V		0.082	19.16		
		64-QAM	-24.17	9.98	10.39	2.30	V		0.064	18.08		
		256-QAM	-27.01	7.14	10.39	2.30	V		0.033	15.24		

8.2 RADIATED SPURIOUS EMISSIONS

- OPERATING FREQUENCY: 1882.5 MHz
- MEASURED OUTPUT POWER: 20.66 dBm = 0.116 W
- MOD: LTE B25/B2
- MODULATION SIGNAL: 15 MHz QPSK
- DISTANCE: 3 meters
- LIMIT: $43 + 10 \log_{10} (W) =$ 33.66 dBc

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	dBc	RB	
									Size	Offset
26115 (1857.5)	3 715.00	-42.34	12.28	-47.25	3.20	H	-38.17	58.83	1	0
	5 572.50	-51.89	13.06	-50.03	3.93	H	-40.90	61.56		
	7 430.00	-57.43	10.78	-46.86	4.69	V	-40.77	61.43		
26365 (1882.5)	3 765.00	-43.85	12.22	-48.38	3.26	H	-39.42	60.08	1	0
	5 647.50	-55.22	13.12	-53.27	4.03	H	-44.18	64.84		
	7 530.00	-57.33	10.85	-46.62	4.72	H	-40.49	61.15		
26615 (1907.5)	3 815.00	-44.44	12.16	-49.29	3.25	V	-40.38	61.04	1	0
	5 722.50	-56.58	13.06	-53.93	4.15	V	-45.02	65.68		
	7 630.00	-58.28	11.18	-48.12	4.74	V	-41.68	62.34		

8.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)	
25/2	1.4 MHz	1882.5	QPSK	6	0	5.32	
			16-QAM	6	0	5.75	
			64-QAM	6	0	6.07	
			256-QAM	6	0	6.68	
	3 MHz		QPSK	15	0	5.34	
			16-QAM	15	0	5.89	
			64-QAM	15	0	6.06	
			256-QAM	15	0	6.60	
	5 MHz		QPSK	25	0	5.35	
			16-QAM	25	0	5.94	
			64-QAM	25	0	6.08	
			256-QAM	25	0	6.54	
	10 MHz		QPSK	50	0	5.48	
			16-QAM	50	0	5.91	
			64-QAM	50	0	6.12	
			256-QAM	50	0	6.57	
	15 MHz		QPSK	75	0	5.35	
			16-QAM	75	0	5.85	
			64-QAM	75	0	6.12	
			256-QAM	75	0	6.58	
	20 MHz		QPSK	100	0	5.36	
			16-QAM	100	0	5.87	
			64-QAM	100	0	6.09	
			256-QAM	100	0	6.58	

Note:

- Plots of the EUT's Peak- to- Average Ratio are shown Page 77 ~ 100.

8.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)	
25/2	1.4 MHz	1882.5	QPSK	6	0	1.0930	
			16-QAM	6	0	1.0989	
			64-QAM	6	0	1.0996	
			256-QAM	6	0	1.1011	
	3 MHz		QPSK	15	0	2.7191	
			16-QAM	15	0	2.7122	
			64-QAM	15	0	2.7177	
			256-QAM	15	0	2.7141	
	5 MHz		QPSK	25	0	4.5219	
			16-QAM	25	0	4.5323	
			64-QAM	25	0	4.5247	
			256-QAM	25	0	4.5242	
	10 MHz		QPSK	50	0	9.0165	
			16-QAM	50	0	9.0368	
			64-QAM	50	0	9.0528	
			256-QAM	50	0	9.0114	
	15 MHz		QPSK	75	0	13.483	
			16-QAM	75	0	13.491	
			64-QAM	75	0	13.496	
			256-QAM	75	0	13.459	
	20 MHz		QPSK	100	0	17.956	
			16-QAM	100	0	17.946	
			64-QAM	100	0	17.892	
			256-QAM	100	0	17.952	

Note:

- Plots of the EUT's Occupied Bandwidth are shown Page 101 ~ 124.

8.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
25/2	1.4	3.6790	3.6965	27.976	-67.007	-39.031	
		3.6790	3.7099	27.976	-67.229	-39.253	
		3.6780	3.7129	27.976	-67.486	-39.510	
	3	3.6815	3.7044	27.976	-67.310	-39.334	
		3.7114	3.7099	27.976	-67.490	-39.514	
		3.6885	3.7304	27.976	-67.226	-39.250	
	5	3.7194	3.6960	27.976	-67.242	-39.266	
		3.7114	3.7089	27.976	-67.071	-39.095	
		3.6850	3.6780	27.976	-67.179	-39.203	
	10	3.7189	3.6930	27.976	-67.333	-39.357	
		3.7044	3.7044	27.976	-67.229	-39.253	
		3.6785	3.6681	27.976	-67.186	-39.210	
	15	3.6910	3.7134	27.976	-67.235	-39.259	
		3.7039	3.6940	27.976	-67.138	-39.162	
		3.7044	3.7094	27.976	-67.175	-39.199	
	20	3.7169	3.6990	27.976	-67.132	-39.156	
		3.7124	3.6995	27.976	-67.148	-39.172	
		3.7005	3.7154	27.976	-67.341	-39.365	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 125 ~ 160.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor(dB) = Cable Loss + Ext. Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

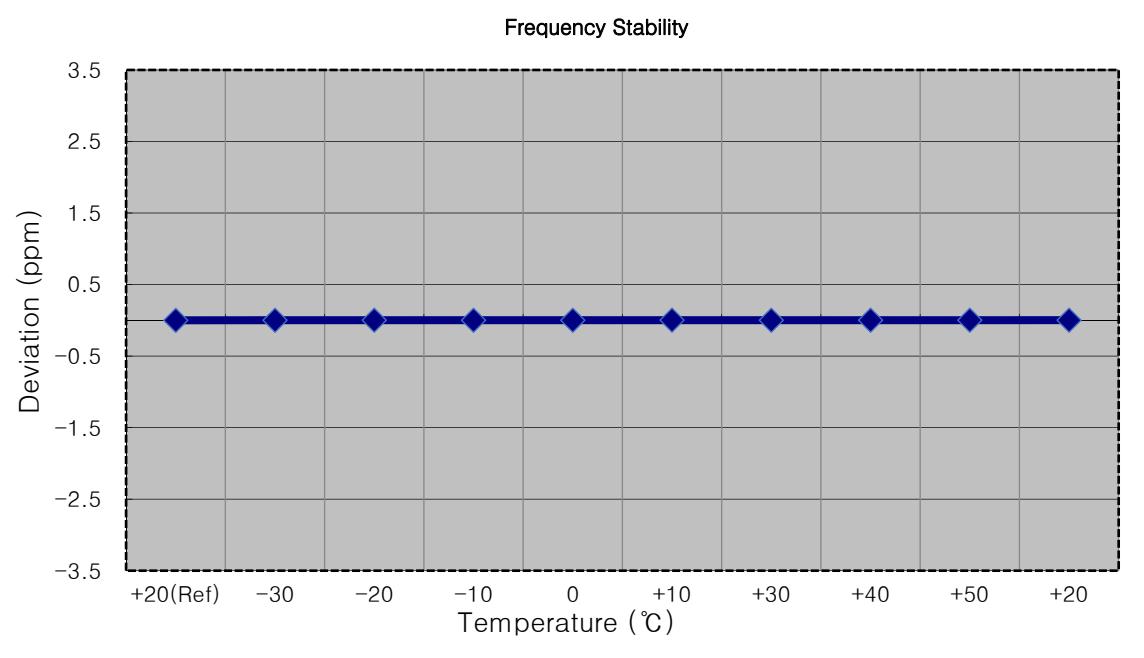
8.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 161 ~ 196.

8.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

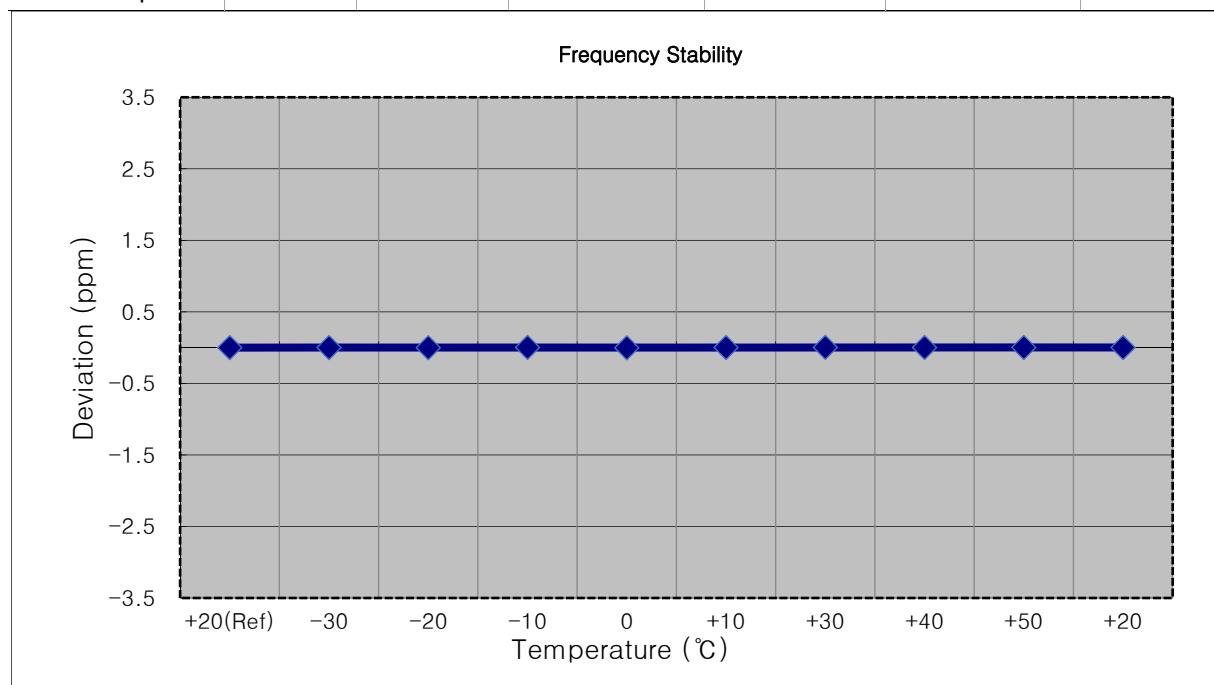
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1850,700,000 Hz
 CHANNEL: 26047 (1.4 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1850 700 004	0.0	0.000 000	0.000
100 %		-30	1850 700 006	2.8	0.000 000	0.002
100 %		-20	1850 700 007	3.4	0.000 000	0.002
100 %		-10	1850 700 006	2.9	0.000 000	0.002
100 %		0	1850 700 006	2.6	0.000 000	0.001
100 %		+10	1850 700 008	4.5	0.000 000	0.002
100 %		+30	1850 700 006	2.7	0.000 000	0.001
100 %		+40	1850 700 007	3.5	0.000 000	0.002
100 %		+50	1850 700 007	3.5	0.000 000	0.002
Batt. Endpoint	3.300	+20	1850 700 007	3.7	0.000 000	0.002



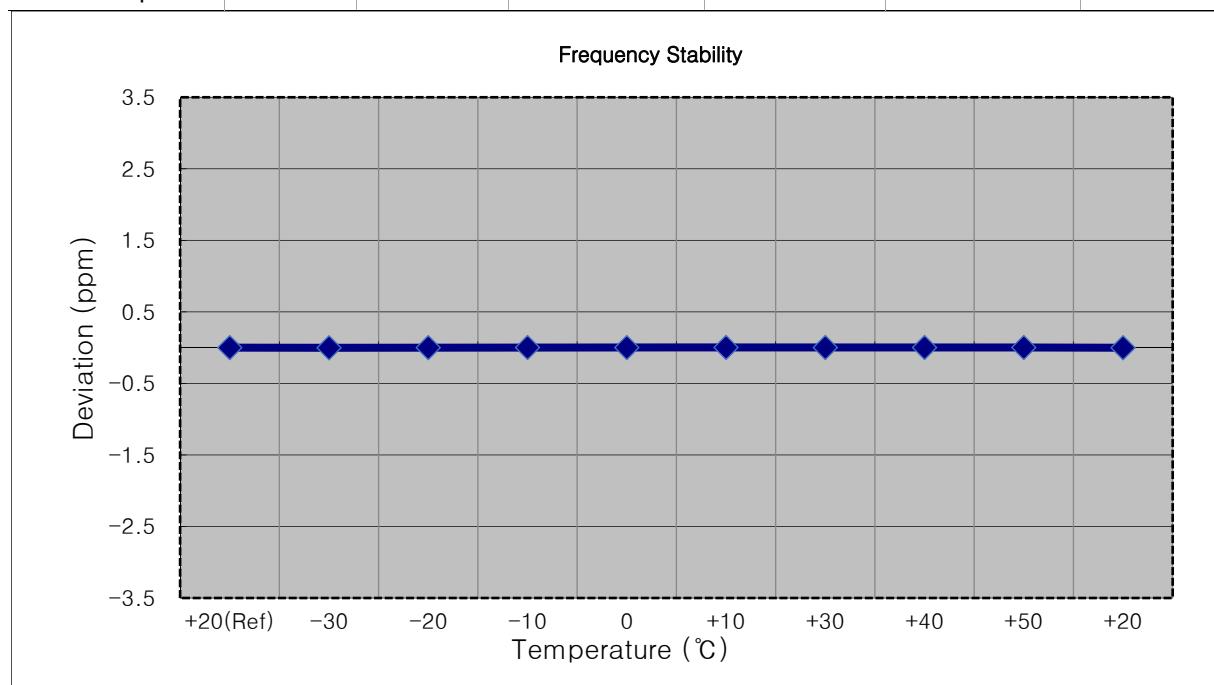
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1851,500,000 Hz
 CHANNEL: 26055 (3 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1851 499 997	0.0	0.000 000	0.000
100 %		-30	1851 499 999	2.1	0.000 000	0.001
100 %		-20	1851 499 995	-2.5	0.000 000	-0.001
100 %		-10	1851 500 003	6.2	0.000 000	0.003
100 %		0	1851 499 994	-2.9	0.000 000	-0.002
100 %		+10	1851 500 000	2.8	0.000 000	0.002
100 %		+30	1851 500 005	8.0	0.000 000	0.004
100 %		+40	1851 500 000	3.0	0.000 000	0.002
100 %		+50	1851 500 002	4.8	0.000 000	0.003
Batt. Endpoint	3.300	+20	1851 500 001	4.0	0.000 000	0.002



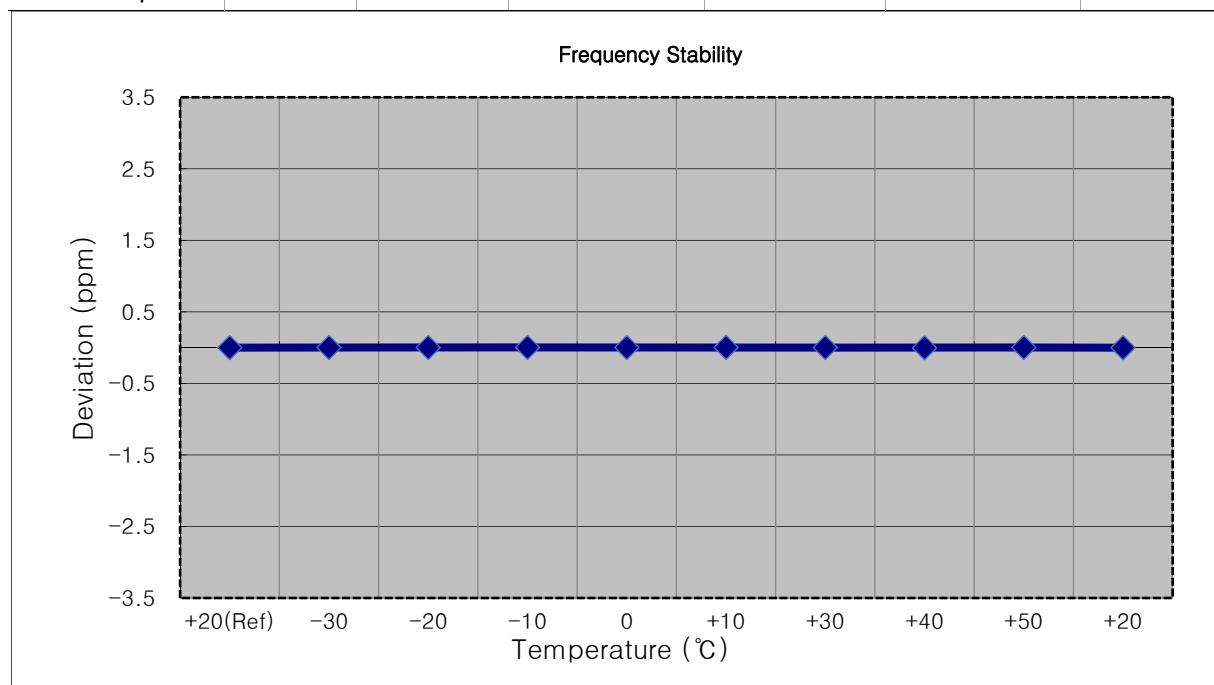
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1852,500,000 Hz
 CHANNEL: 26065 (5 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1852 499 998	0.0	0.000 000	0.000
100 %		-30	1852 499 994	-3.8	0.000 000	-0.002
100 %		-20	1852 499 999	1.3	0.000 000	0.001
100 %		-10	1852 500 002	3.7	0.000 000	0.002
100 %		0	1852 500 001	2.7	0.000 000	0.001
100 %		+10	1852 500 002	4.1	0.000 000	0.002
100 %		+30	1852 500 002	3.8	0.000 000	0.002
100 %		+40	1852 500 002	3.9	0.000 000	0.002
100 %		+50	1852 500 001	3.6	0.000 000	0.002
Batt. Endpoint	3.300	+20	1852 499 995	-2.7	0.000 000	-0.001



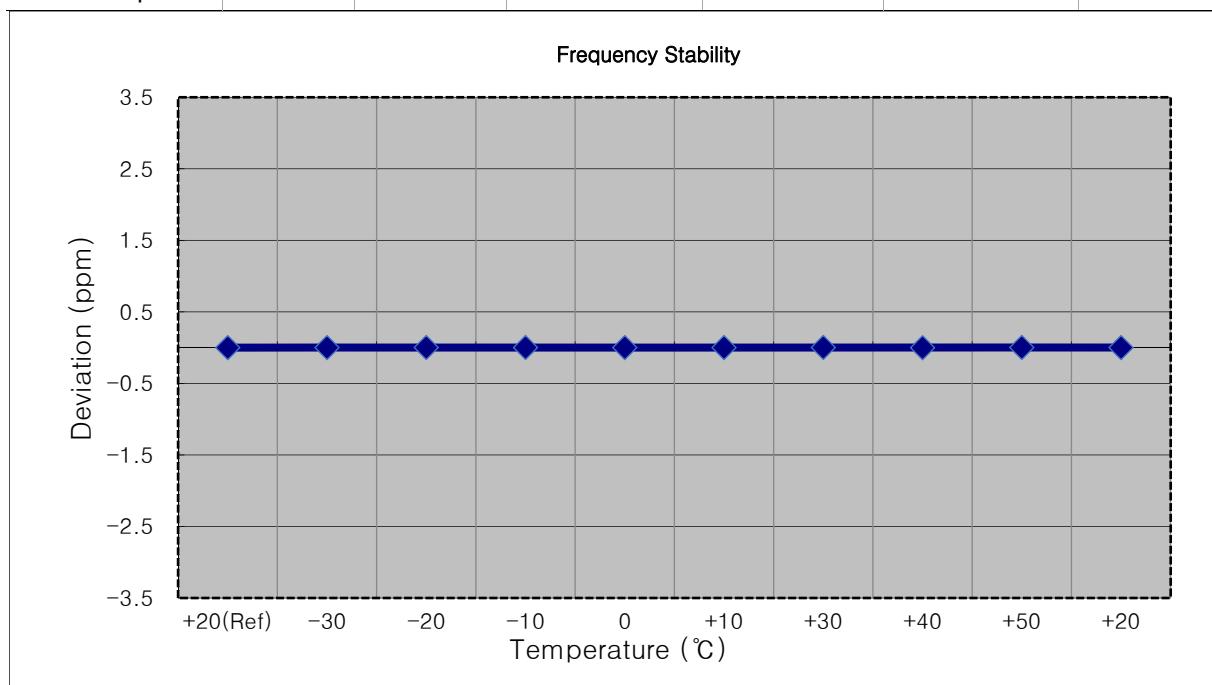
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1855,000,000 Hz
 CHANNEL: 26090 (10 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1855 000 003	0.0	0.000 000	0.000
100 %		-30	1855 000 006	3.3	0.000 000	0.002
100 %		-20	1855 000 007	3.5	0.000 000	0.002
100 %		-10	1855 000 007	4.2	0.000 000	0.002
100 %		0	1855 000 007	3.8	0.000 000	0.002
100 %		+10	1855 000 009	6.0	0.000 000	0.003
100 %		+30	1855 000 006	3.1	0.000 000	0.002
100 %		+40	1855 000 000	-3.0	0.000 000	-0.002
100 %		+50	1855 000 008	4.4	0.000 000	0.002
Batt. Endpoint	3.300	+20	1855 000 001	-1.7	0.000 000	-0.001



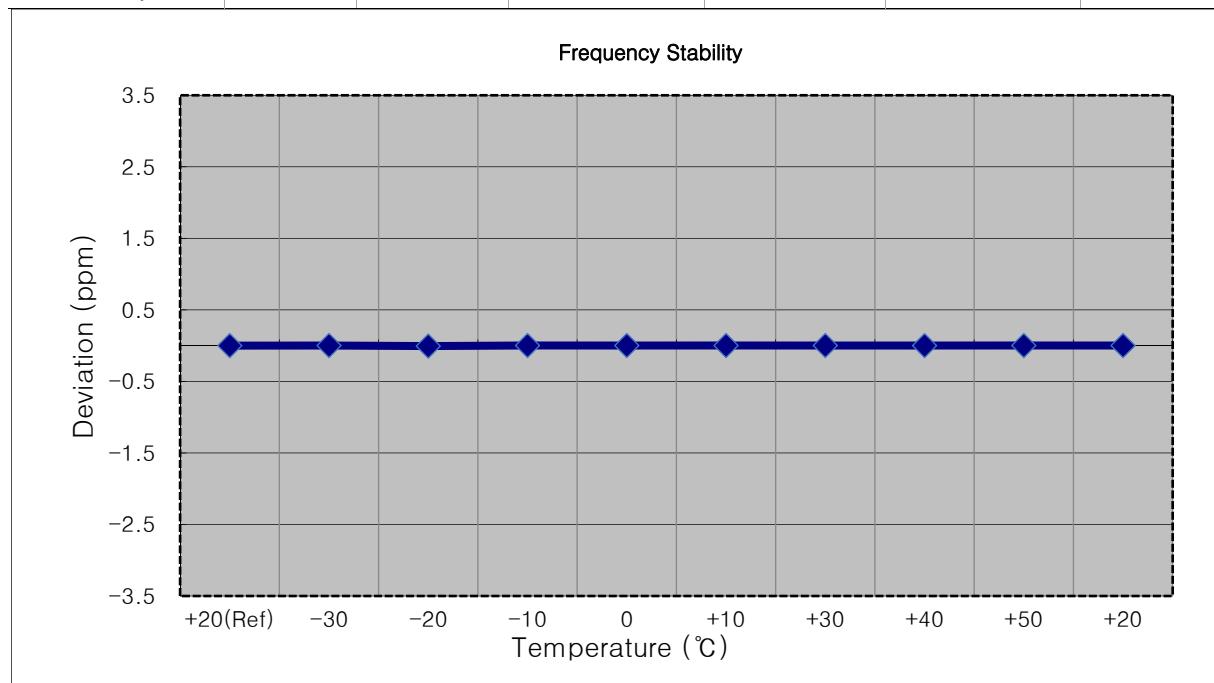
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1857,500,000 Hz
 CHANNEL: 26115 (15 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1857 500 002	0.0	0.000 000	0.000
100 %		-30	1857 500 005	2.6	0.000 000	0.001
100 %		-20	1857 500 005	2.9	0.000 000	0.002
100 %		-10	1857 500 005	3.3	0.000 000	0.002
100 %		0	1857 500 005	2.6	0.000 000	0.001
100 %		+10	1857 500 004	1.6	0.000 000	0.001
100 %		+30	1857 500 006	4.3	0.000 000	0.002
100 %		+40	1857 500 000	-2.4	0.000 000	-0.001
100 %		+50	1857 500 006	4.4	0.000 000	0.002
Batt. Endpoint	3.300	+20	1857 500 004	2.1	0.000 000	0.001



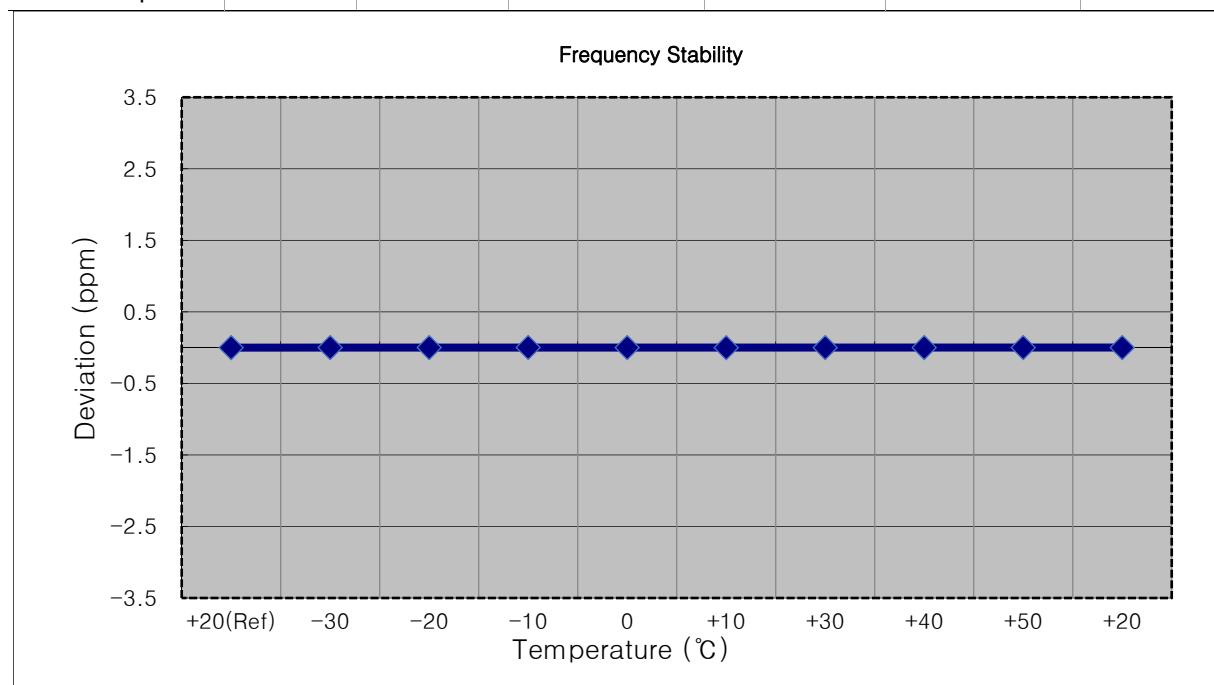
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1860,000,000 Hz
 CHANNEL: 26140 (20 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1860 000 007	0.0	0.000 000	0.000
100 %		-30	1860 000 011	3.2	0.000 000	0.002
100 %		-20	1859 999 996	-11.8	-0.000 001	-0.006
100 %		-10	1860 000 011	3.5	0.000 000	0.002
100 %		0	1860 000 010	3.0	0.000 000	0.002
100 %		+10	1860 000 011	3.6	0.000 000	0.002
100 %		+30	1860 000 011	3.2	0.000 000	0.002
100 %		+40	1860 000 010	2.6	0.000 000	0.001
100 %		+50	1860 000 011	4.1	0.000 000	0.002
Batt. Endpoint	3.300	+20	1860 000 010	2.4	0.000 000	0.001



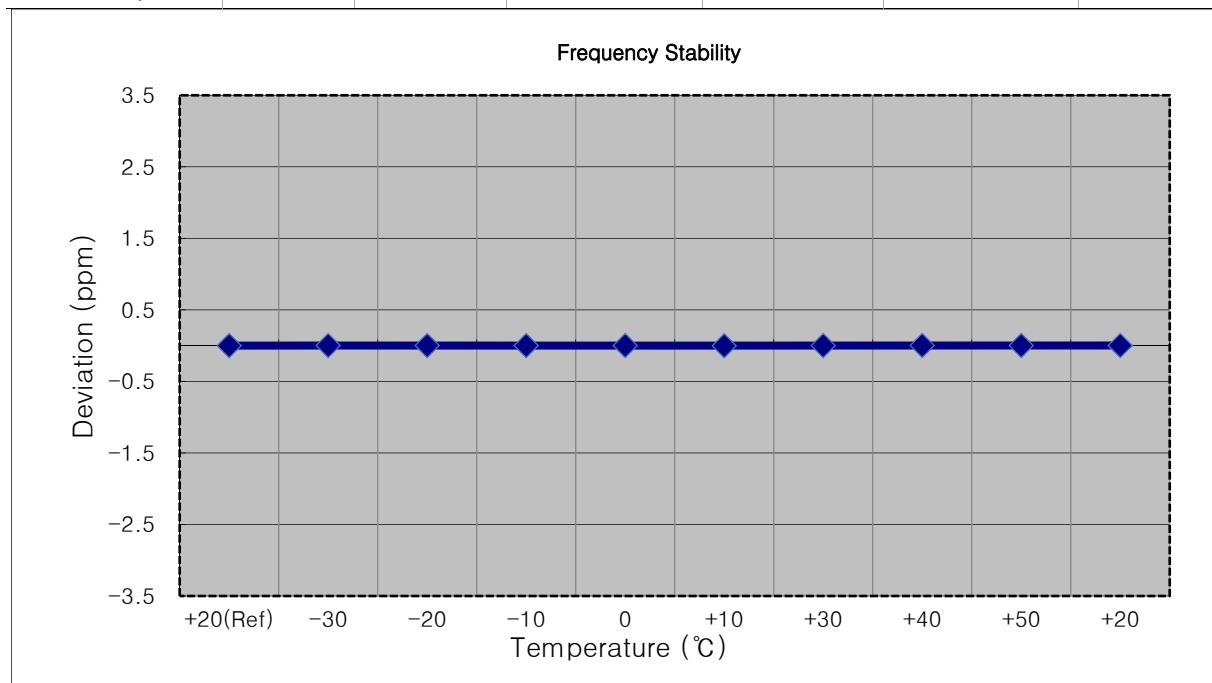
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (1.4 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 499 998	0.0	0.000 000	0.000
100 %		-30	1882 499 999	1.5	0.000 000	0.001
100 %		-20	1882 499 999	1.5	0.000 000	0.001
100 %		-10	1882 500 003	5.0	0.000 000	0.003
100 %		0	1882 500 000	1.8	0.000 000	0.001
100 %		+10	1882 499 997	-1.1	0.000 000	-0.001
100 %		+30	1882 500 001	2.7	0.000 000	0.001
100 %		+40	1882 500 000	2.4	0.000 000	0.001
100 %		+50	1882 500 001	2.7	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 500 000	2.4	0.000 000	0.001



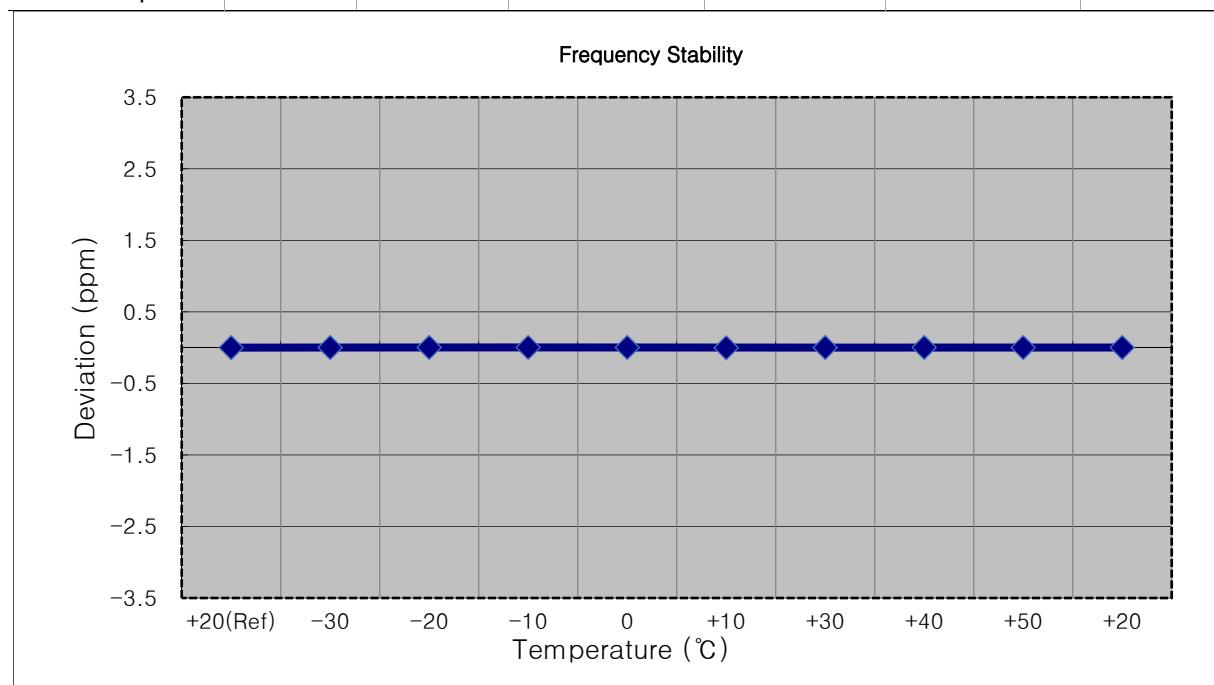
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (3 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 499 997	0.0	0.000 000	0.000
100 %		-30	1882 499 999	2.9	0.000 000	0.002
100 %		-20	1882 500 000	3.6	0.000 000	0.002
100 %		-10	1882 499 998	1.9	0.000 000	0.001
100 %		0	1882 499 999	2.7	0.000 000	0.001
100 %		+10	1882 499 994	-2.9	0.000 000	-0.002
100 %		+30	1882 499 999	2.6	0.000 000	0.001
100 %		+40	1882 500 001	4.4	0.000 000	0.002
100 %		+50	1882 500 001	4.1	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 000	3.6	0.000 000	0.002



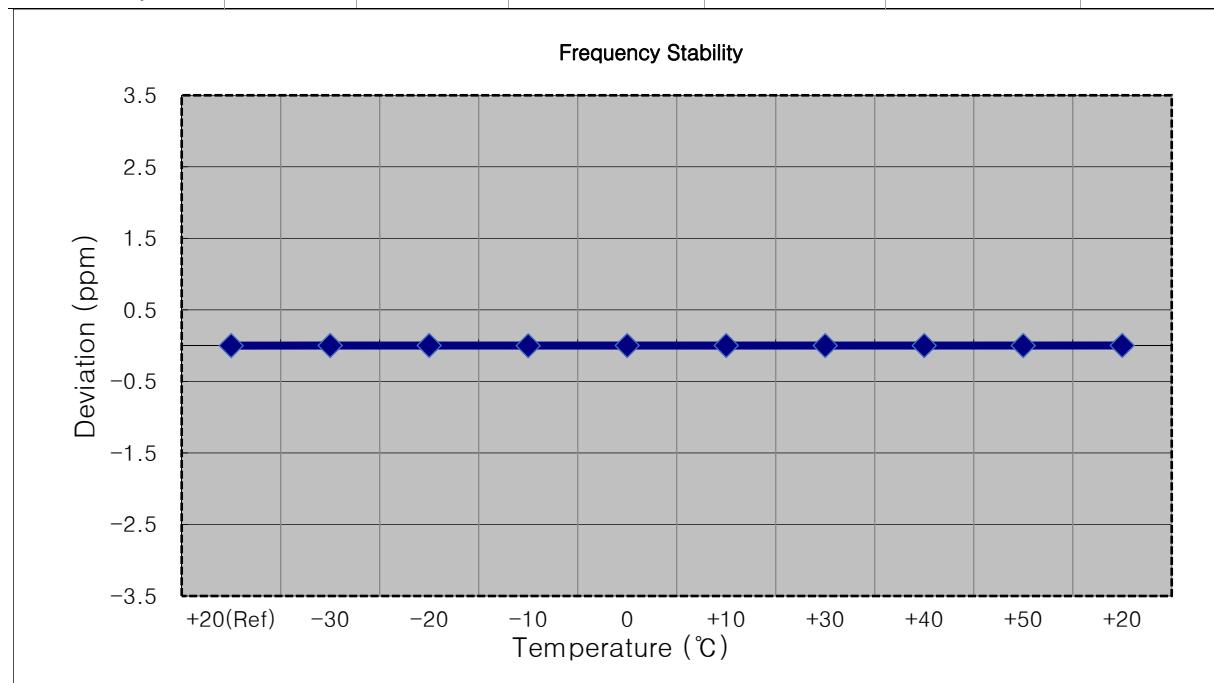
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (5 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 500 006	3.3	0.000 000	0.002
100 %		-20	1882 500 009	6.0	0.000 000	0.003
100 %		-10	1882 500 009	6.3	0.000 000	0.003
100 %		0	1882 500 008	5.0	0.000 000	0.003
100 %		+10	1882 500 000	-3.2	0.000 000	-0.002
100 %		+30	1882 500 006	3.3	0.000 000	0.002
100 %		+40	1882 500 008	5.0	0.000 000	0.003
100 %		+50	1882 500 005	2.2	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 500 006	3.1	0.000 000	0.002



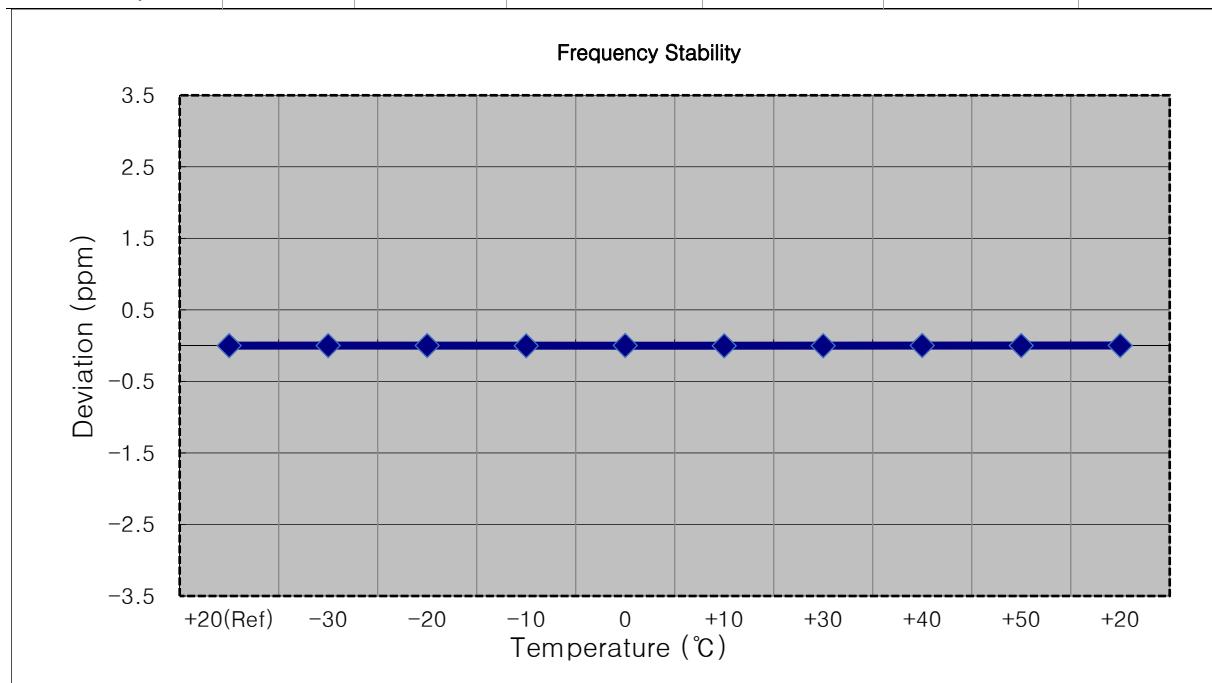
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (10 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 004	0.0	0.000 000	0.000
100 %		-30	1882 500 007	2.8	0.000 000	0.001
100 %		-20	1882 500 008	4.2	0.000 000	0.002
100 %		-10	1882 500 002	-2.2	0.000 000	-0.001
100 %		0	1882 500 007	3.1	0.000 000	0.002
100 %		+10	1882 500 008	3.8	0.000 000	0.002
100 %		+30	1882 500 006	2.1	0.000 000	0.001
100 %		+40	1882 500 006	2.3	0.000 000	0.001
100 %		+50	1882 500 006	2.5	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 500 008	4.4	0.000 000	0.002



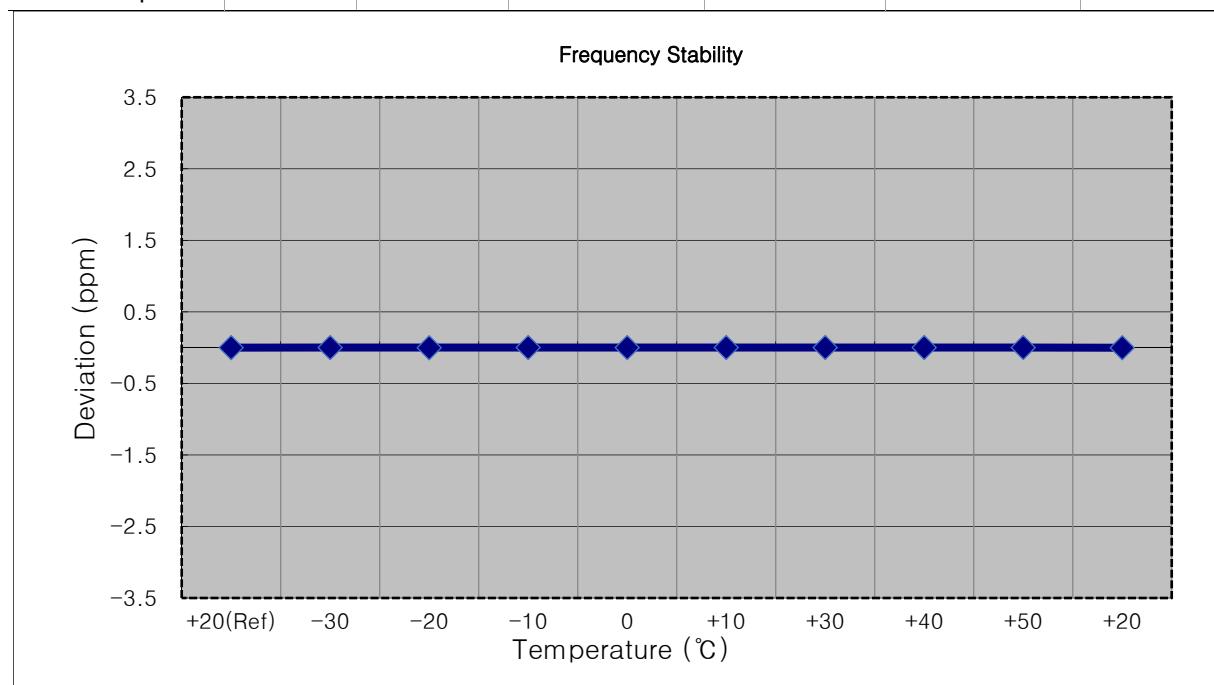
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (15 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 002	0.0	0.000 000	0.000
100 %		-30	1882 500 004	1.9	0.000 000	0.001
100 %		-20	1882 500 005	3.1	0.000 000	0.002
100 %		-10	1882 499 998	-3.6	0.000 000	-0.002
100 %		0	1882 500 007	4.6	0.000 000	0.002
100 %		+10	1882 499 998	-3.7	0.000 000	-0.002
100 %		+30	1882 499 999	-2.6	0.000 000	-0.001
100 %		+40	1882 500 005	3.5	0.000 000	0.002
100 %		+50	1882 500 004	2.3	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 500 006	4.3	0.000 000	0.002



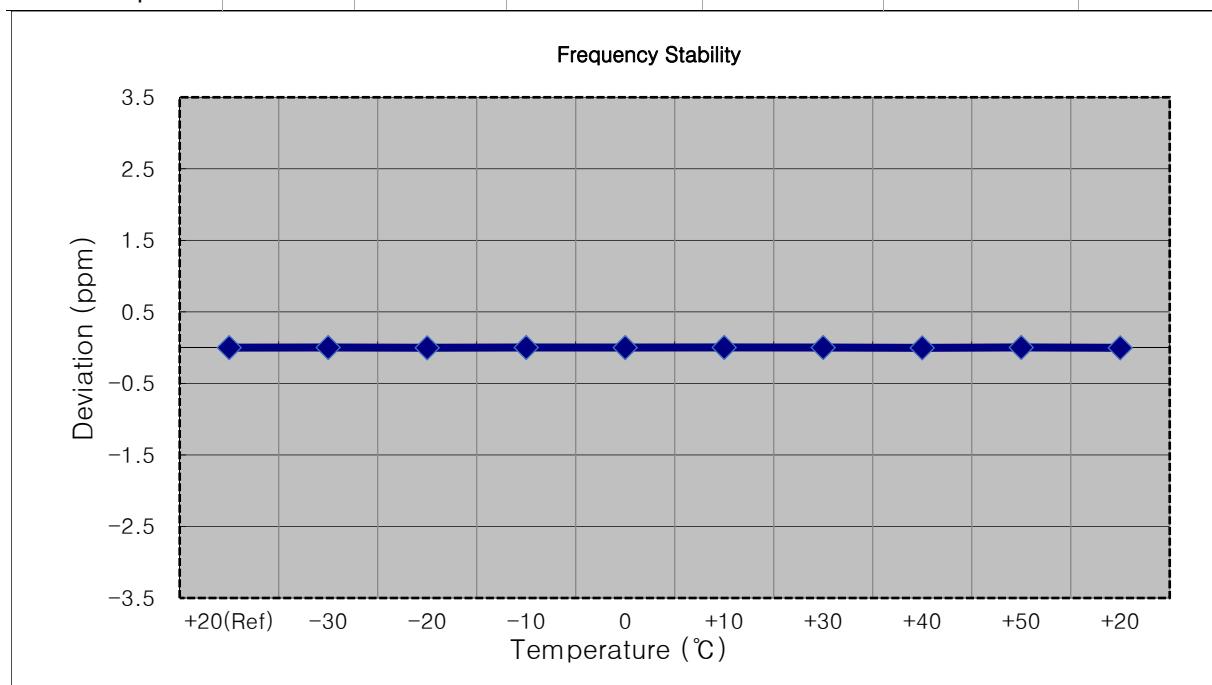
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (20 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 002	0.0	0.000 000	0.000
100 %		-30	1882 500 004	2.6	0.000 000	0.001
100 %		-20	1882 500 000	-1.8	0.000 000	-0.001
100 %		-10	1882 500 005	3.6	0.000 000	0.002
100 %		0	1882 500 004	2.3	0.000 000	0.001
100 %		+10	1882 500 005	3.1	0.000 000	0.002
100 %		+30	1882 500 005	3.6	0.000 000	0.002
100 %		+40	1882 500 005	3.3	0.000 000	0.002
100 %		+50	1882 500 005	3.2	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 000	-2.2	0.000 000	-0.001



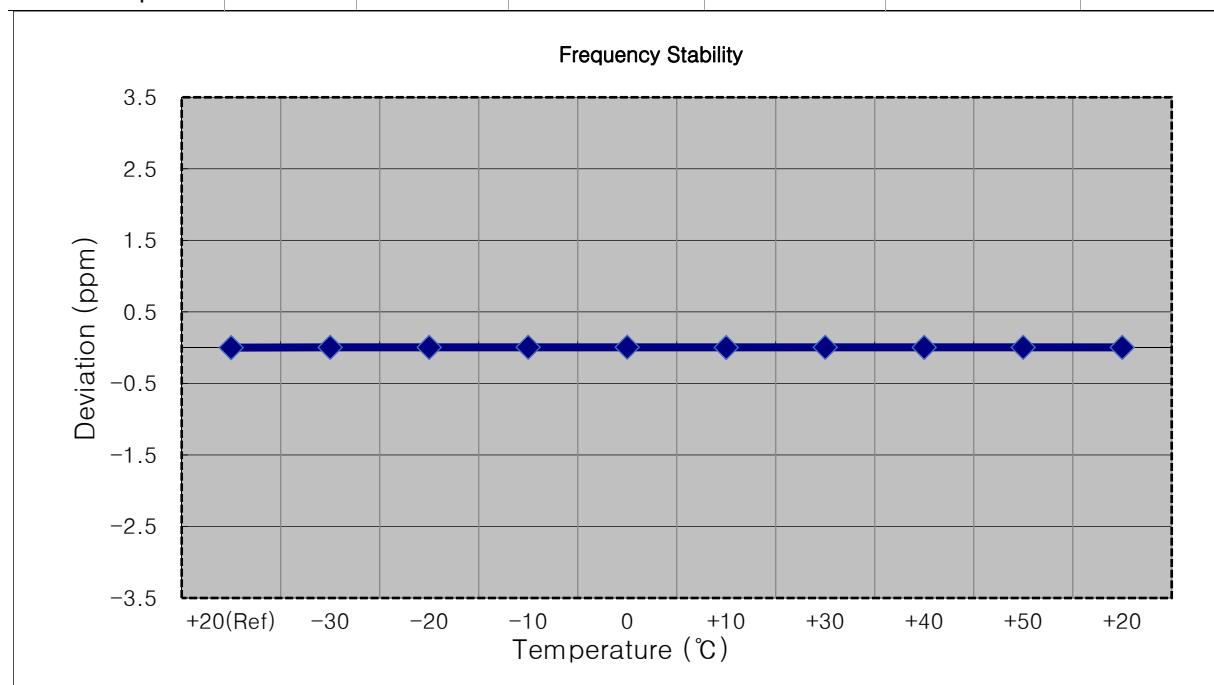
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1914,300,000 Hz
 CHANNEL: 26683 (1.4 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1914 300 006	0.0	0.000 000	0.000
100 %		-30	1914 300 010	4.0	0.000 000	0.002
100 %		-20	1914 300 002	-3.6	0.000 000	-0.002
100 %		-10	1914 300 009	3.6	0.000 000	0.002
100 %		0	1914 300 008	2.2	0.000 000	0.001
100 %		+10	1914 300 011	5.3	0.000 000	0.003
100 %		+30	1914 300 009	2.9	0.000 000	0.002
100 %		+40	1914 300 000	-5.5	0.000 000	-0.003
100 %		+50	1914 300 011	5.6	0.000 000	0.003
Batt. Endpoint	3.300	+20	1914 300 001	-4.5	0.000 000	-0.002



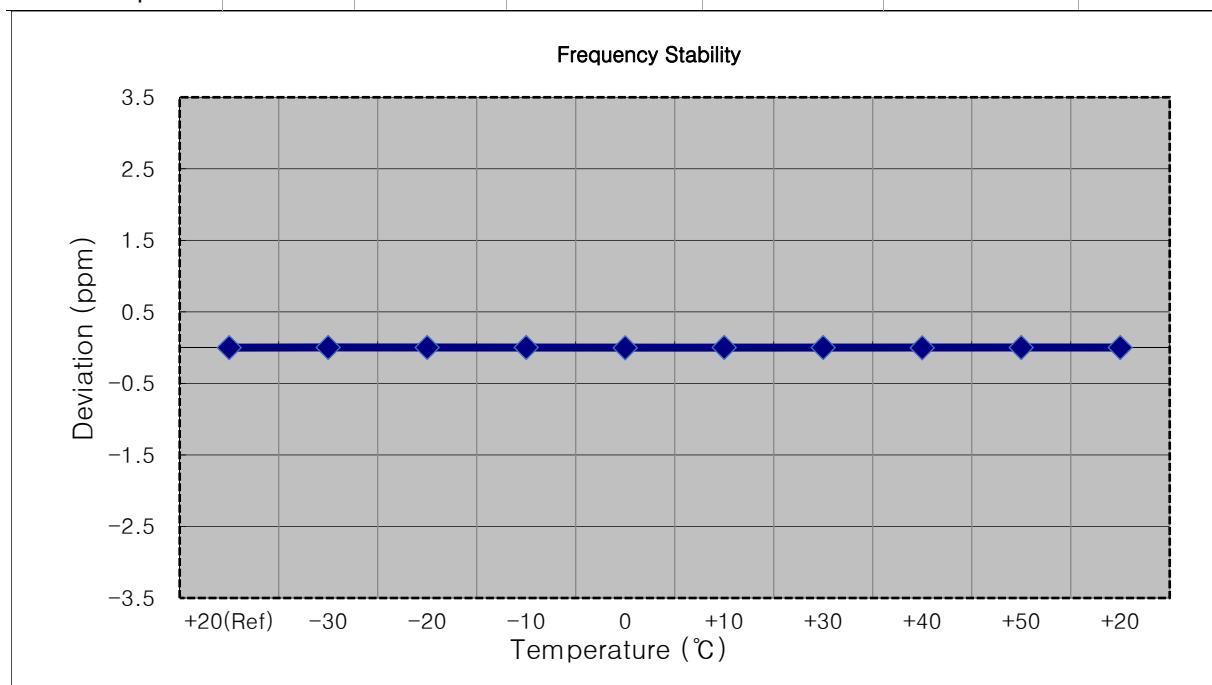
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1913,500,000 Hz
 CHANNEL: 26675 (3 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1913 500 007	0.0	0.000 000	0.000
100 %		-30	1913 500 015	8.2	0.000 000	0.004
100 %		-20	1913 500 014	7.8	0.000 000	0.004
100 %		-10	1913 500 017	10.3	0.000 001	0.005
100 %		0	1913 500 018	11.7	0.000 001	0.006
100 %		+10	1913 500 011	4.2	0.000 000	0.002
100 %		+30	1913 500 015	8.6	0.000 000	0.004
100 %		+40	1913 500 012	5.8	0.000 000	0.003
100 %		+50	1913 500 014	7.8	0.000 000	0.004
Batt. Endpoint	3.300	+20	1913 500 013	6.8	0.000 000	0.004



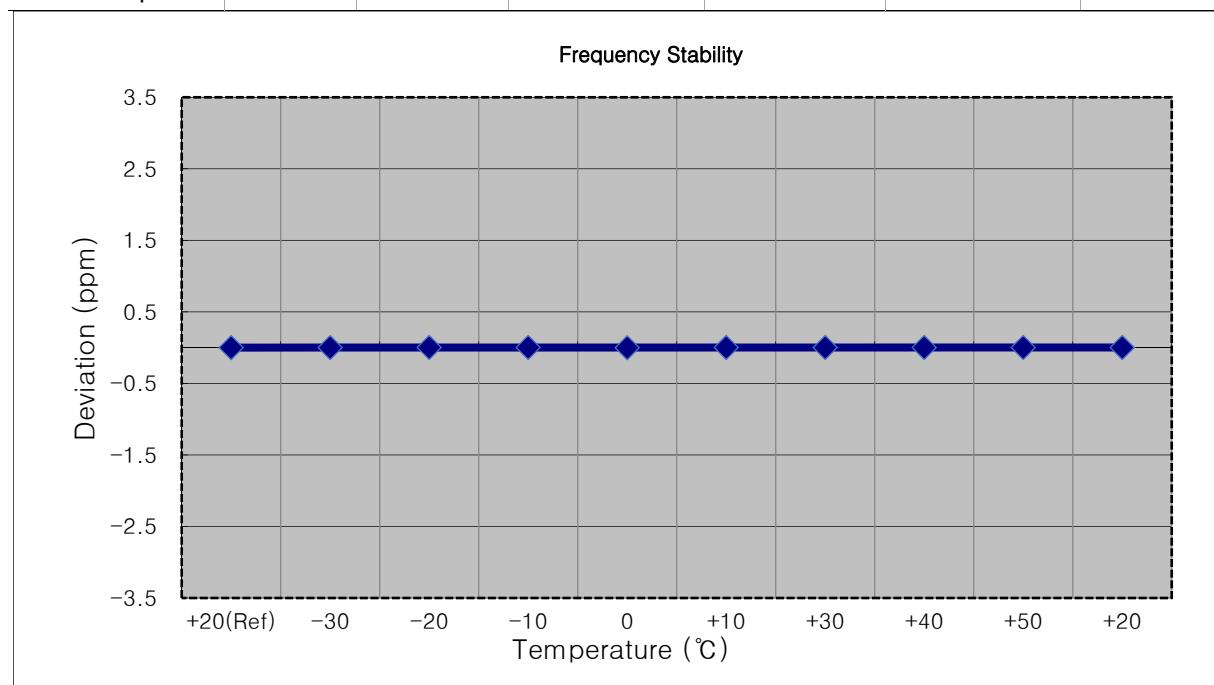
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1912,500,000 Hz
 CHANNEL: 26665 (5 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1912 500 005	0.0	0.000 000	0.000
100 %		-30	1912 500 010	5.2	0.000 000	0.003
100 %		-20	1912 500 009	4.3	0.000 000	0.002
100 %		-10	1912 500 010	5.3	0.000 000	0.003
100 %		0	1912 500 001	-3.3	0.000 000	-0.002
100 %		+10	1912 500 009	4.5	0.000 000	0.002
100 %		+30	1912 500 008	3.5	0.000 000	0.002
100 %		+40	1912 500 001	-3.3	0.000 000	-0.002
100 %		+50	1912 500 008	3.6	0.000 000	0.002
Batt. Endpoint	3.300	+20	1912 500 008	3.4	0.000 000	0.002



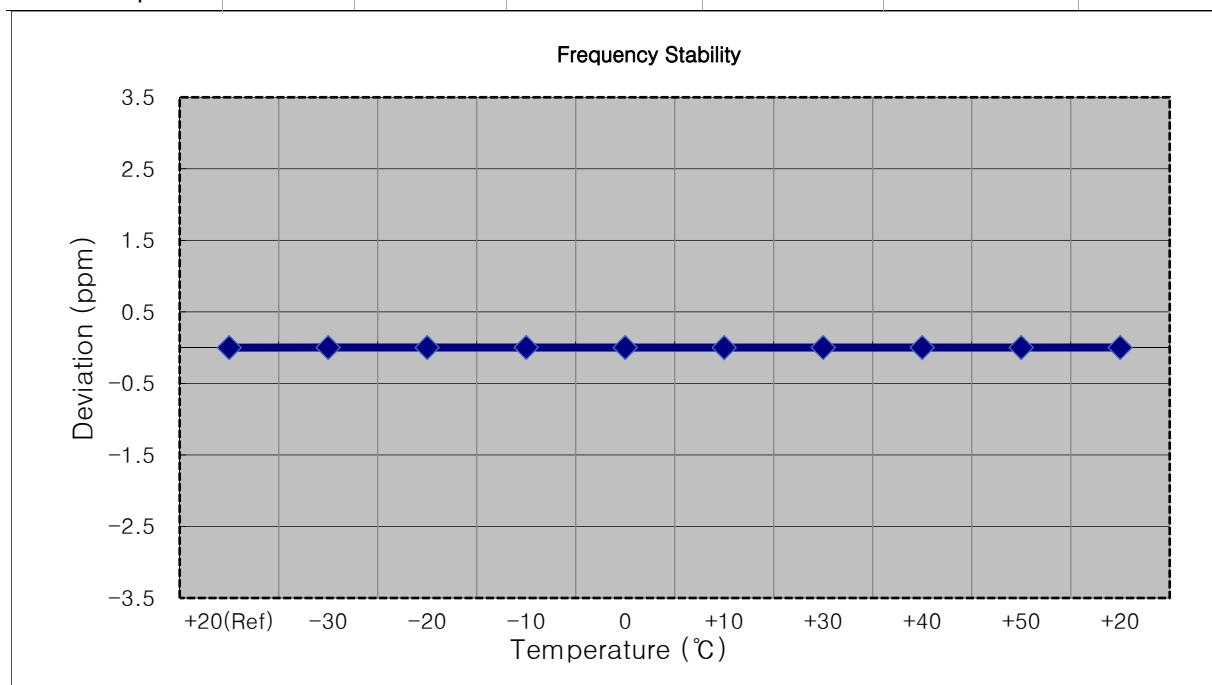
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1910,000,000 Hz
 CHANNEL: 26640 (10 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1910 000 005	0.0	0.000 000	0.000
100 %		-30	1910 000 007	2.7	0.000 000	0.001
100 %		-20	1910 000 010	5.3	0.000 000	0.003
100 %		-10	1910 000 010	5.5	0.000 000	0.003
100 %		0	1910 000 002	-2.6	0.000 000	-0.001
100 %		+10	1910 000 009	4.2	0.000 000	0.002
100 %		+30	1910 000 008	3.8	0.000 000	0.002
100 %		+40	1910 000 008	3.6	0.000 000	0.002
100 %		+50	1910 000 009	4.0	0.000 000	0.002
Batt. Endpoint	3.300	+20	1910 000 008	3.6	0.000 000	0.002



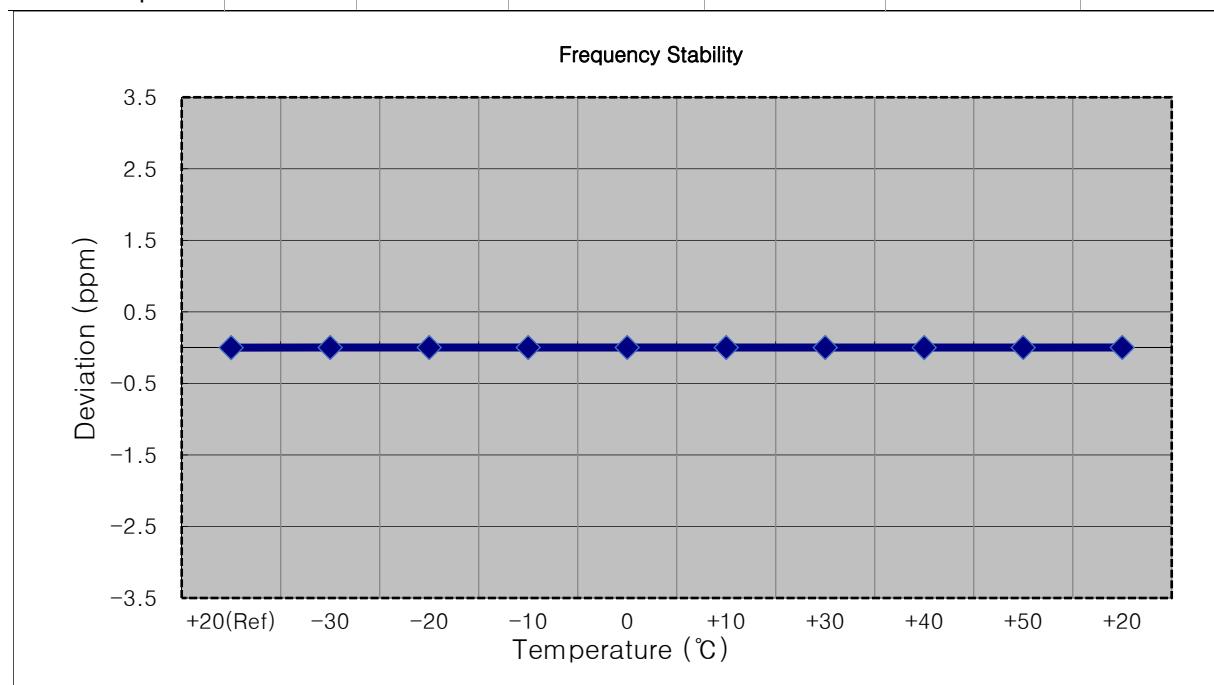
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1907,500,000 Hz
 CHANNEL: 26615 (15 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1907 499 998	0.0	0.000 000	0.000
100 %		-30	1907 500 002	4.0	0.000 000	0.002
100 %		-20	1907 500 001	3.1	0.000 000	0.002
100 %		-10	1907 500 003	4.6	0.000 000	0.002
100 %		0	1907 500 001	3.1	0.000 000	0.002
100 %		+10	1907 499 999	1.2	0.000 000	0.001
100 %		+30	1907 500 001	2.8	0.000 000	0.001
100 %		+40	1907 500 000	2.3	0.000 000	0.001
100 %		+50	1907 500 001	3.2	0.000 000	0.002
Batt. Endpoint	3.300	+20	1907 500 002	3.7	0.000 000	0.002



- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1905,000,000 Hz
 CHANNEL: 26590 (20 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1905 000 005	0.0	0.000 000	0.000
100 %		-30	1905 000 009	4.1	0.000 000	0.002
100 %		-20	1905 000 009	4.0	0.000 000	0.002
100 %		-10	1905 000 008	3.6	0.000 000	0.002
100 %		0	1905 000 009	4.8	0.000 000	0.003
100 %		+10	1905 000 008	3.4	0.000 000	0.002
100 %		+30	1905 000 008	3.5	0.000 000	0.002
100 %		+40	1905 000 007	2.7	0.000 000	0.001
100 %		+50	1905 000 007	2.8	0.000 000	0.001
Batt. Endpoint	3.300	+20	1905 000 010	4.9	0.000 000	0.003



9. TEST DATA(Sub 5 Ant)

9.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB		
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset	
1850.7	LTE B25/B2 1.4 MHz	QPSK	-20.90	12.99	10.31	2.30	H	< 2.00	0.126	21.00	1	0	
		16-QAM	-21.68	12.21	10.31	2.30	H		0.105	20.22			
		64-QAM	-22.73	11.16	10.31	2.30	H		0.083	19.17			
		256-QAM	-25.95	7.94	10.31	2.30	H		0.039	15.95			
1882.5		QPSK	-21.05	13.65	10.35	2.33	H	< 2.00	0.147	21.67	1	0	
		16-QAM	-21.90	12.80	10.35	2.33	H		0.121	20.82			
		64-QAM	-22.89	11.81	10.35	2.33	H		0.096	19.83			
		256-QAM	-26.16	8.54	10.35	2.33	H		0.045	16.56			
1914.3		QPSK	-21.42	12.68	10.41	2.29	H	< 2.00	0.120	20.80	1	0	
		16-QAM	-22.32	11.78	10.41	2.29	H		0.098	19.90			
		64-QAM	-23.30	10.80	10.41	2.29	H		0.078	18.92			
		256-QAM	-26.58	7.52	10.41	2.29	H		0.037	15.64			

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB		
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset	
1851.5	LTE B25/B2 3 MHz	QPSK	-20.90	12.99	10.31	2.30	H	< 2.00	0.126	21.00	1	0	
		16-QAM	-21.71	12.18	10.31	2.30	H		0.104	20.19			
		64-QAM	-22.72	11.17	10.31	2.30	H		0.083	19.18			
		256-QAM	-25.92	7.97	10.31	2.30	H		0.040	15.98			
1882.5		QPSK	-21.04	13.66	10.35	2.33	H	< 2.00	0.147	21.68	1	0	
		16-QAM	-21.89	12.81	10.35	2.33	H		0.121	20.83			
		64-QAM	-22.82	11.88	10.35	2.33	H		0.098	19.90			
		256-QAM	-26.00	8.70	10.35	2.33	H		0.047	16.72			
1913.5		QPSK	-21.36	12.74	10.41	2.29	H	< 2.00	0.122	20.86	1	0	
		16-QAM	-22.18	11.92	10.41	2.29	H		0.101	20.04			
		64-QAM	-23.27	10.83	10.41	2.29	H		0.079	18.95			
		256-QAM	-26.24	7.86	10.41	2.29	H		0.040	15.98			

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1852.5	LTE B25/B2 5 MHz	QPSK	-20.95	12.94	10.31	2.30	H	< 2.00	0.124	20.95	1	0
		16-QAM	-21.77	12.12	10.31	2.30	H		0.103	20.13		
		64-QAM	-22.81	11.08	10.31	2.30	H		0.081	19.09		
		256-QAM	-26.00	7.89	10.31	2.30	H		0.039	15.90		
		QPSK	-20.97	13.73	10.35	2.33	H	< 2.00	0.150	21.75	1	0
		16-QAM	-21.75	12.95	10.35	2.33	H		0.125	20.97		
		64-QAM	-22.78	11.92	10.35	2.33	H		0.099	19.94		
		256-QAM	-26.05	8.65	10.35	2.33	H		0.046	16.67		
		QPSK	-21.38	12.66	10.40	2.29	H	< 2.00	0.119	20.77	1	0
		16-QAM	-22.12	11.91	10.41	2.29	H		0.101	20.03		
		64-QAM	-23.05	10.98	10.41	2.29	H		0.081	19.10		
		256-QAM	-26.22	7.81	10.41	2.29	H		0.039	15.93		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1855.0	LTE B25/B2 10 MHz	QPSK	-20.95	12.91	10.41	2.29	H	< 2.00	0.127	21.03	1	0
		16-QAM	-21.86	12.05	10.32	2.25	H		0.103	20.12		
		64-QAM	-22.87	11.04	10.32	2.25	H		0.081	19.11		
		256-QAM	-26.07	7.84	10.32	2.25	H		0.039	15.91		
		QPSK	-21.09	13.61	10.35	2.33	H	< 2.00	0.146	21.63	1	0
		16-QAM	-22.00	12.70	10.35	2.33	H		0.118	20.72		
		64-QAM	-23.02	11.68	10.35	2.33	H		0.093	19.70		
		256-QAM	-26.17	8.53	10.35	2.33	H		0.045	16.55		
		QPSK	-21.27	12.76	10.41	2.29	H	< 2.00	0.122	20.88	1	0
		16-QAM	-22.13	11.90	10.41	2.29	H		0.100	20.02		
		64-QAM	-23.27	10.76	10.41	2.29	H		0.077	18.88		
		256-QAM	-26.36	7.67	10.41	2.29	H		0.038	15.79		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1857.5	LTE B25/B2 15 MHz	QPSK	-20.96	13.04	10.32	2.26	H	< 2.00	0.129	21.10	1	0
		16-QAM	-21.81	12.19	10.32	2.26	H		0.106	20.25		
		64-QAM	-22.90	11.10	10.32	2.26	H		0.082	19.16		
		256-QAM	-26.11	7.89	10.32	2.26	H		0.039	15.95		
		QPSK	-20.94	13.76	10.35	2.33	H	< 2.00	0.151	21.78	1	0
		16-QAM	-21.70	13.00	10.35	2.33	H		0.126	21.02		
		64-QAM	-22.82	11.88	10.35	2.33	H		0.098	19.90		
		256-QAM	-25.96	8.74	10.35	2.33	H		0.047	16.76		
		QPSK	-21.22	12.81	10.41	2.29	H	< 2.00	0.124	20.93	1	0
		16-QAM	-22.08	11.95	10.41	2.29	H		0.102	20.07		
		64-QAM	-23.16	10.87	10.41	2.29	H		0.079	18.99		
		256-QAM	-26.33	7.70	10.41	2.29	H		0.038	15.82		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1860.0	LTE B25/B2 20 MHz	QPSK	-21.09	12.91	10.32	2.26	H	< 2.00	0.125	20.97	1	0
		16-QAM	-22.01	11.99	10.32	2.26	H		0.101	20.05		
		64-QAM	-23.07	10.93	10.32	2.26	H		0.079	18.99		
		256-QAM	-26.23	7.77	10.32	2.26	H		0.038	15.83		
		QPSK	-20.99	13.71	10.35	2.33	H	< 2.00	0.149	21.73	1	0
		16-QAM	-21.86	12.84	10.35	2.33	H		0.122	20.86		
		64-QAM	-22.94	11.76	10.35	2.33	H		0.095	19.78		
		256-QAM	-25.99	8.71	10.35	2.33	H		0.047	16.73		
		QPSK	-21.43	12.72	10.39	2.30	H	< 2.00	0.121	20.82	1	0
		16-QAM	-22.22	11.93	10.39	2.30	H		0.101	20.03		
		64-QAM	-23.20	10.95	10.39	2.30	H		0.080	19.05		
		256-QAM	-26.28	7.87	10.39	2.30	H		0.040	15.97		

9.2 RADIATED SPURIOUS EMISSIONS

- OPERATING FREQUENCY: 1882.5 MHz
- MEASURED OUTPUT POWER: 21.78 dBm = 0.151 W
- MOD: LTE B25/B2
- MODULATION SIGNAL: 15 MHz QPSK
- DISTANCE: 3 meters
- LIMIT: $43 + 10 \log_{10} (W) =$ 34.78 dBc

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	dBc	RB	
									Size	Offset
26115 (1857.5)	3 715.00	-55.54	12.28	-60.45	3.20	V	-51.37	73.15	1	0
	5 572.50	-58.23	13.06	-56.37	3.93	V	-47.24	69.02		
	7 430.00	-57.18	10.78	-46.61	4.69	V	-40.52	62.30		
26365 (1882.5)	3 765.00	-54.25	12.22	-58.78	3.26	V	-49.82	71.60	1	0
	5 647.50	-55.53	13.12	-53.58	4.03	V	-44.49	66.27		
	7 530.00	-58.67	10.85	-47.96	4.72	V	-41.83	63.61		
26615 (1907.5)	3 815.00	-54.28	12.16	-59.13	3.25	V	-50.22	72.00	1	0
	5 722.50	-56.26	13.06	-53.61	4.15	V	-44.70	66.48		
	7 630.00	-57.27	11.18	-47.11	4.74	V	-40.67	62.45		

9.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)	
25/2	1.4 MHz	1882.5	QPSK	6	0	5.07	
			16-QAM	6	0	5.60	
			64-QAM	6	0	5.87	
			256-QAM	6	0	6.11	
	3 MHz		QPSK	15	0	5.16	
			16-QAM	15	0	5.79	
			64-QAM	15	0	5.92	
			256-QAM	15	0	6.12	
	5 MHz		QPSK	25	0	5.12	
			16-QAM	25	0	5.79	
			64-QAM	25	0	5.90	
			256-QAM	25	0	6.08	
	10 MHz		QPSK	50	0	5.22	
			16-QAM	50	0	5.75	
			64-QAM	50	0	5.93	
			256-QAM	50	0	6.11	
	15 MHz		QPSK	75	0	5.09	
			16-QAM	75	0	5.68	
			64-QAM	75	0	5.92	
			256-QAM	75	0	6.13	
	20 MHz		QPSK	100	0	5.07	
			16-QAM	100	0	5.67	
			64-QAM	100	0	5.90	
			256-QAM	100	0	6.11	

Note:

- Plots of the EUT's Peak- to- Average Ratio are shown Page 198 ~ 221.

9.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)	
25/2	1.4 MHz	1882.5	QPSK	6	0	1.0975	
			16-QAM	6	0	1.1044	
			64-QAM	6	0	1.1080	
			256-QAM	6	0	1.0953	
	3 MHz		QPSK	15	0	2.7206	
			16-QAM	15	0	2.7308	
			64-QAM	15	0	2.7095	
			256-QAM	15	0	2.7225	
	5 MHz		QPSK	25	0	4.5411	
			16-QAM	25	0	4.5401	
			64-QAM	25	0	4.5193	
			256-QAM	25	0	4.5083	
	10 MHz		QPSK	50	0	9.0424	
			16-QAM	50	0	9.0395	
			64-QAM	50	0	9.0258	
			256-QAM	50	0	9.0209	
	15 MHz		QPSK	75	0	13.529	
			16-QAM	75	0	13.491	
			64-QAM	75	0	13.466	
			256-QAM	75	0	13.525	
	20 MHz		QPSK	100	0	17.950	
			16-QAM	100	0	17.978	
			64-QAM	100	0	17.958	
			256-QAM	100	0	17.982	

Note:

- Plots of the EUT's Occupied Bandwidth are shown Page 222 ~ 245.

9.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
25/2	1.4	3.6790	3.1611	27.976	-67.357	-39.381	
		3.6790	3.7084	27.976	-67.324	-39.348	
		3.6780	3.7079	27.976	-67.424	-39.448	
	3	3.6815	3.7169	27.976	-67.465	-39.489	
		3.7114	3.7149	27.976	-67.218	-39.242	
		3.6885	3.6880	27.976	-67.241	-39.265	
	5	3.7194	3.6730	27.976	-67.121	-39.145	
		3.7114	3.6910	27.976	-67.194	-39.218	
		3.6850	3.6960	27.976	-67.267	-39.291	
	10	3.7189	3.6860	27.976	-67.249	-39.273	
		3.7044	3.7129	27.976	-66.839	-38.863	
		3.6785	3.7174	27.976	-67.051	-39.075	
	15	3.6910	3.6970	27.976	-66.805	-38.829	
		3.7039	3.7069	27.976	-67.578	-39.602	
		3.7044	3.7229	27.976	-66.966	-38.990	
	20	3.7169	3.6860	27.976	-66.906	-38.930	
		3.7124	3.7109	27.976	-67.093	-39.117	
		3.7005	3.6860	27.976	-67.128	-39.152	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 246 ~ 281.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor(dB) = Cable Loss + Ext. Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

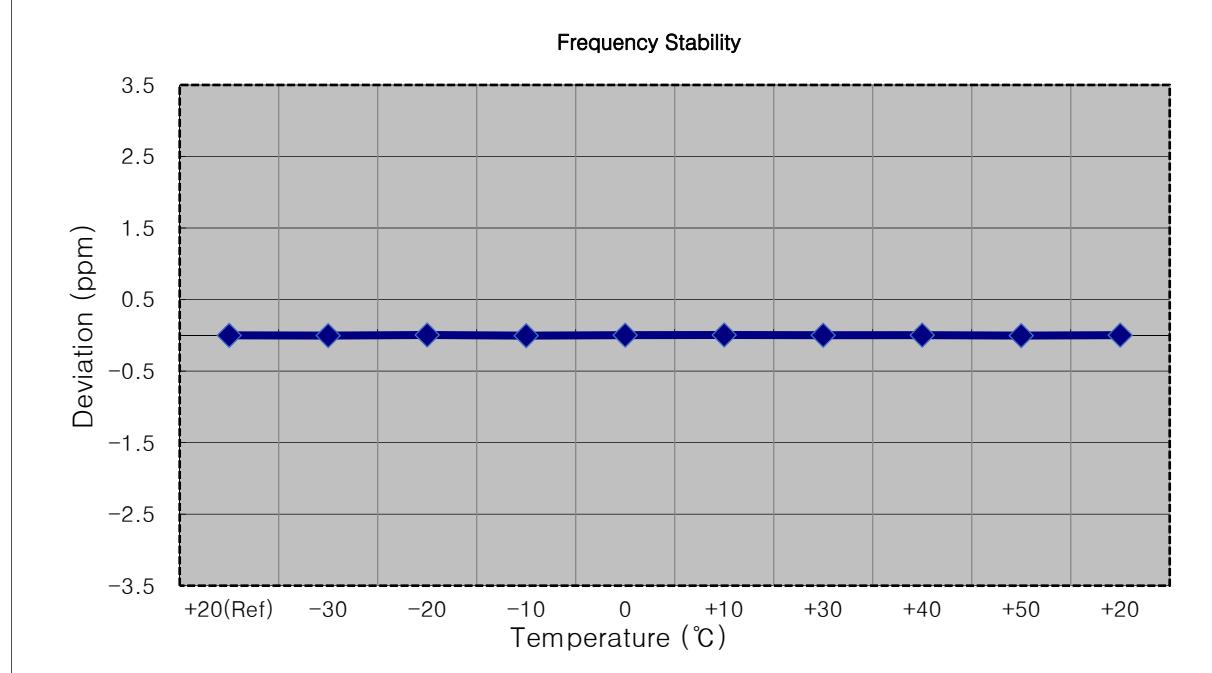
9.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 282 ~ 317.

9.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

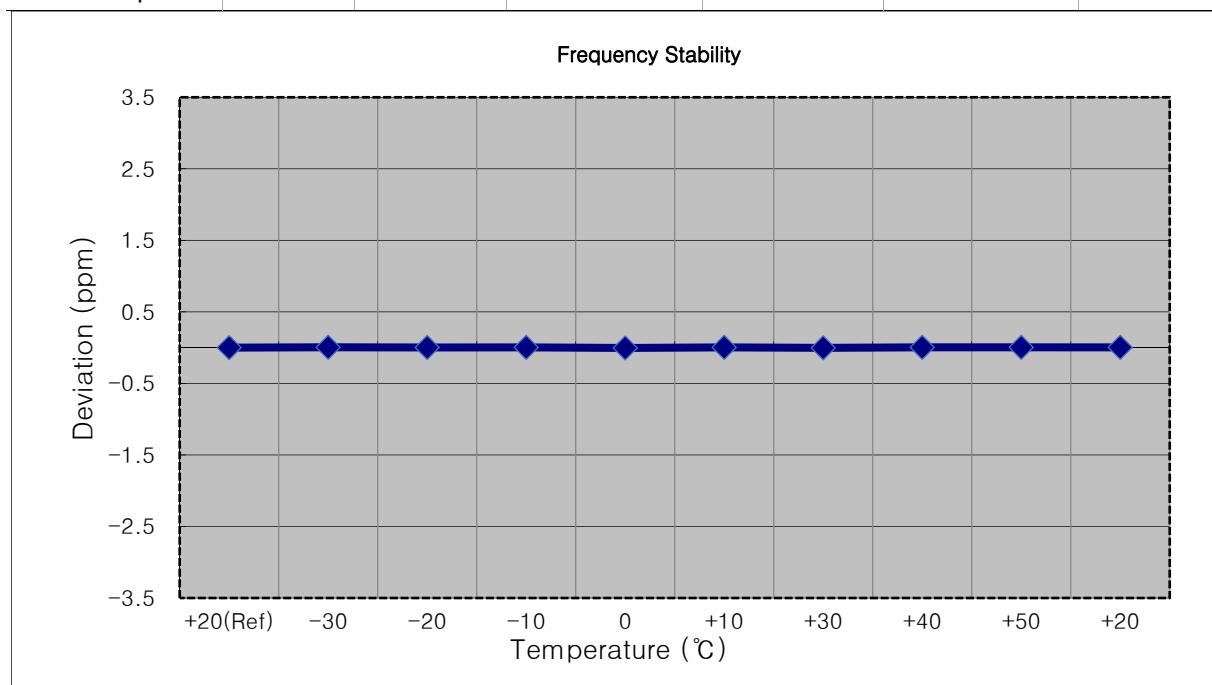
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1850,700,000 Hz
 CHANNEL: 26047 (1.4 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1850 700 009	0.0	0.000 000	0.000
100 %		-30	1850 700 002	-6.3	0.000 000	-0.003
100 %		-20	1850 700 017	8.6	0.000 000	0.005
100 %		-10	1850 700 000	-8.7	0.000 000	-0.005
100 %		0	1850 700 013	4.2	0.000 000	0.002
100 %		+10	1850 700 017	8.9	0.000 000	0.005
100 %		+30	1850 700 011	2.8	0.000 000	0.002
100 %		+40	1850 700 014	5.0	0.000 000	0.003
100 %		+50	1850 700 002	-6.7	0.000 000	-0.004
Batt. Endpoint	3.300	+20	1850 700 014	5.0	0.000 000	0.003



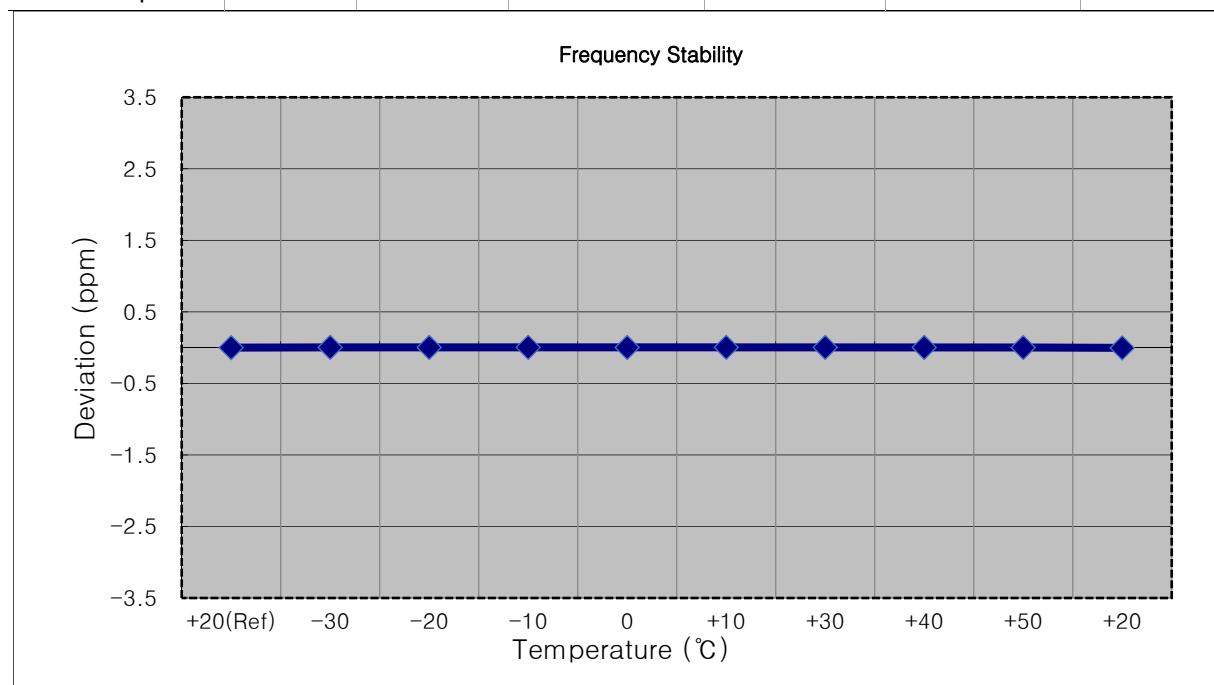
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1851,500,000 Hz
 CHANNEL: 26055 (3 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1851 499 993	0.0	0.000 000	0.000
100 %		-30	1851 500 002	9.0	0.000 000	0.005
100 %		-20	1851 499 998	4.3	0.000 000	0.002
100 %		-10	1851 500 000	6.7	0.000 000	0.004
100 %		0	1851 499 985	-8.2	0.000 000	-0.004
100 %		+10	1851 500 000	7.2	0.000 000	0.004
100 %		+30	1851 499 988	-5.4	0.000 000	-0.003
100 %		+40	1851 500 001	8.0	0.000 000	0.004
100 %		+50	1851 500 001	7.7	0.000 000	0.004
Batt. Endpoint	3.300	+20	1851 500 001	7.3	0.000 000	0.004



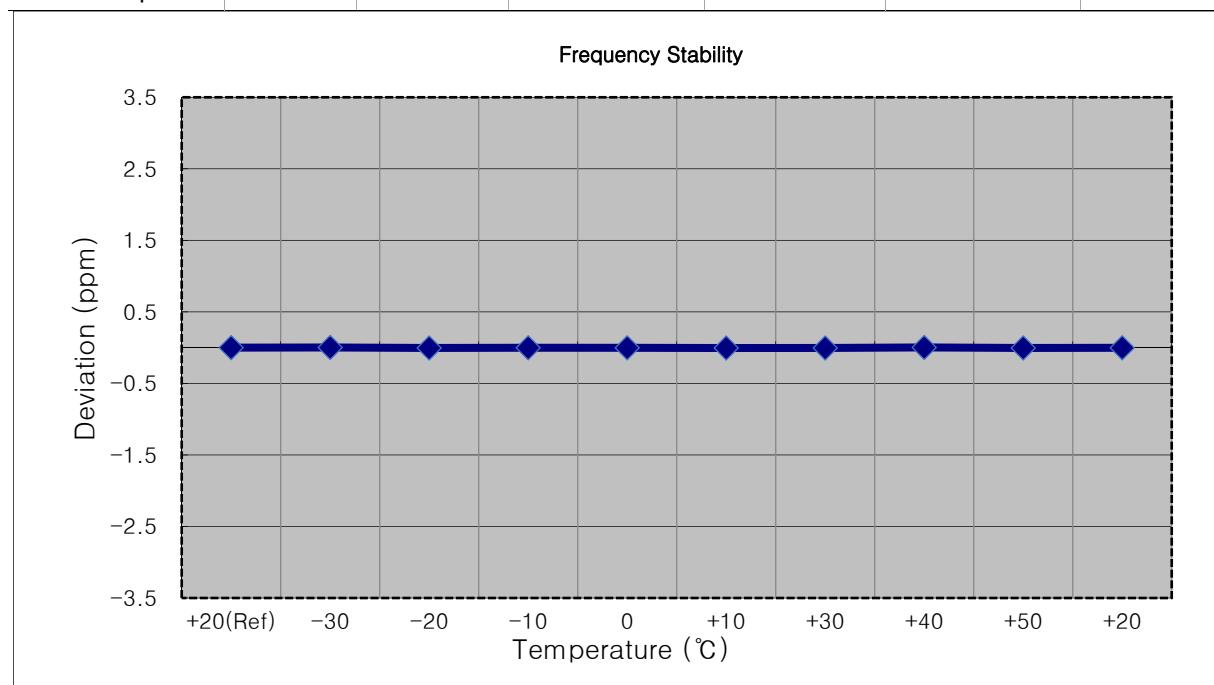
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1852,500,000 Hz
 CHANNEL: 26065 (5 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1852 500 007	0.0	0.000 000	0.000
100 %		-30	1852 500 014	7.4	0.000 000	0.004
100 %		-20	1852 500 014	6.7	0.000 000	0.004
100 %		-10	1852 500 015	8.1	0.000 000	0.004
100 %		0	1852 500 012	4.9	0.000 000	0.003
100 %		+10	1852 500 015	7.7	0.000 000	0.004
100 %		+30	1852 500 014	6.8	0.000 000	0.004
100 %		+40	1852 500 014	6.8	0.000 000	0.004
100 %		+50	1852 500 011	3.9	0.000 000	0.002
Batt. Endpoint	3.300	+20	1852 500 001	-6.2	0.000 000	-0.003



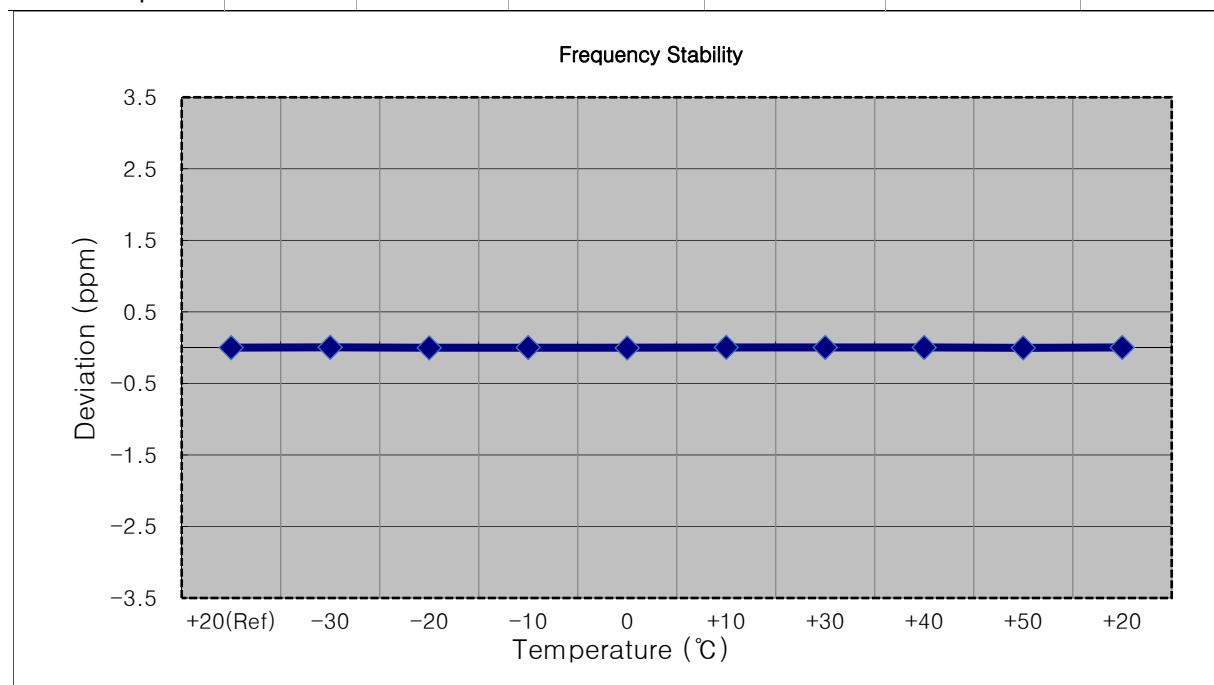
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1855,000,000 Hz
 CHANNEL: 26090 (10 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1855 000 004	0.0	0.000 000	0.000
100 %		-30	1855 000 009	4.5	0.000 000	0.002
100 %		-20	1854 999 995	-8.7	0.000 000	-0.005
100 %		-10	1855 000 001	-3.0	0.000 000	-0.002
100 %		0	1855 000 000	-3.9	0.000 000	-0.002
100 %		+10	1854 999 994	-9.6	-0.000 001	-0.005
100 %		+30	1854 999 995	-8.6	0.000 000	-0.005
100 %		+40	1855 000 009	5.4	0.000 000	0.003
100 %		+50	1854 999 996	-8.2	0.000 000	-0.004
Batt. Endpoint	3.300	+20	1855 000 000	-3.7	0.000 000	-0.002



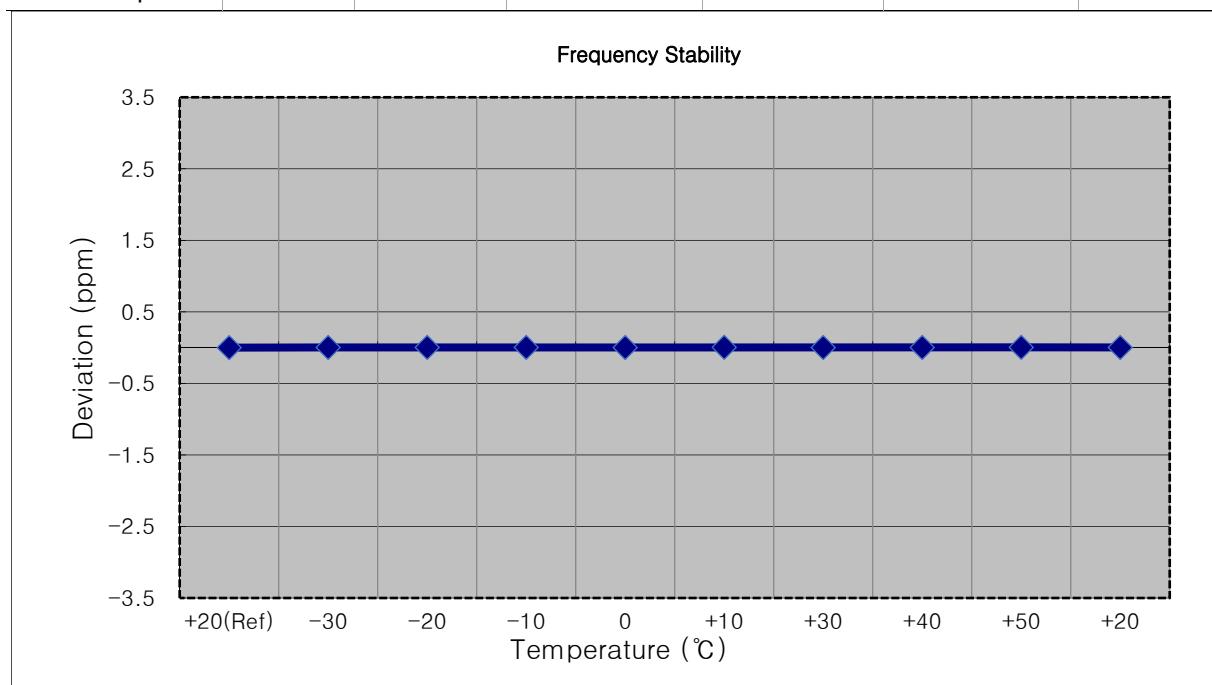
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1857,500,000 Hz
 CHANNEL: 26115 (15 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1857 499 994	0.0	0.000 000	0.000
100 %		-30	1857 500 003	8.7	0.000 000	0.005
100 %		-20	1857 499 990	-4.5	0.000 000	-0.002
100 %		-10	1857 499 997	3.0	0.000 000	0.002
100 %		0	1857 499 987	-7.0	0.000 000	-0.004
100 %		+10	1857 500 003	8.6	0.000 000	0.005
100 %		+30	1857 499 999	4.7	0.000 000	0.003
100 %		+40	1857 500 000	5.4	0.000 000	0.003
100 %		+50	1857 499 989	-5.0	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1857 499 999	5.1	0.000 000	0.003



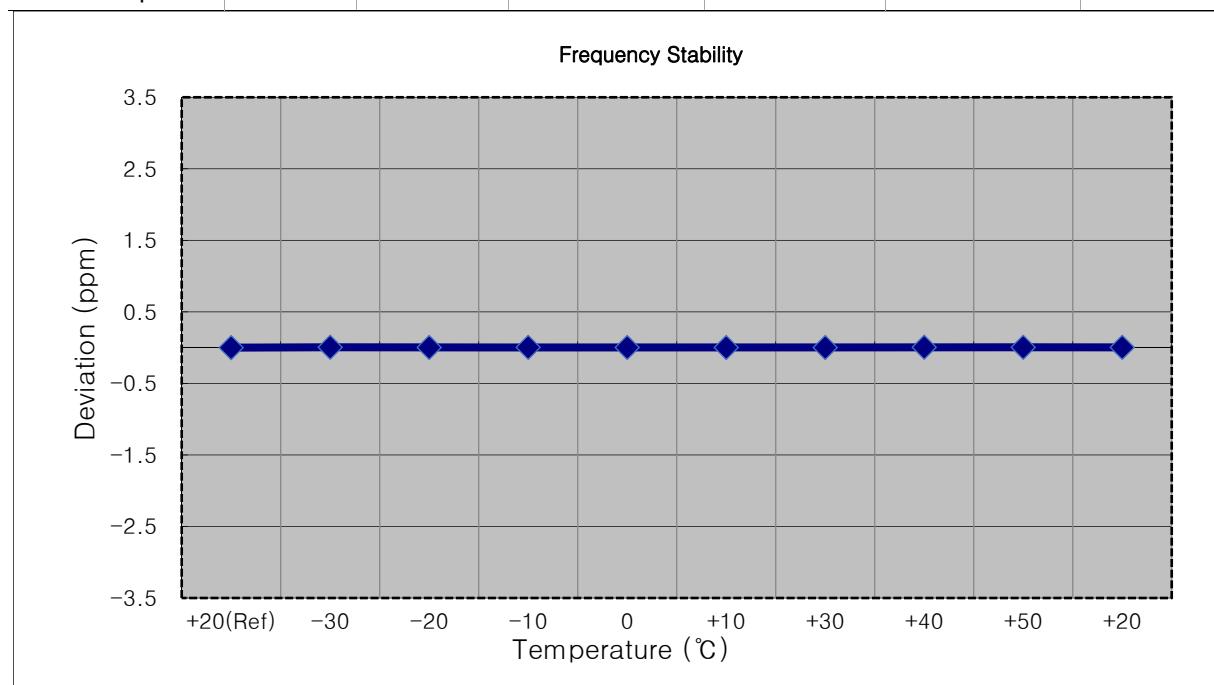
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1860,000,000 Hz
 CHANNEL: 26140 (20 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1859 999 993	0.0	0.000 000	0.000
100 %		-30	1859 999 998	5.3	0.000 000	0.003
100 %		-20	1859 999 999	6.1	0.000 000	0.003
100 %		-10	1859 999 999	5.6	0.000 000	0.003
100 %		0	1859 999 997	4.1	0.000 000	0.002
100 %		+10	1860 000 002	8.7	0.000 000	0.005
100 %		+30	1859 999 997	3.6	0.000 000	0.002
100 %		+40	1859 999 997	4.2	0.000 000	0.002
100 %		+50	1860 000 001	7.8	0.000 000	0.004
Batt. Endpoint	3.300	+20	1859 999 998	4.9	0.000 000	0.003



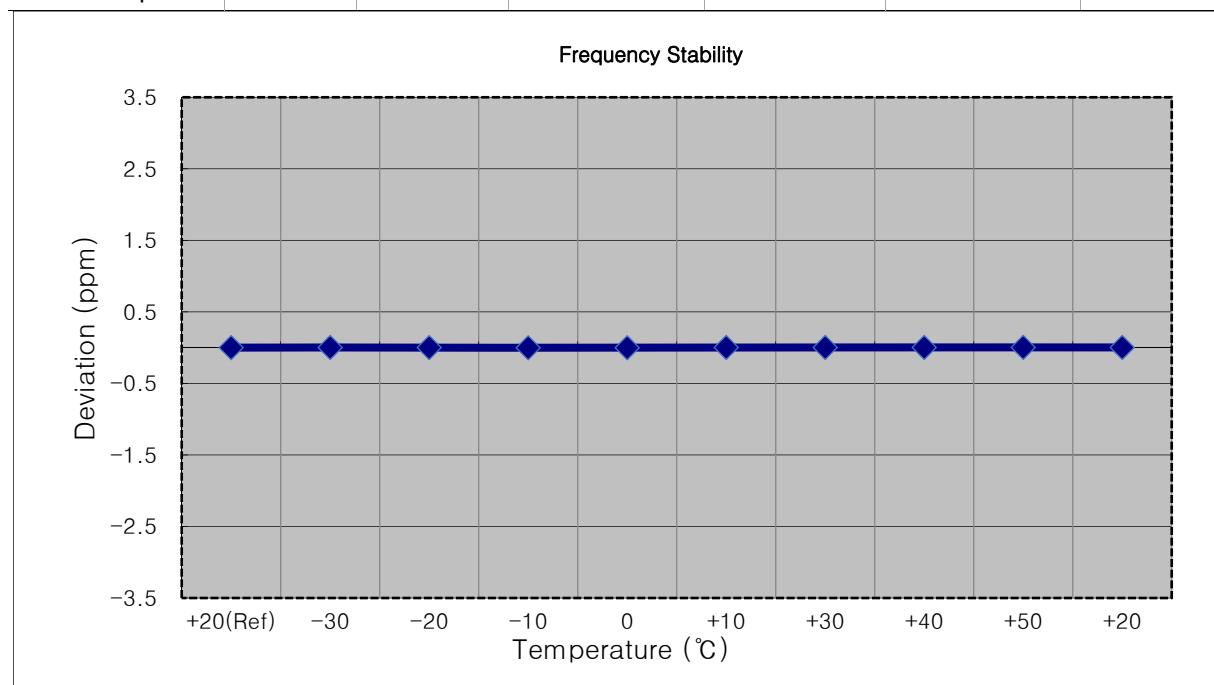
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (1.4 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 005	0.0	0.000 000	0.000
100 %		-30	1882 500 015	10.1	0.000 001	0.005
100 %		-20	1882 500 009	4.4	0.000 000	0.002
100 %		-10	1882 500 012	7.0	0.000 000	0.004
100 %		0	1882 500 010	5.1	0.000 000	0.003
100 %		+10	1882 500 009	3.6	0.000 000	0.002
100 %		+30	1882 500 009	3.5	0.000 000	0.002
100 %		+40	1882 500 015	9.9	0.000 001	0.005
100 %		+50	1882 500 014	9.1	0.000 000	0.005
Batt. Endpoint	3.300	+20	1882 500 012	7.4	0.000 000	0.004



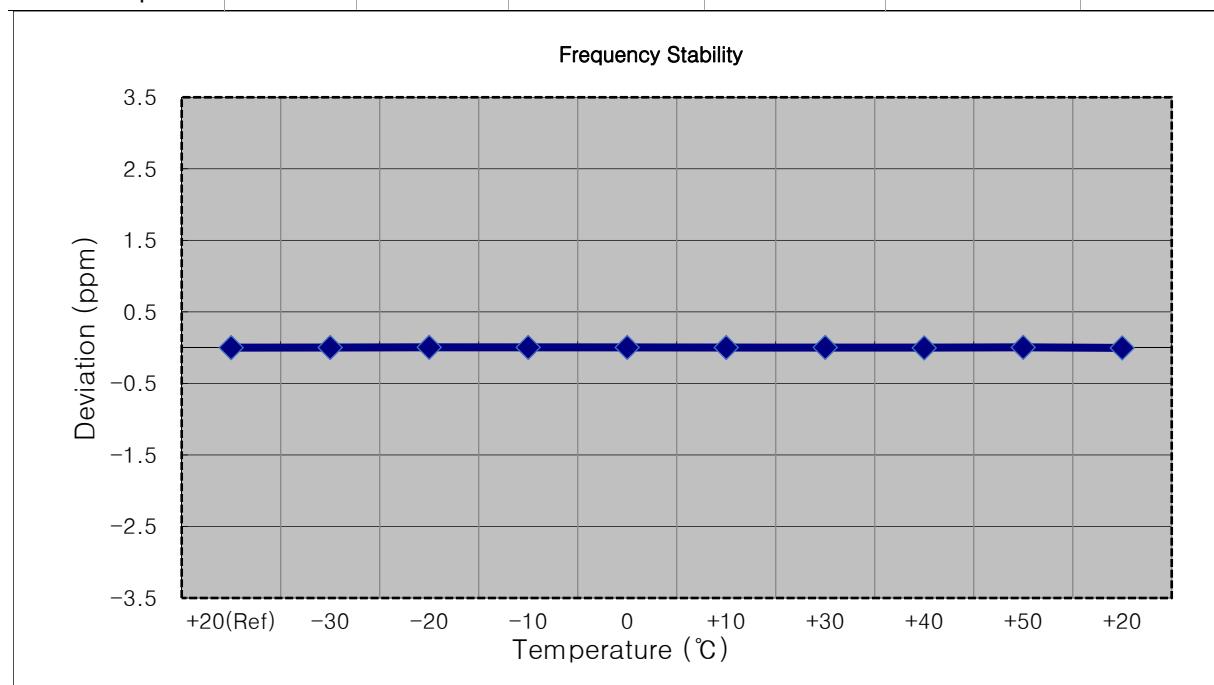
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (3 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 499 998	0.0	0.000 000	0.000
100 %		-30	1882 500 002	4.7	0.000 000	0.002
100 %		-20	1882 500 000	2.6	0.000 000	0.001
100 %		-10	1882 499 993	-4.1	0.000 000	-0.002
100 %		0	1882 499 995	-2.4	0.000 000	-0.001
100 %		+10	1882 500 003	5.4	0.000 000	0.003
100 %		+30	1882 500 002	4.6	0.000 000	0.002
100 %		+40	1882 500 003	5.2	0.000 000	0.003
100 %		+50	1882 500 004	6.5	0.000 000	0.003
Batt. Endpoint	3.300	+20	1882 500 003	5.2	0.000 000	0.003



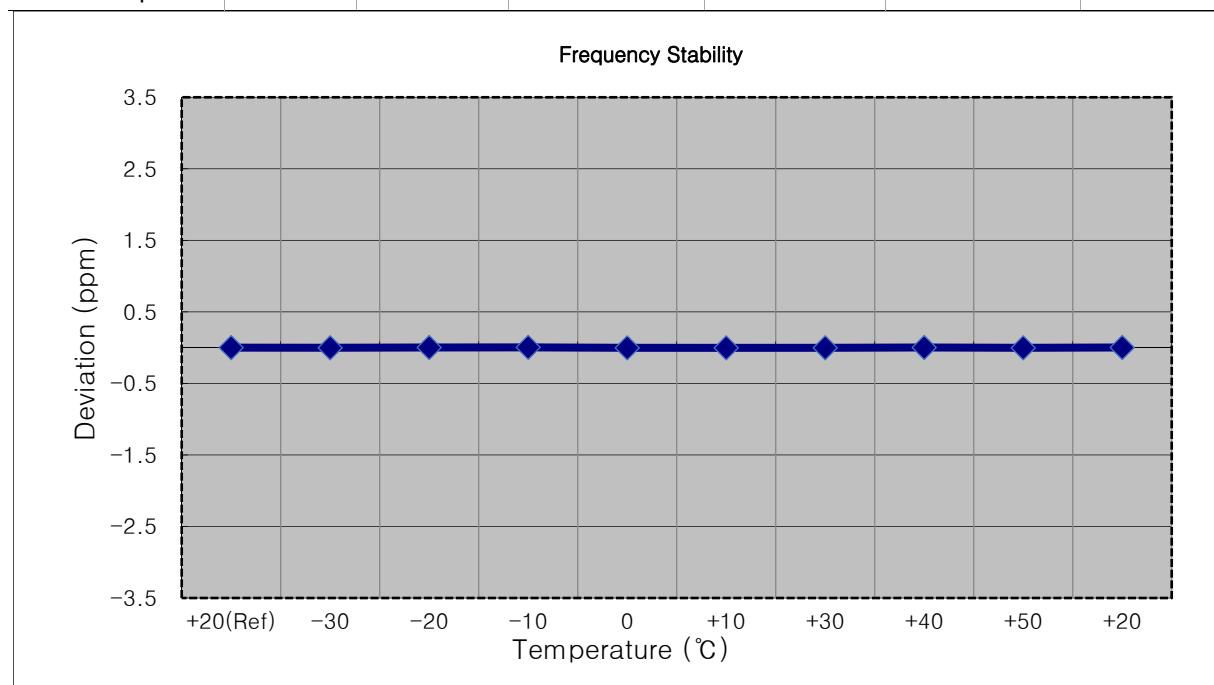
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (5 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 006	0.0	0.000 000	0.000
100 %		-30	1882 500 009	3.3	0.000 000	0.002
100 %		-20	1882 500 015	8.8	0.000 000	0.005
100 %		-10	1882 500 013	6.9	0.000 000	0.004
100 %		0	1882 500 012	5.8	0.000 000	0.003
100 %		+10	1882 500 009	3.5	0.000 000	0.002
100 %		+30	1882 500 012	5.6	0.000 000	0.003
100 %		+40	1882 500 000	-6.3	0.000 000	-0.003
100 %		+50	1882 500 014	8.1	0.000 000	0.004
Batt. Endpoint	3.300	+20	1882 499 999	-6.5	0.000 000	-0.003



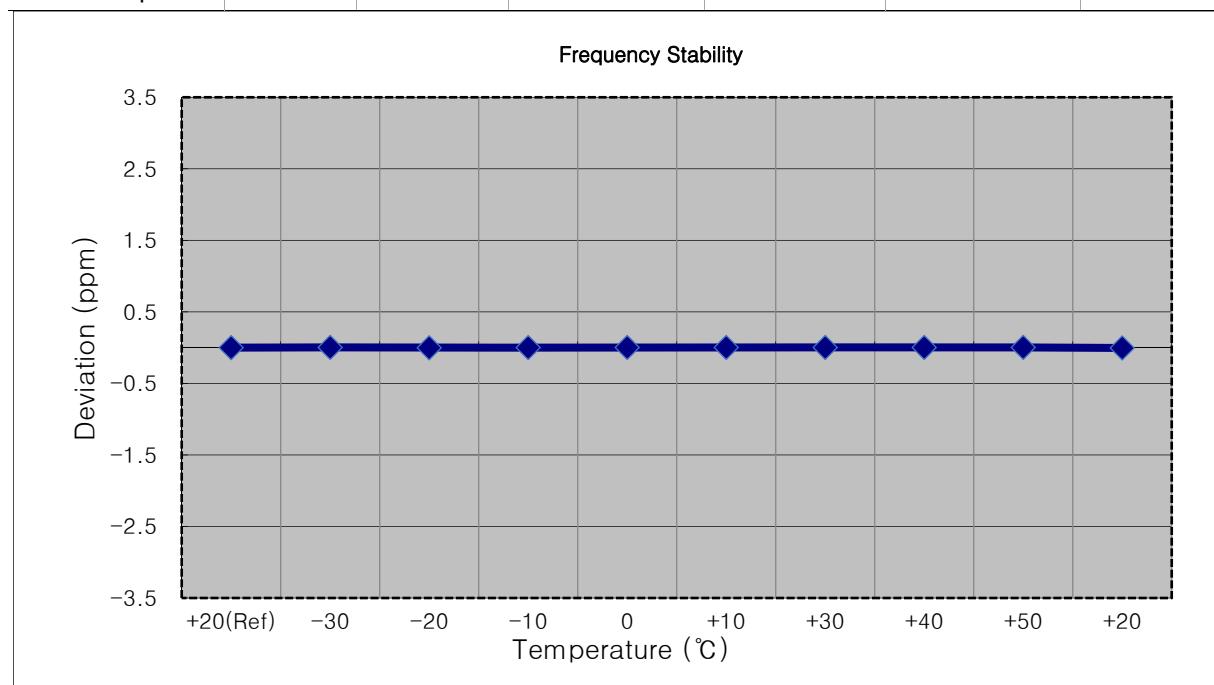
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (10 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 499 999	-3.1	0.000 000	-0.002
100 %		-20	1882 500 006	3.9	0.000 000	0.002
100 %		-10	1882 500 010	7.3	0.000 000	0.004
100 %		0	1882 499 998	-4.6	0.000 000	-0.002
100 %		+10	1882 499 997	-5.3	0.000 000	-0.003
100 %		+30	1882 499 999	-4.0	0.000 000	-0.002
100 %		+40	1882 500 007	4.1	0.000 000	0.002
100 %		+50	1882 499 998	-4.3	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1882 500 006	3.9	0.000 000	0.002



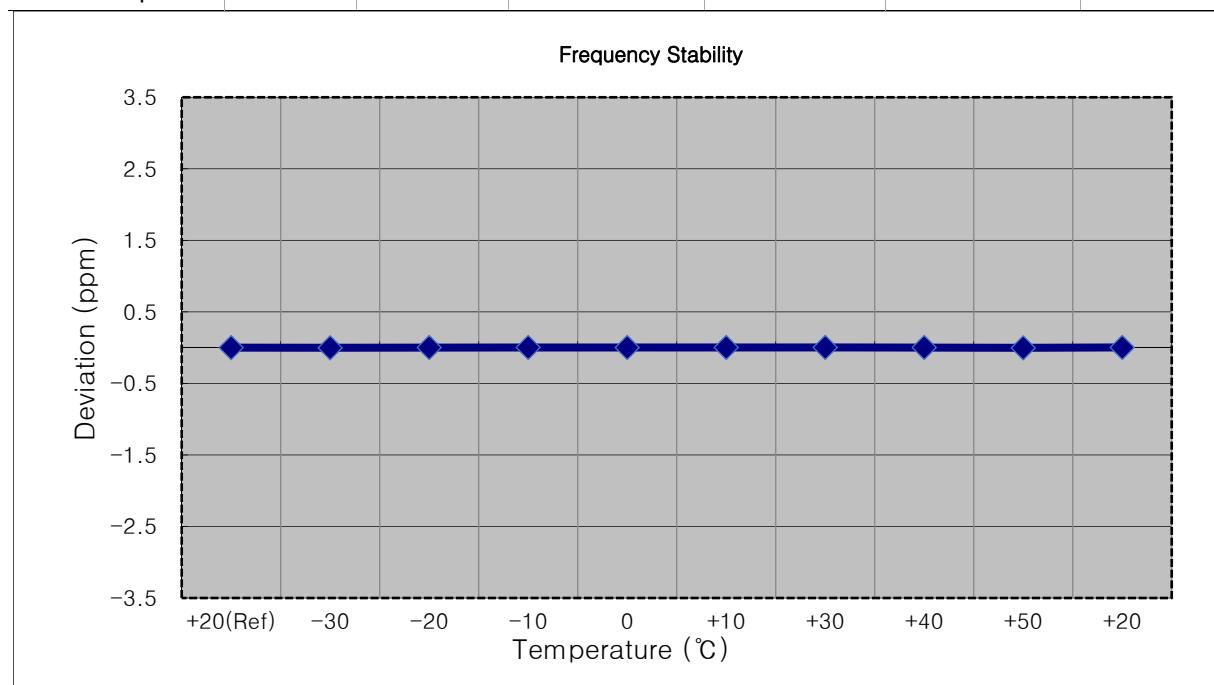
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (15 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 005	0.0	0.000 000	0.000
100 %		-30	1882 500 012	6.5	0.000 000	0.003
100 %		-20	1882 500 002	-3.4	0.000 000	-0.002
100 %		-10	1882 500 007	1.9	0.000 000	0.001
100 %		0	1882 500 010	5.1	0.000 000	0.003
100 %		+10	1882 500 010	5.2	0.000 000	0.003
100 %		+30	1882 500 010	4.5	0.000 000	0.002
100 %		+40	1882 500 010	4.9	0.000 000	0.003
100 %		+50	1882 500 011	5.8	0.000 000	0.003
Batt. Endpoint	3.300	+20	1882 499 997	-7.8	0.000 000	-0.004



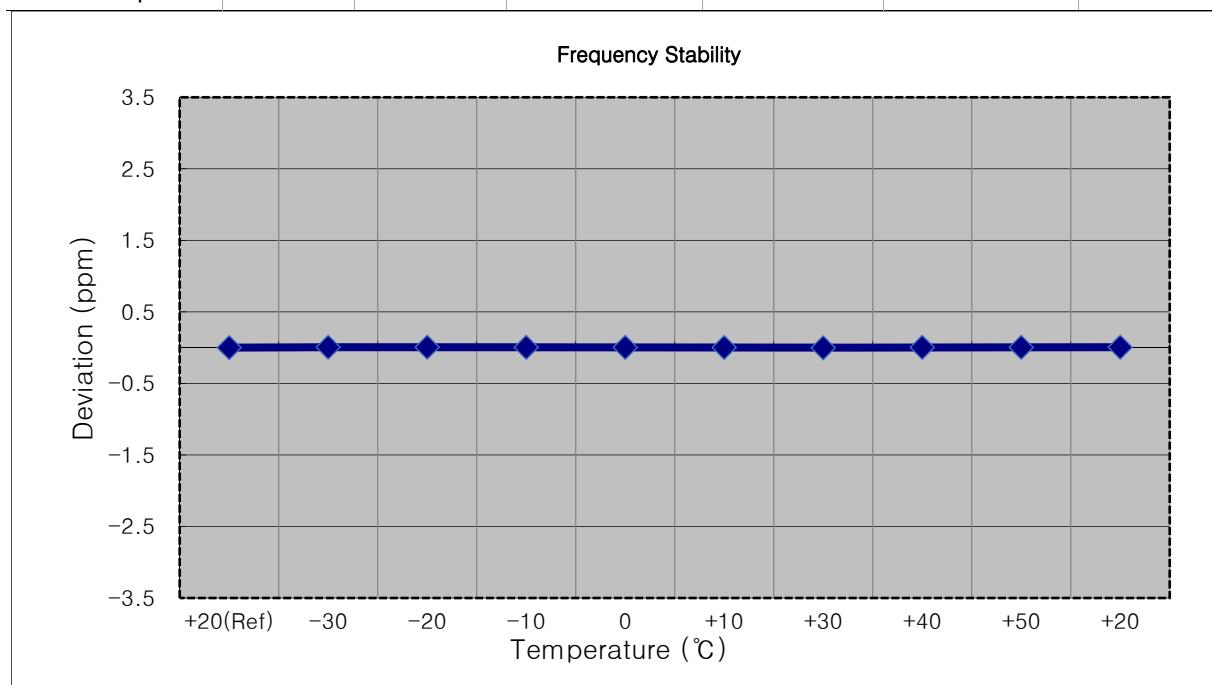
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1882,500,000 Hz
 CHANNEL: 26365 (20 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1882 500 004	0.0	0.000 000	0.000
100 %		-30	1882 500 000	-3.4	0.000 000	-0.002
100 %		-20	1882 500 008	4.1	0.000 000	0.002
100 %		-10	1882 500 008	4.7	0.000 000	0.002
100 %		0	1882 500 007	3.3	0.000 000	0.002
100 %		+10	1882 500 008	4.4	0.000 000	0.002
100 %		+30	1882 500 010	6.1	0.000 000	0.003
100 %		+40	1882 500 008	4.2	0.000 000	0.002
100 %		+50	1882 499 999	-4.4	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1882 500 009	5.2	0.000 000	0.003



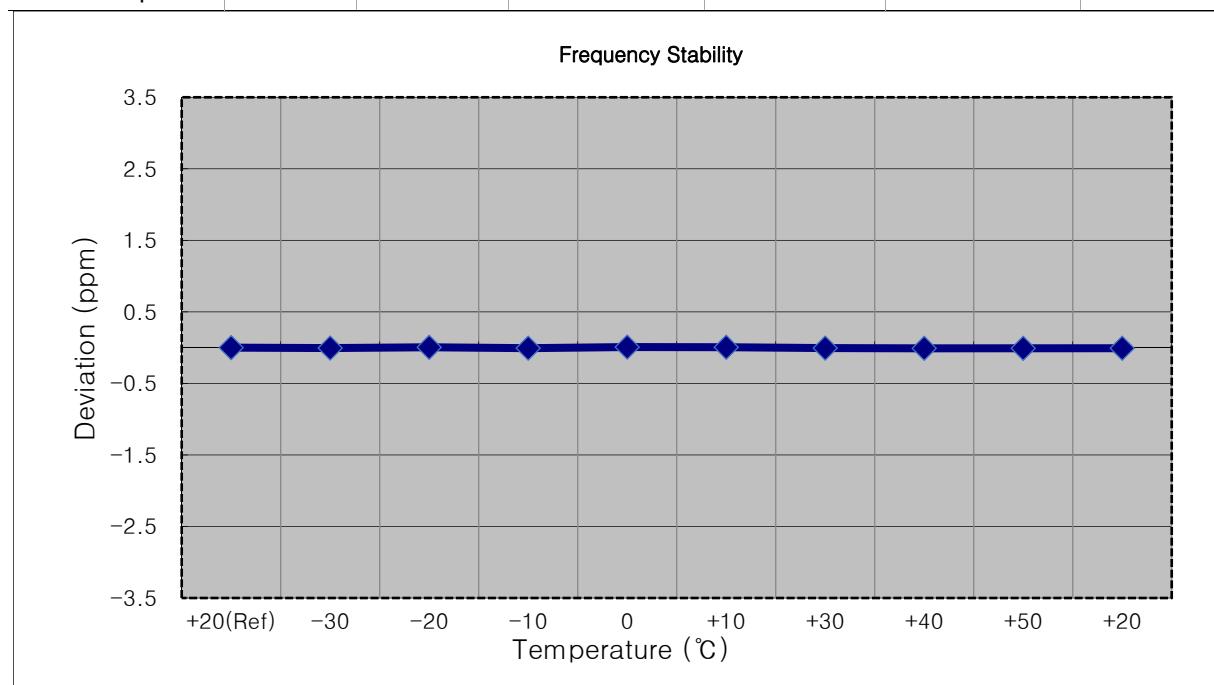
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1914,300,000 Hz
 CHANNEL: 26683 (1.4 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1914 300 012	0.0	0.000 000	0.000
100 %		-30	1914 300 024	11.5	0.000 001	0.006
100 %		-20	1914 300 025	12.3	0.000 001	0.006
100 %		-10	1914 300 020	7.5	0.000 000	0.004
100 %		0	1914 300 020	7.2	0.000 000	0.004
100 %		+10	1914 300 017	4.4	0.000 000	0.002
100 %		+30	1914 300 009	-3.4	0.000 000	-0.002
100 %		+40	1914 300 020	7.7	0.000 000	0.004
100 %		+50	1914 300 020	8.0	0.000 000	0.004
Batt. Endpoint	3.300	+20	1914 300 024	11.5	0.000 001	0.006



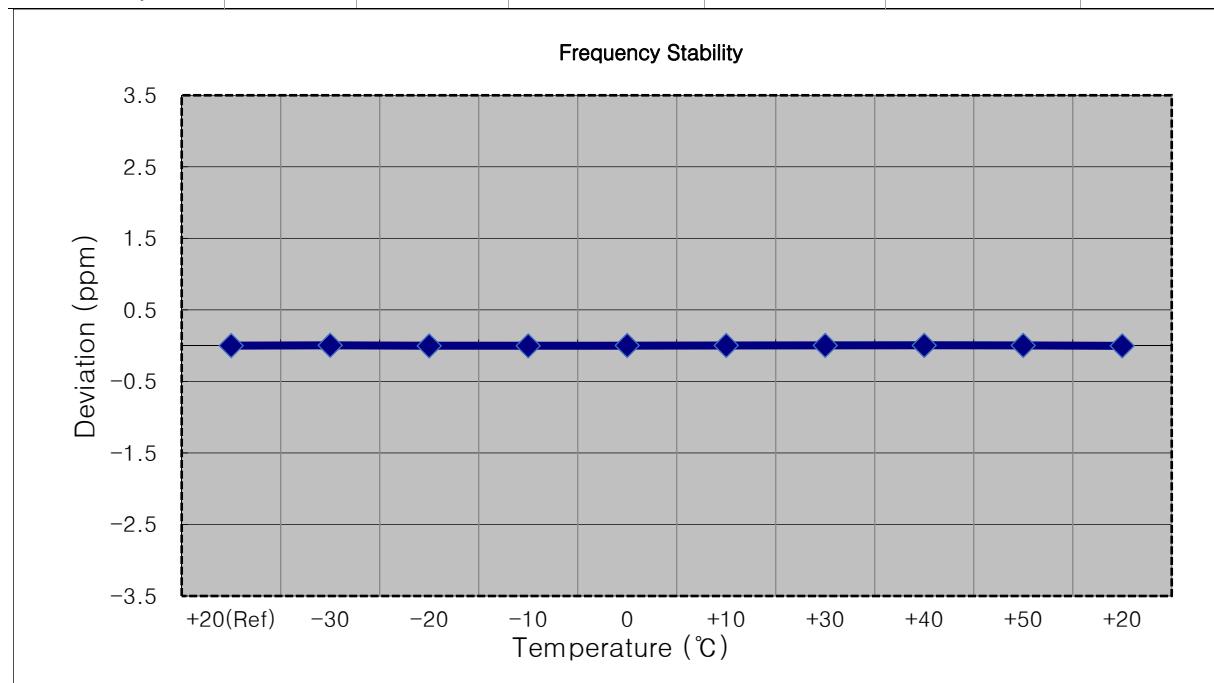
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1913,500,000 Hz
 CHANNEL: 26675 (3 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1913 500 009	0.0	0.000 000	0.000
100 %		-30	1913 499 998	-11.2	-0.000 001	-0.006
100 %		-20	1913 500 018	9.5	0.000 000	0.005
100 %		-10	1913 499 995	-14.0	-0.000 001	-0.007
100 %		0	1913 500 024	15.1	0.000 001	0.008
100 %		+10	1913 500 020	10.8	0.000 001	0.006
100 %		+30	1913 499 997	-11.9	-0.000 001	-0.006
100 %		+40	1913 499 990	-18.5	-0.000 001	-0.010
100 %		+50	1913 499 991	-17.6	-0.000 001	-0.009
Batt. Endpoint	3.300	+20	1913 499 993	-15.7	-0.000 001	-0.008



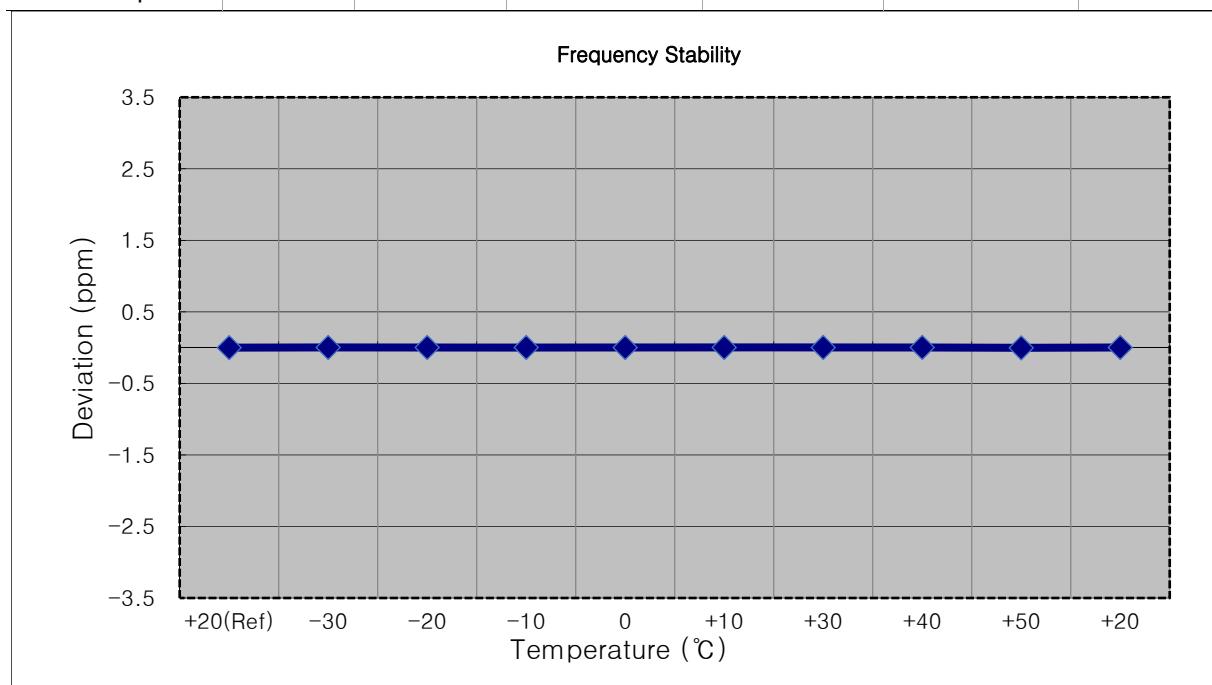
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1912,500,000 Hz
 CHANNEL: 26665 (5 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1912 499 994	0.0	0.000 000	0.000
100 %		-30	1912 500 003	9.1	0.000 000	0.005
100 %		-20	1912 499 988	-6.1	0.000 000	-0.003
100 %		-10	1912 499 989	-5.4	0.000 000	-0.003
100 %		0	1912 500 000	5.6	0.000 000	0.003
100 %		+10	1912 499 999	4.8	0.000 000	0.003
100 %		+30	1912 500 000	6.2	0.000 000	0.003
100 %		+40	1912 500 000	6.4	0.000 000	0.003
100 %		+50	1912 500 000	6.0	0.000 000	0.003
Batt. Endpoint	3.300	+20	1912 499 989	-5.2	0.000 000	-0.003



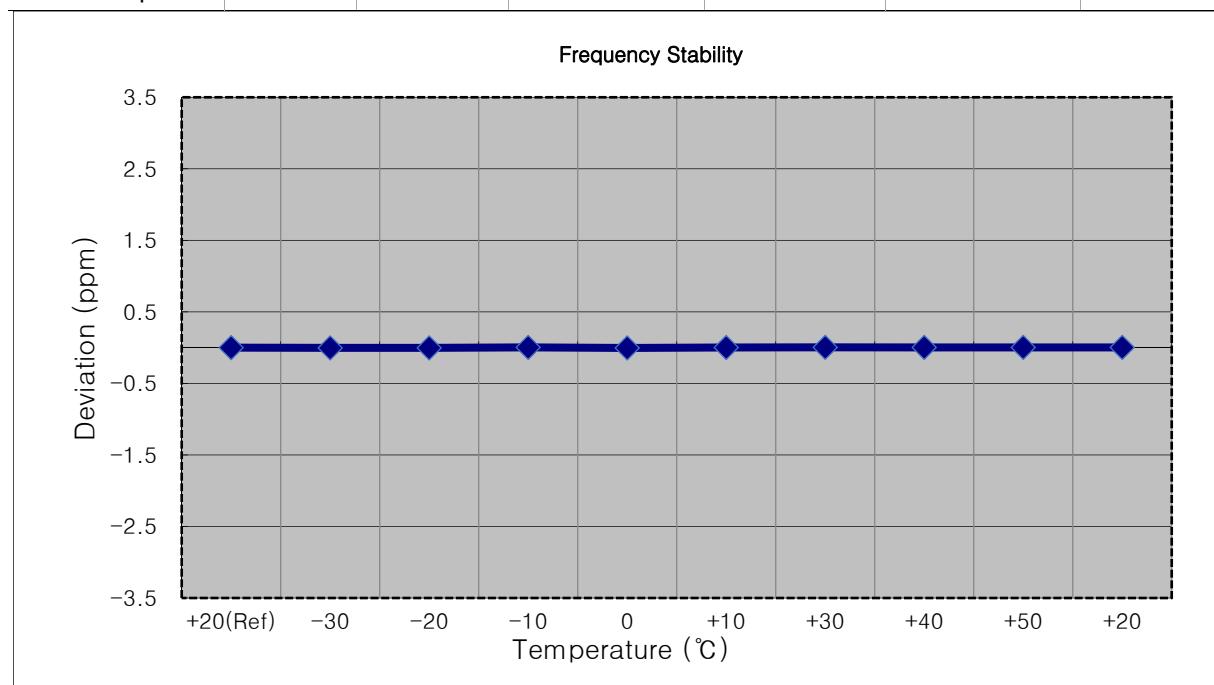
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1910,000,000 Hz
 CHANNEL: 26640 (10 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1909 999 995	0.0	0.000 000	0.000
100 %		-30	1910 000 000	5.2	0.000 000	0.003
100 %		-20	1910 000 000	4.4	0.000 000	0.002
100 %		-10	1910 000 000	4.5	0.000 000	0.002
100 %		0	1909 999 999	3.8	0.000 000	0.002
100 %		+10	1910 000 000	4.5	0.000 000	0.002
100 %		+30	1910 000 000	5.2	0.000 000	0.003
100 %		+40	1910 000 002	6.5	0.000 000	0.003
100 %		+50	1909 999 991	-4.5	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1910 000 000	4.4	0.000 000	0.002



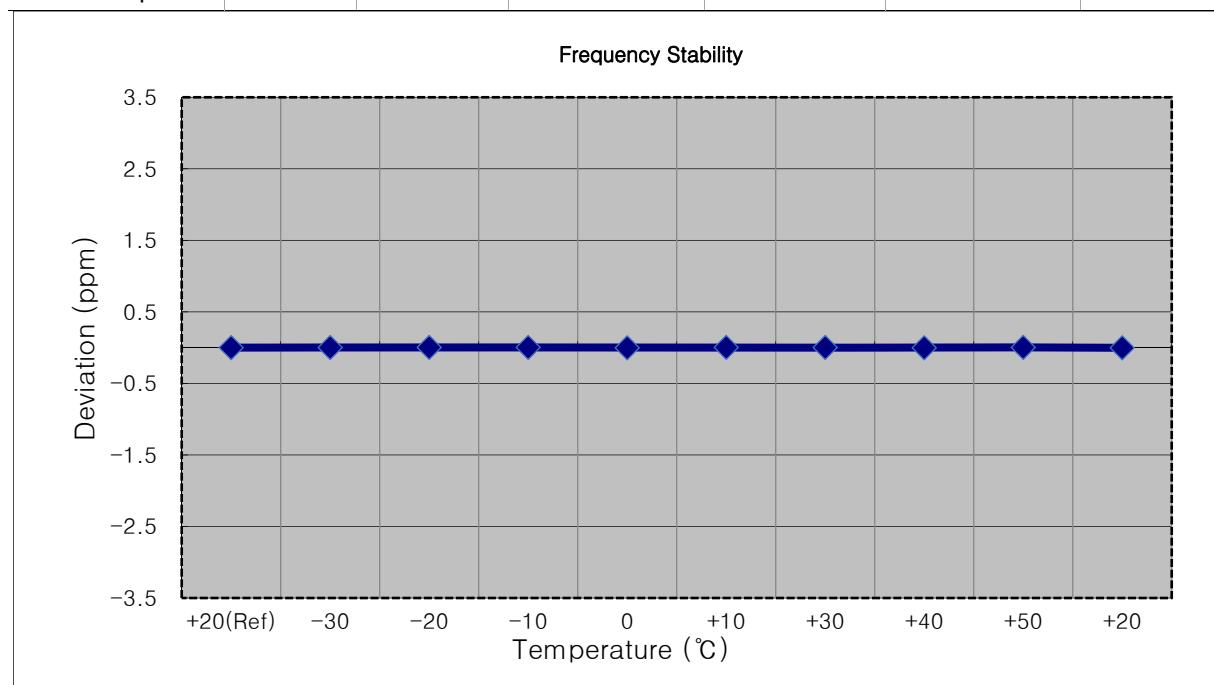
- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1907,500,000 Hz
 CHANNEL: 26615 (15 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1907 500 007	0.0	0.000 000	0.000
100 %		-30	1907 500 001	-5.8	0.000 000	-0.003
100 %		-20	1907 500 001	-6.0	0.000 000	-0.003
100 %		-10	1907 500 014	6.6	0.000 000	0.003
100 %		0	1907 499 999	-8.4	0.000 000	-0.004
100 %		+10	1907 500 011	4.2	0.000 000	0.002
100 %		+30	1907 500 015	7.8	0.000 000	0.004
100 %		+40	1907 500 013	5.8	0.000 000	0.003
100 %		+50	1907 500 013	6.0	0.000 000	0.003
Batt. Endpoint	3.300	+20	1907 500 013	5.8	0.000 000	0.003



- MODE: LTE B25/B2
 OPERATING FREQUENCY: 1905,000,000 Hz
 CHANNEL: 26590 (20 MHz)
 REFERENCE VOLTAGE: 3.880 VDC
 DEVIATION LIMIT: Emission must remain in band

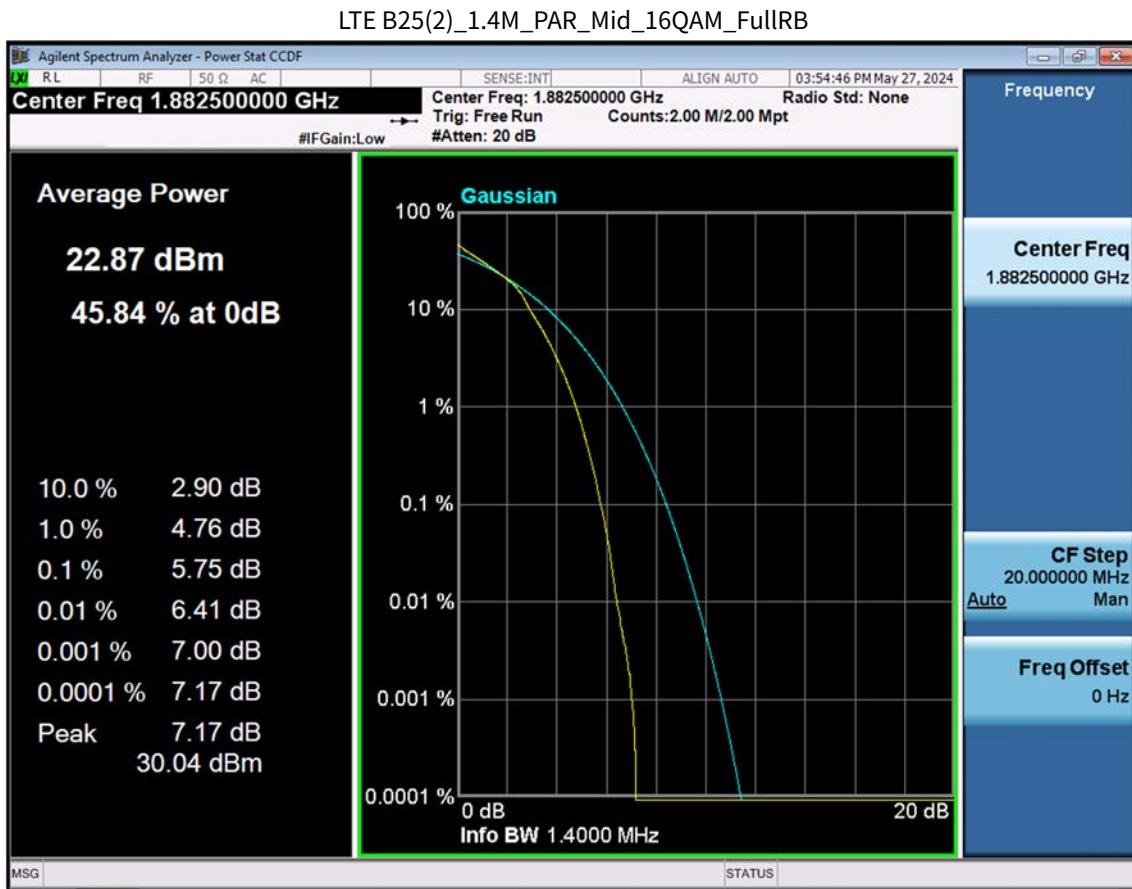
Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1905 000 004	0.0	0.000 000	0.000
100 %		-30	1905 000 008	3.8	0.000 000	0.002
100 %		-20	1905 000 010	5.9	0.000 000	0.003
100 %		-10	1905 000 010	6.4	0.000 000	0.003
100 %		0	1905 000 000	-4.2	0.000 000	-0.002
100 %		+10	1905 000 010	6.0	0.000 000	0.003
100 %		+30	1905 000 008	4.4	0.000 000	0.002
100 %		+40	1905 000 000	-3.9	0.000 000	-0.002
100 %		+50	1905 000 010	6.6	0.000 000	0.003
Batt. Endpoint	3.300	+20	1905 000 000	-4.3	0.000 000	-0.002

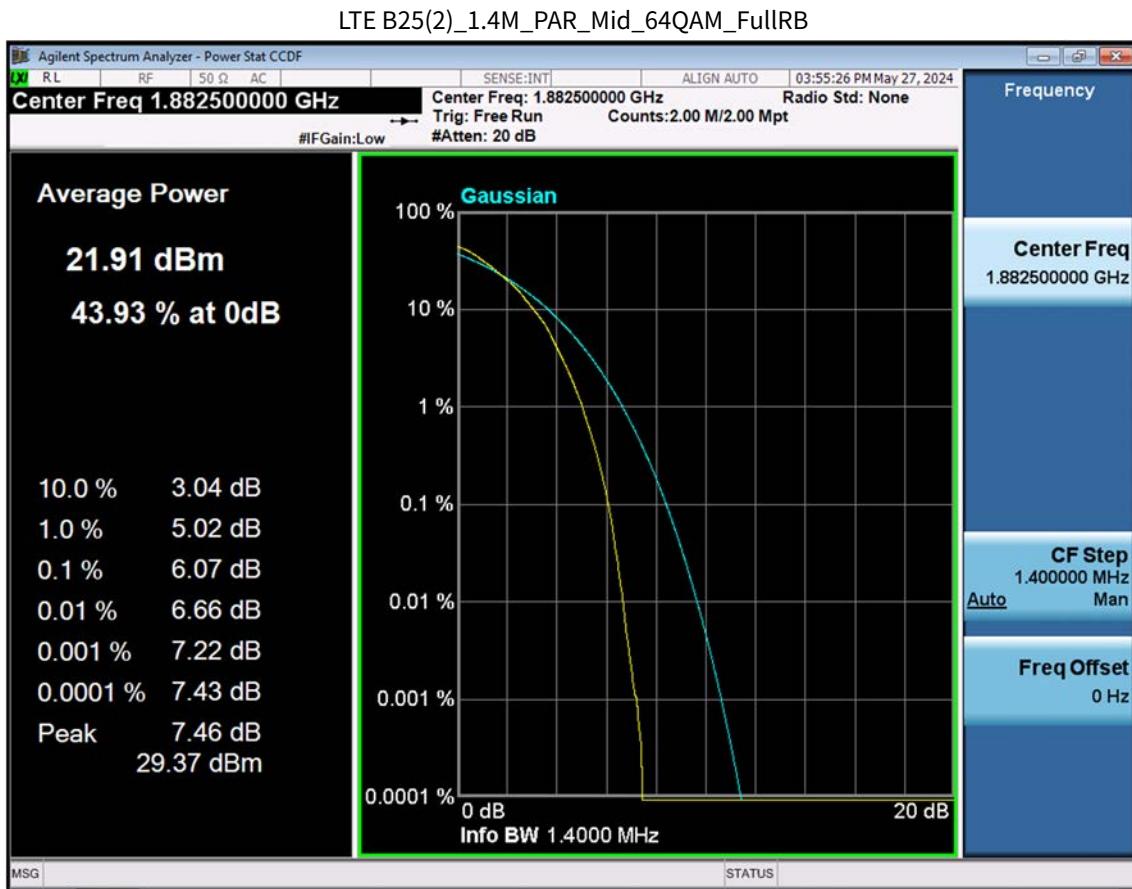


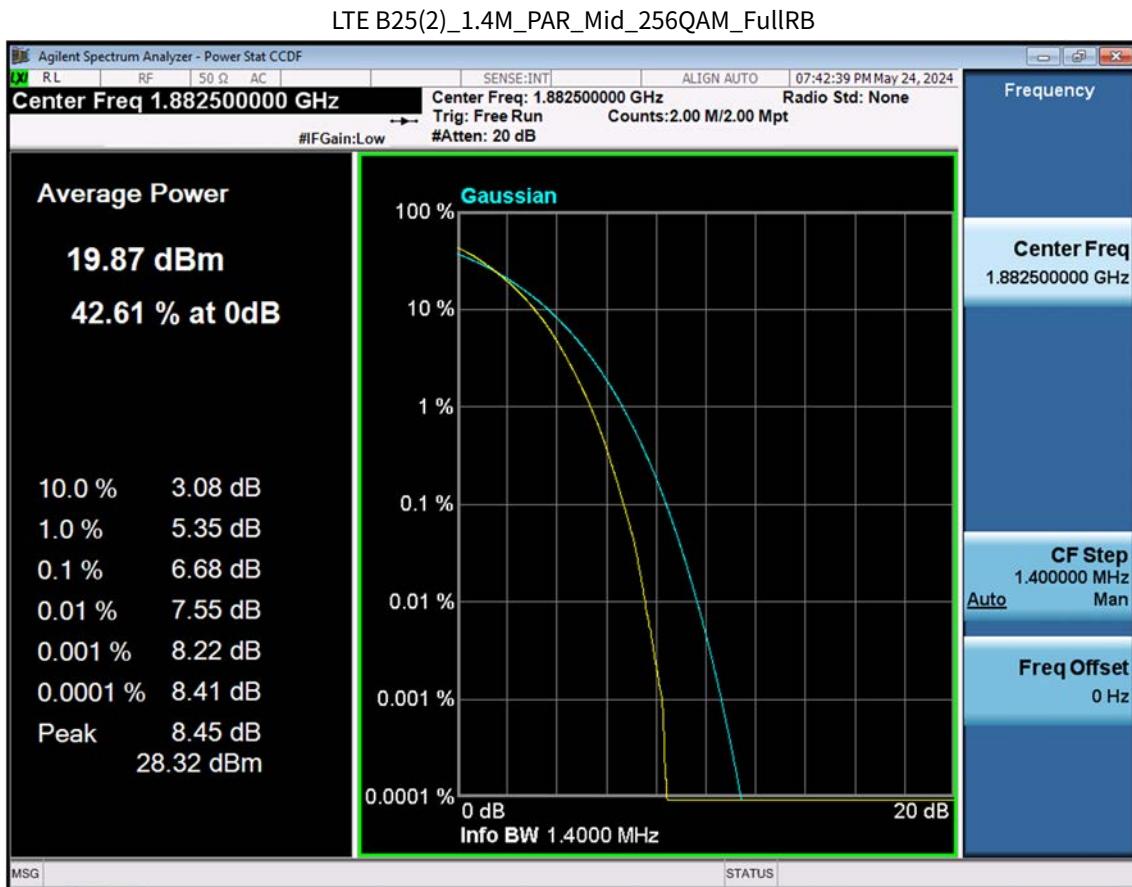
10. TEST PLOTS(Main 1 Ant)

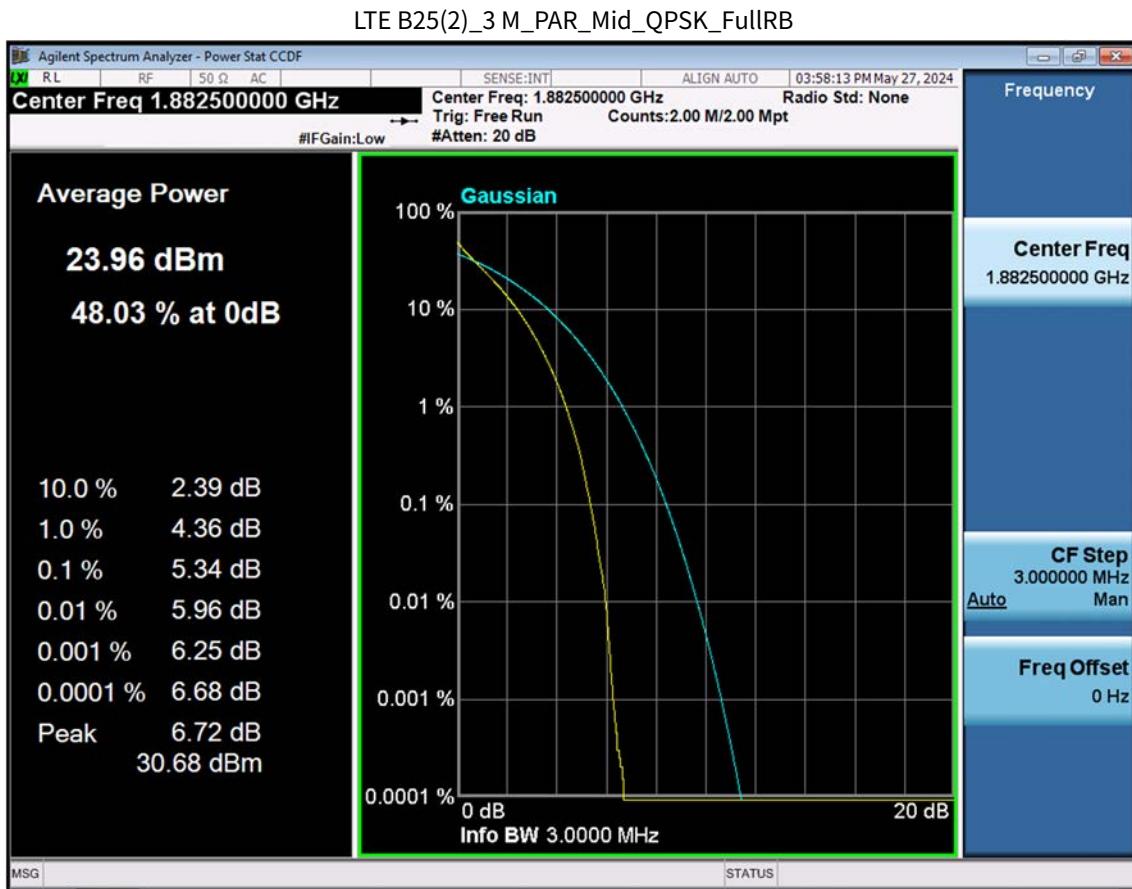
LTE B25(2)_1.4M_PAR_Mid_QPSK_FullRB

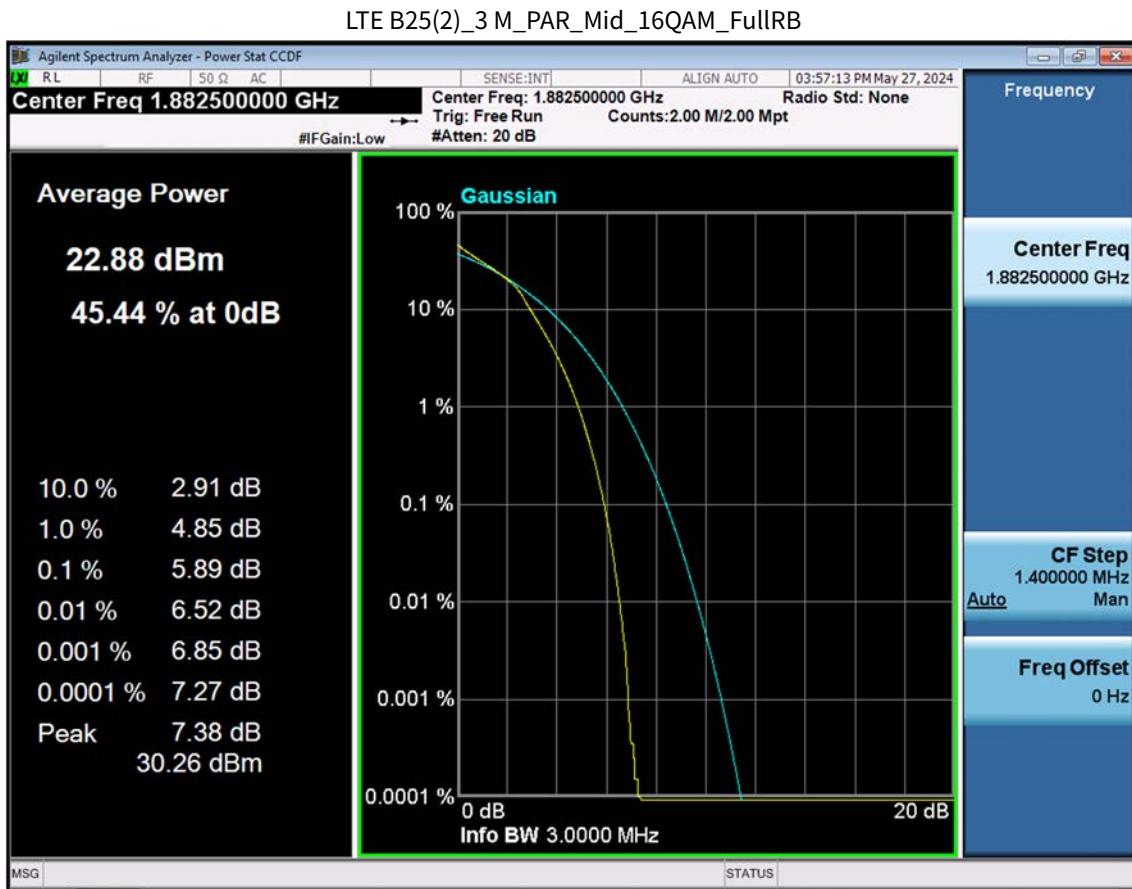


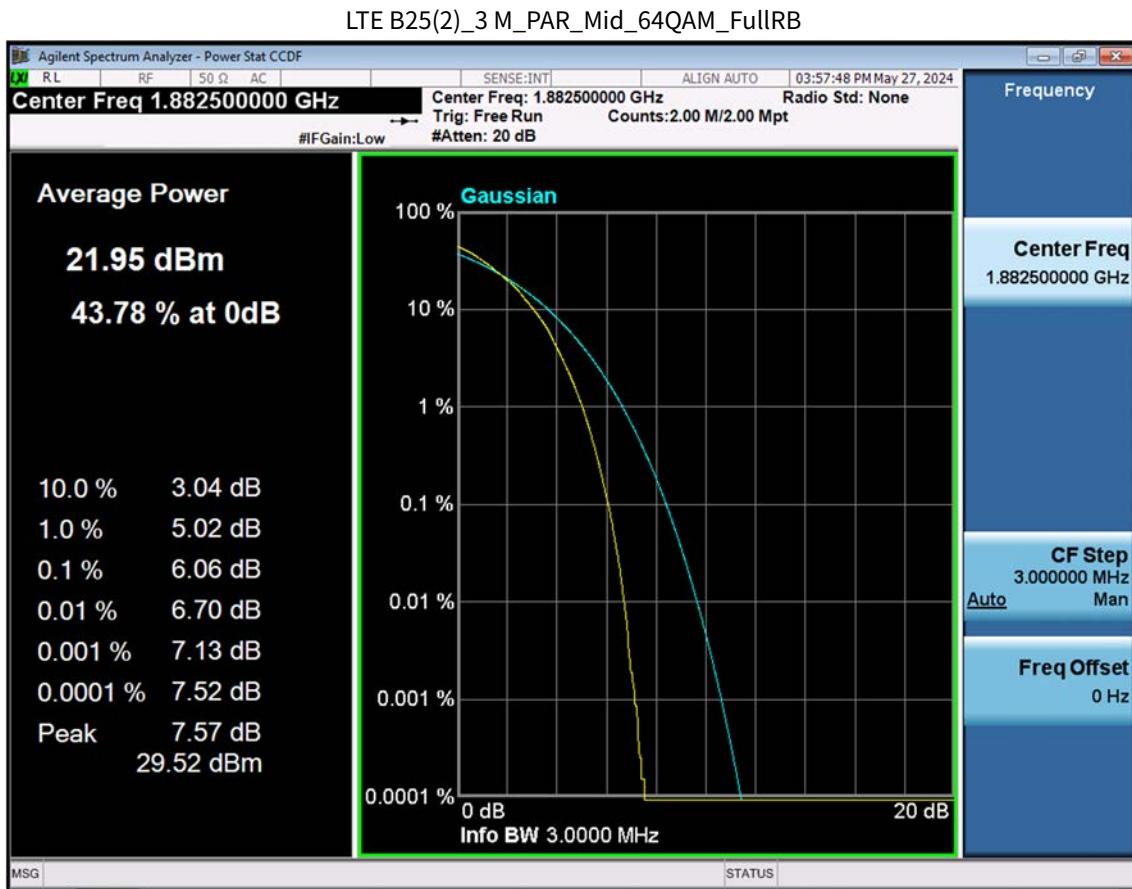


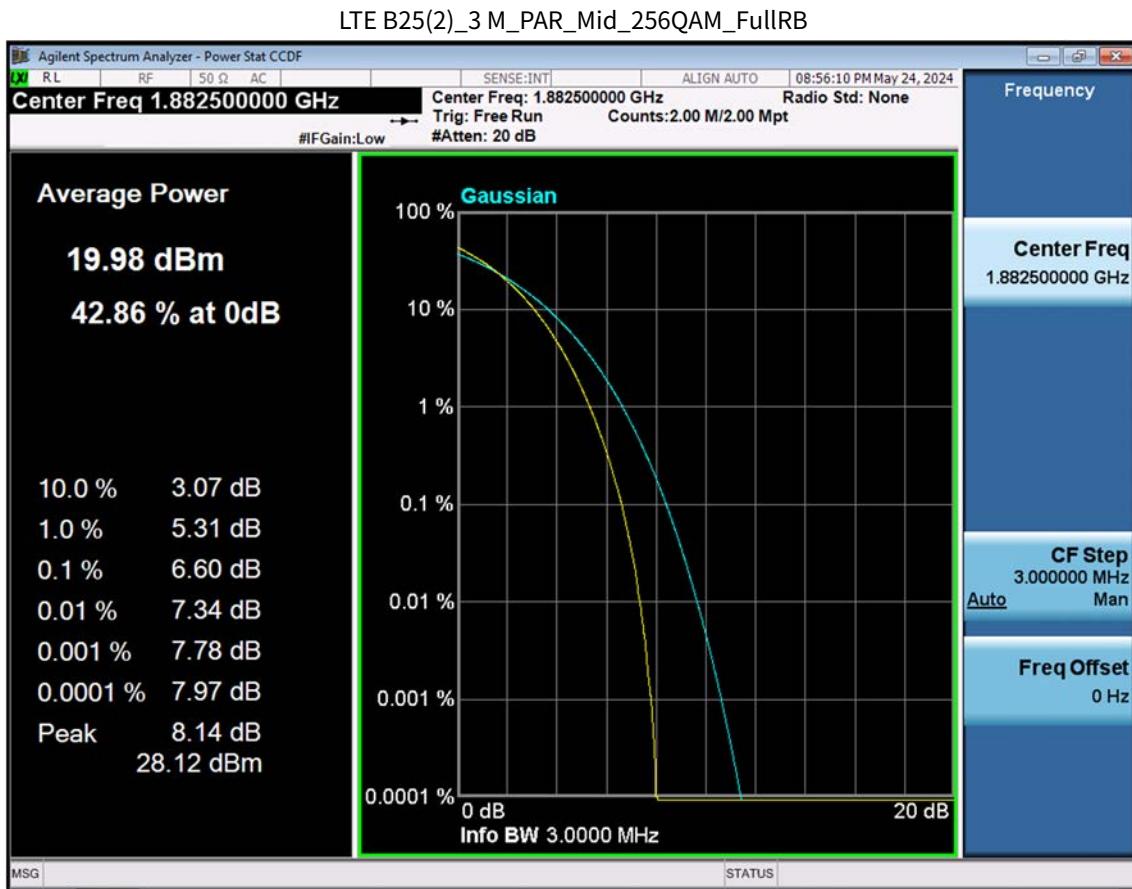


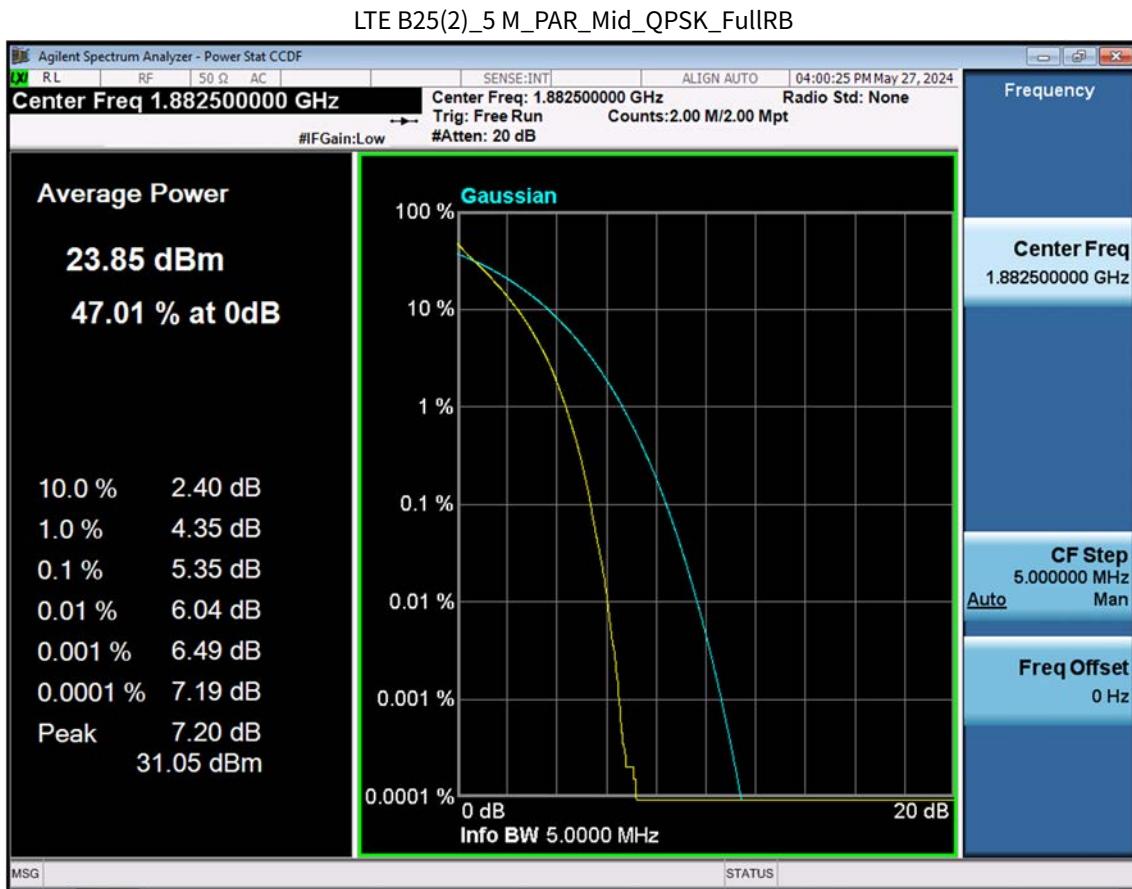


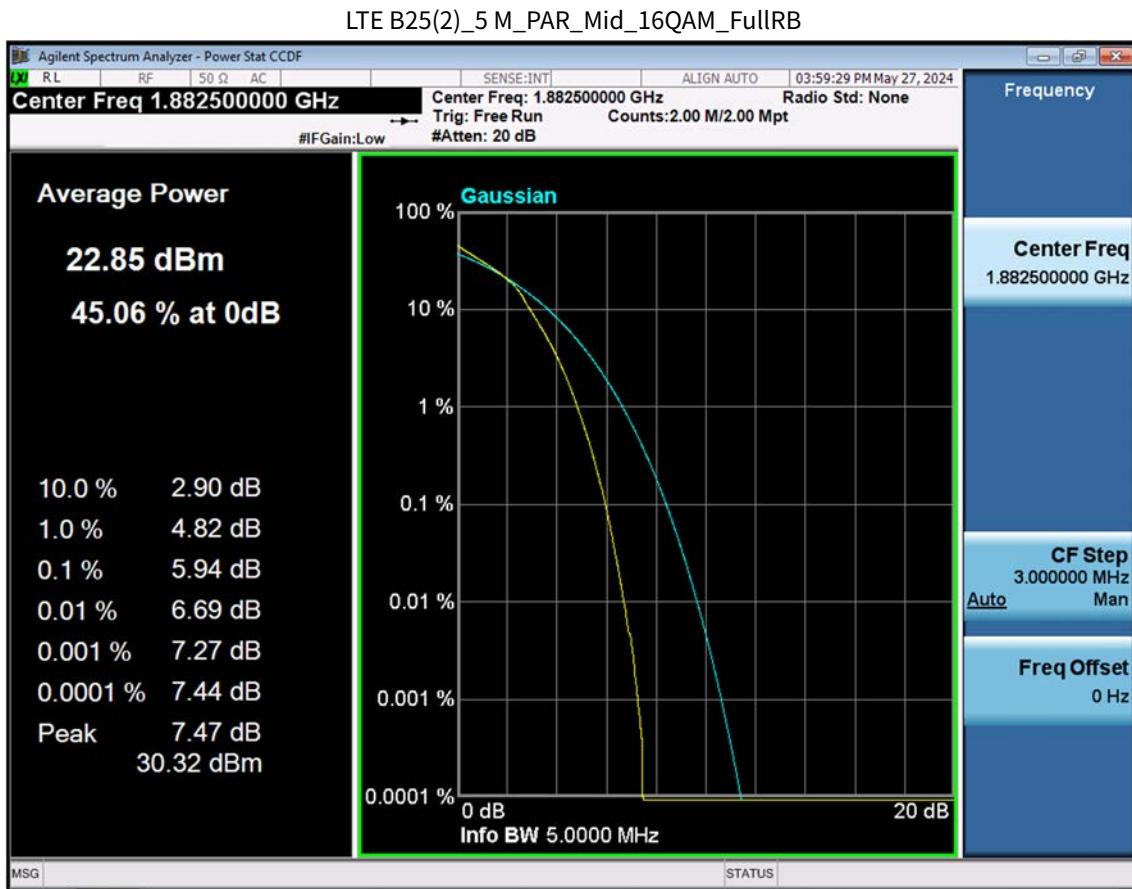


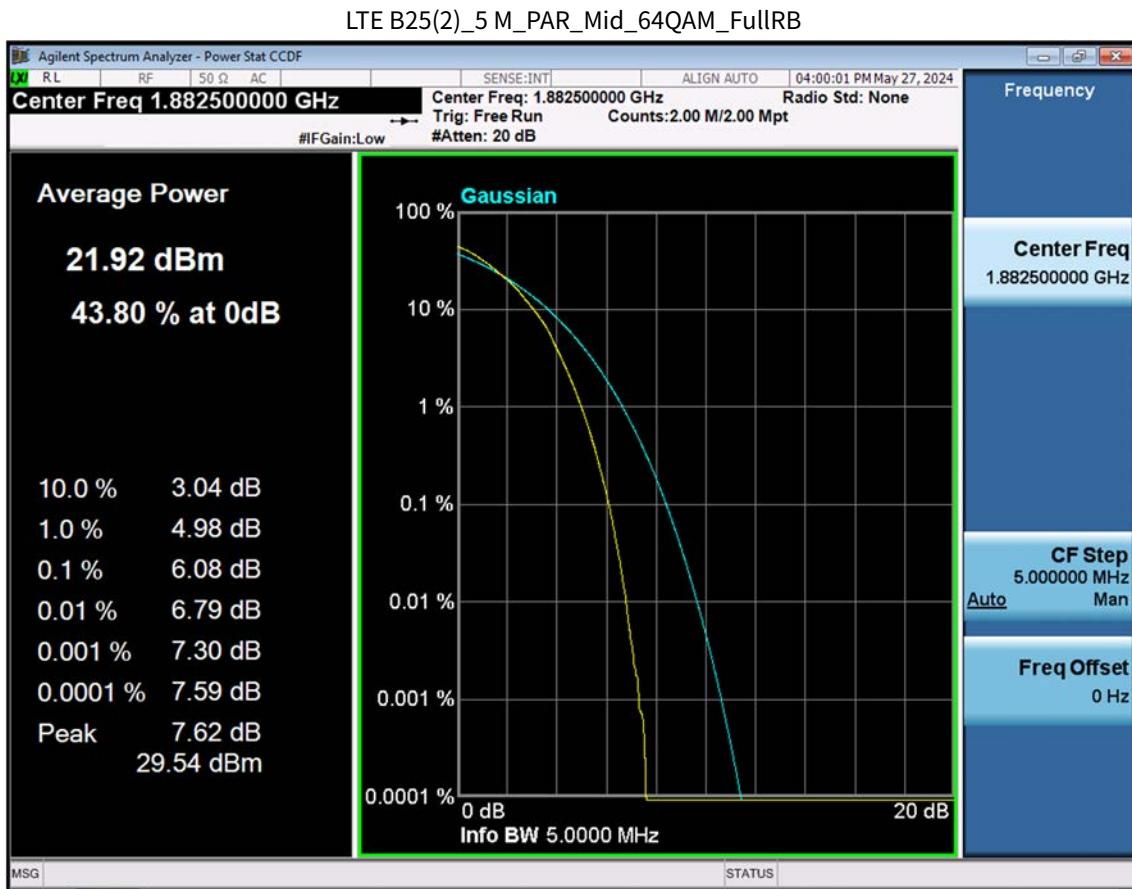


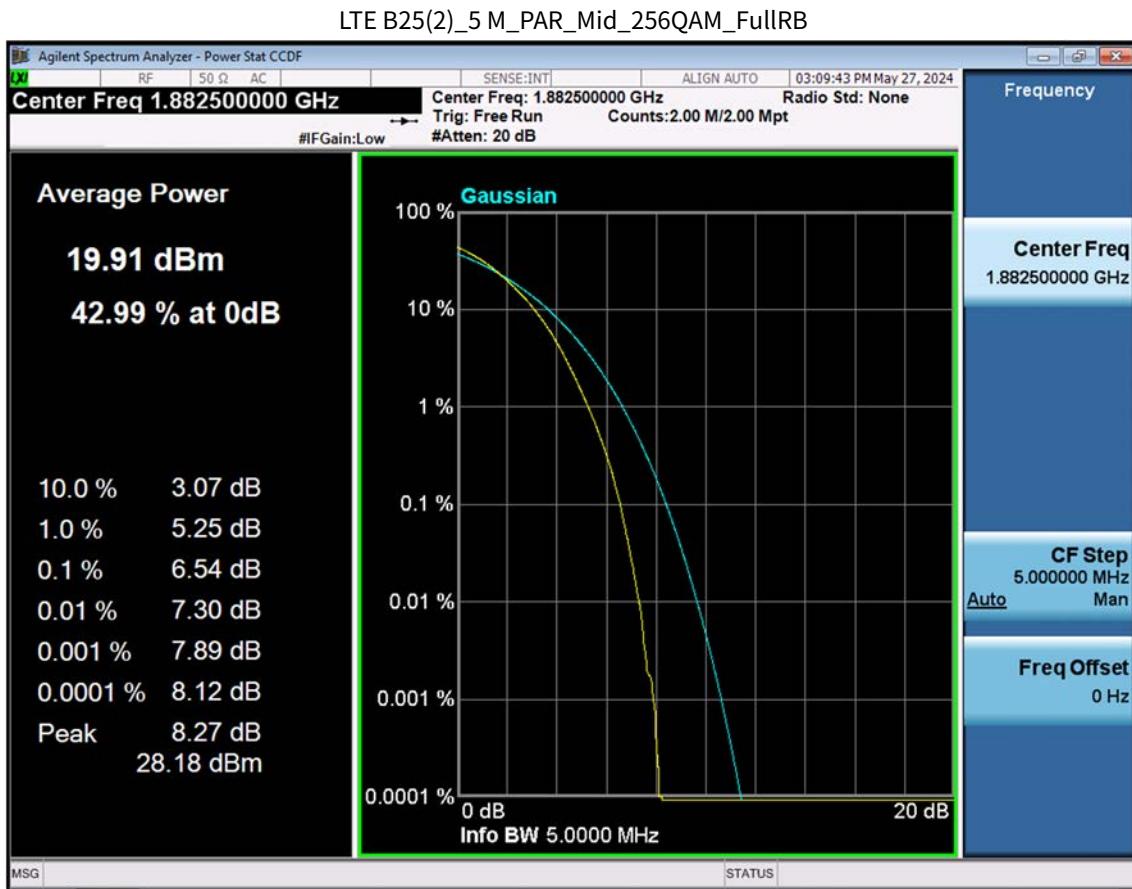


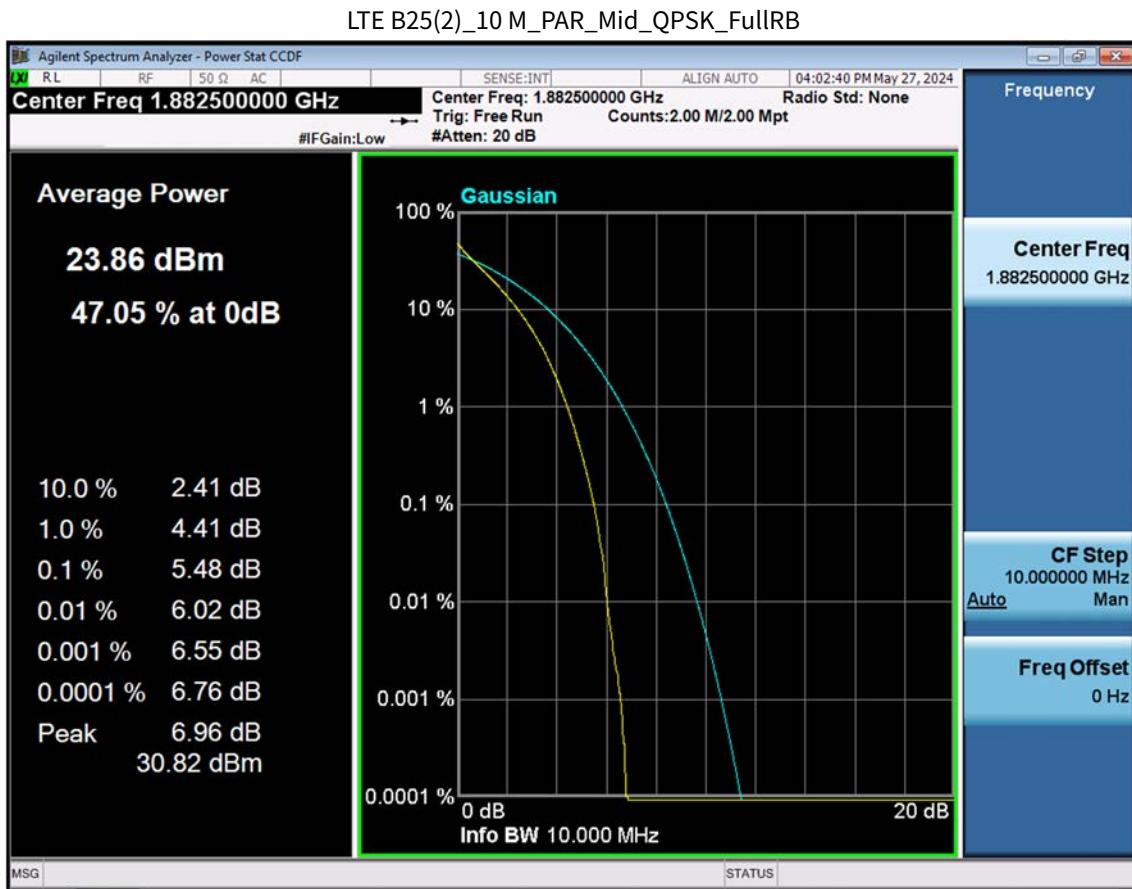




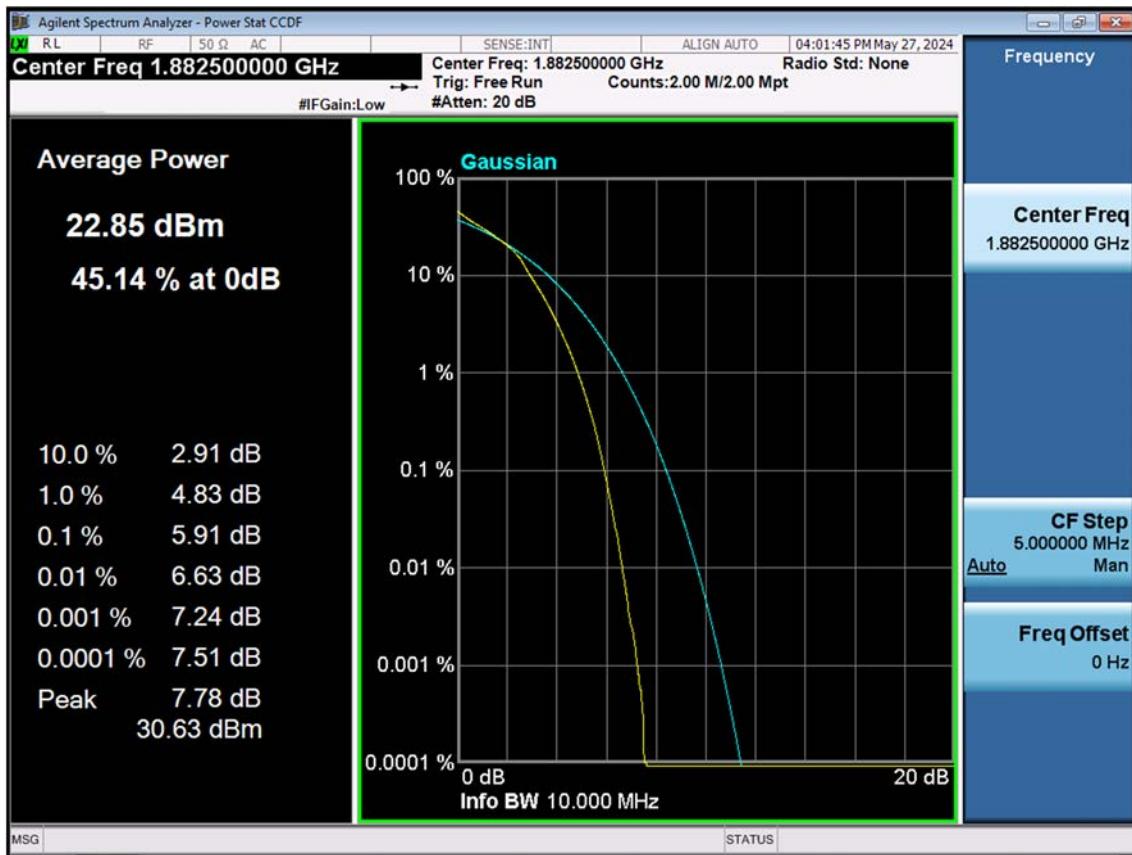


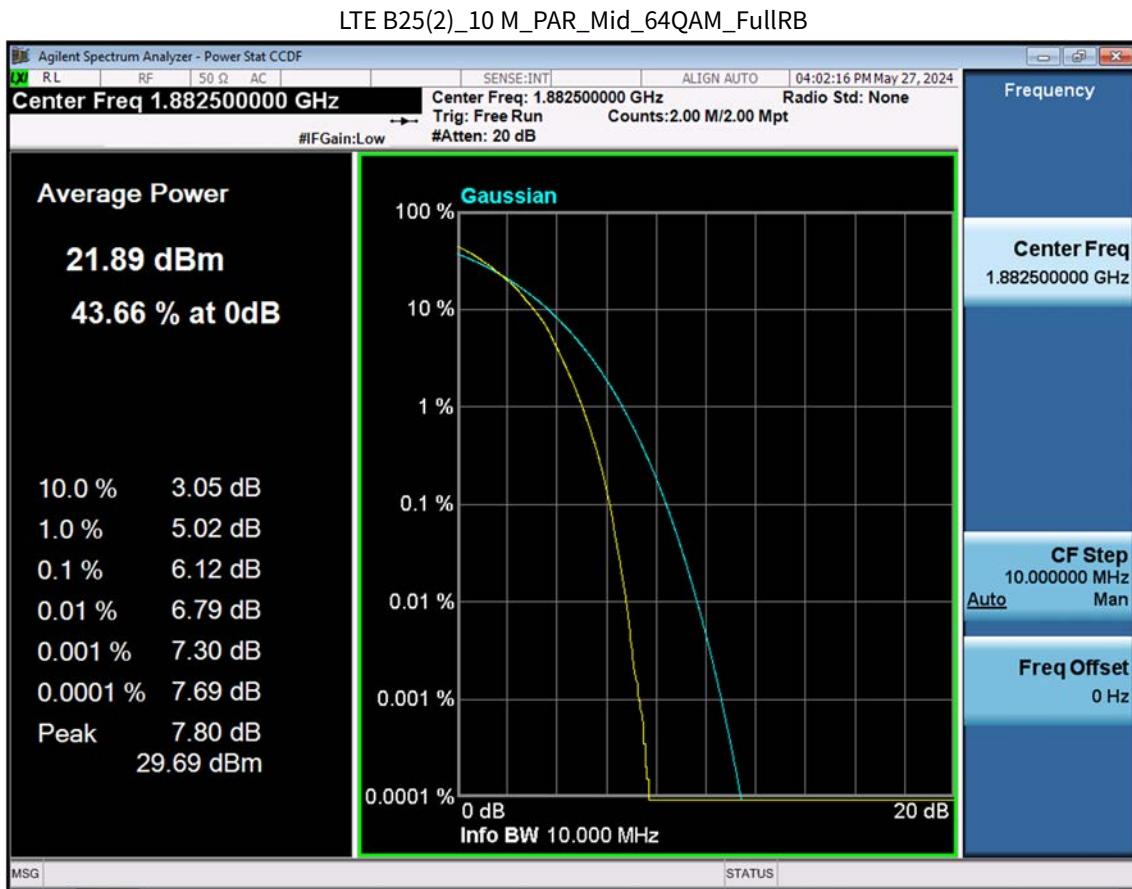


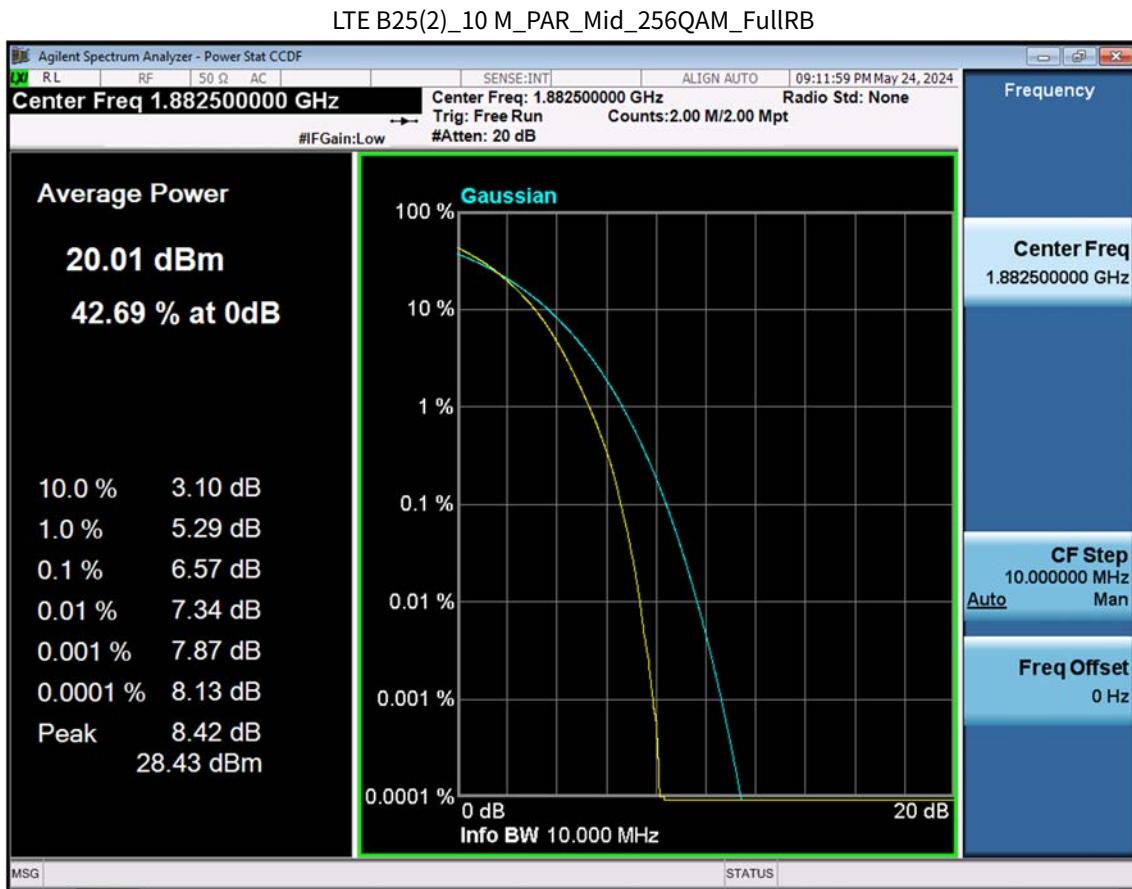


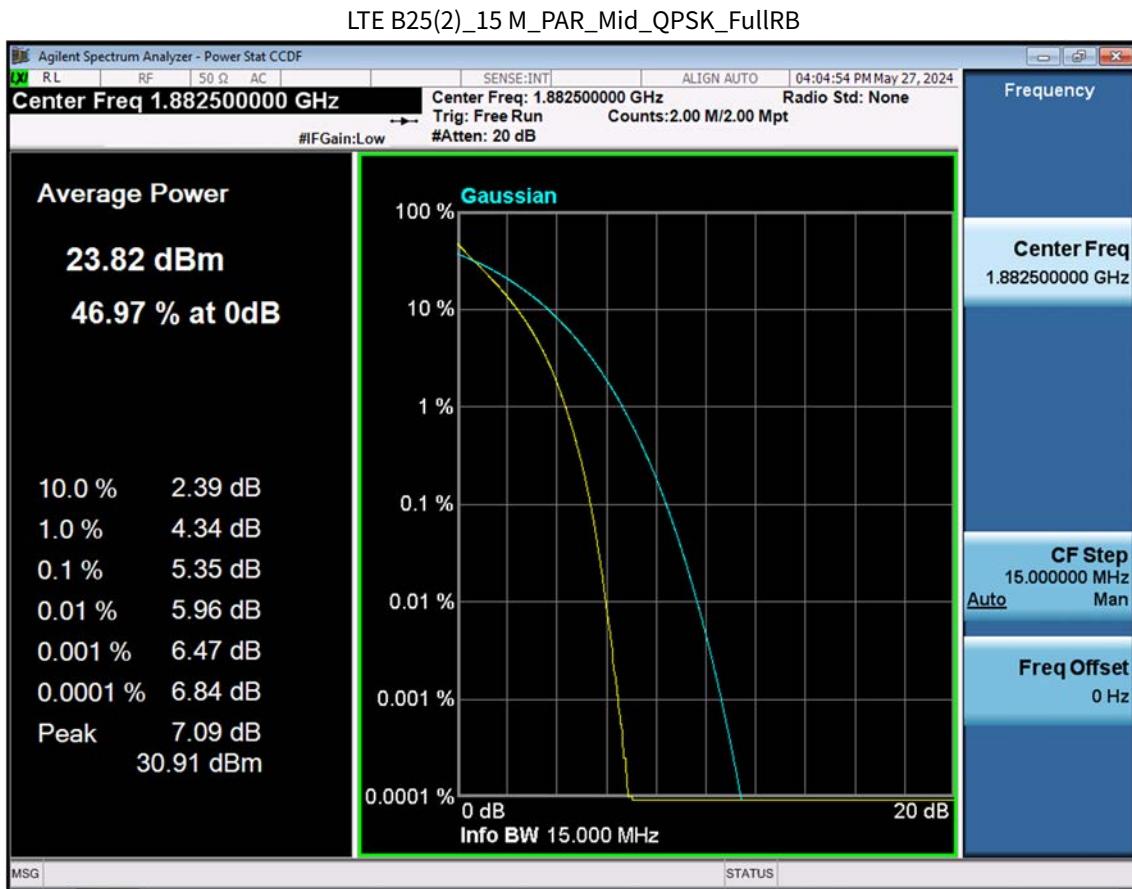


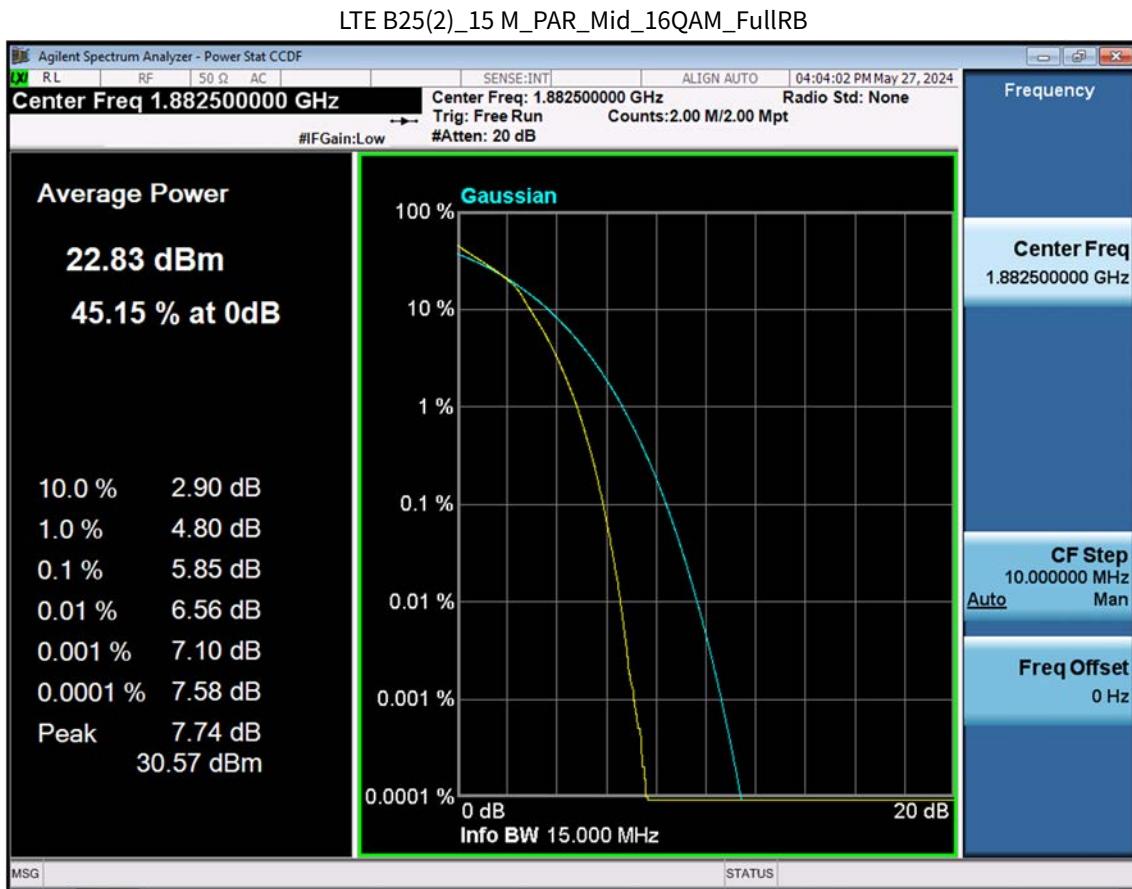
LTE B25(2)_10 M_PAR_Mid_16QAM_FullRB

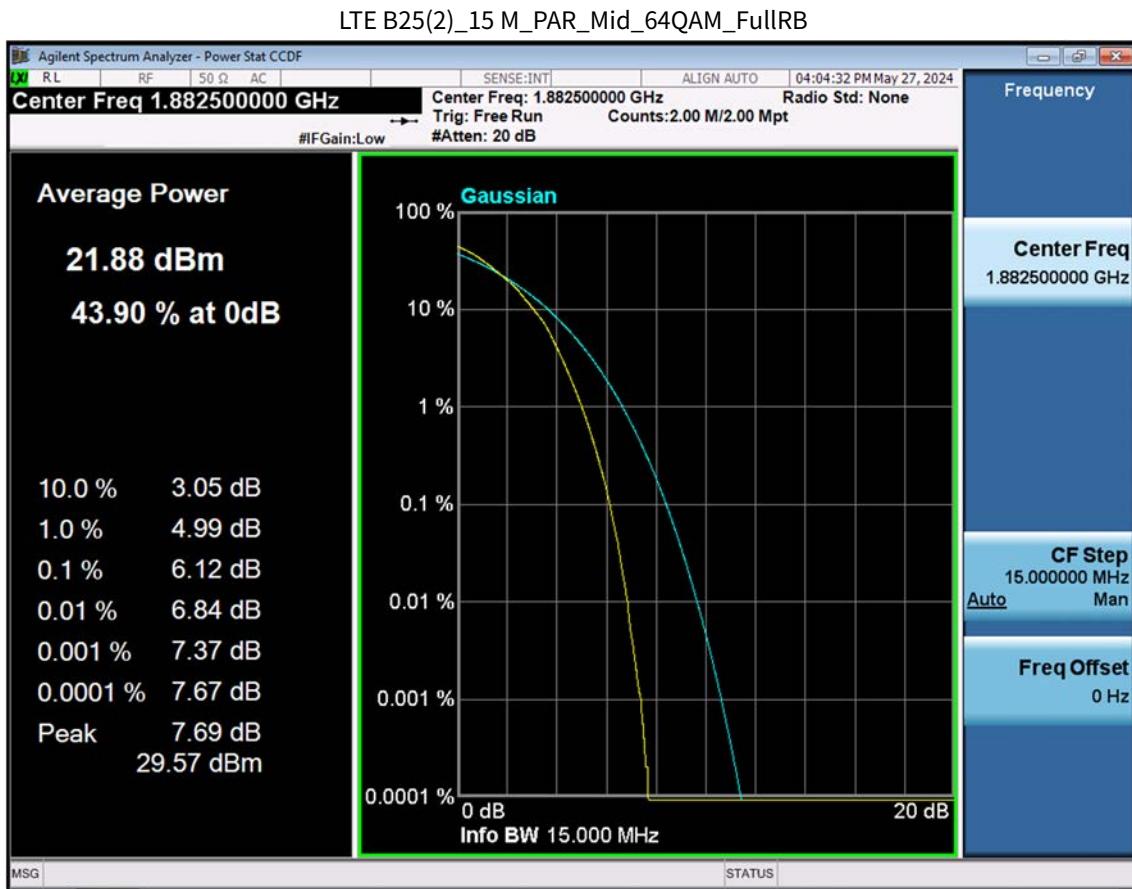


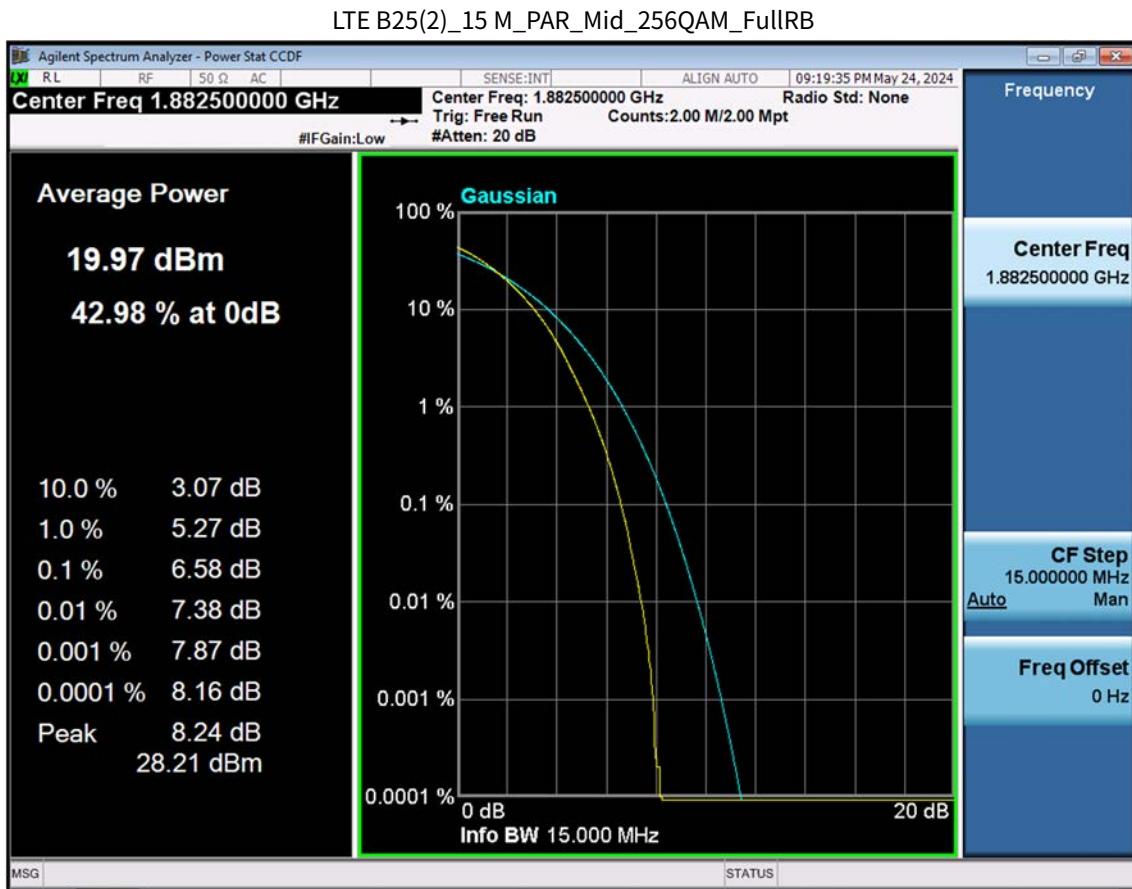


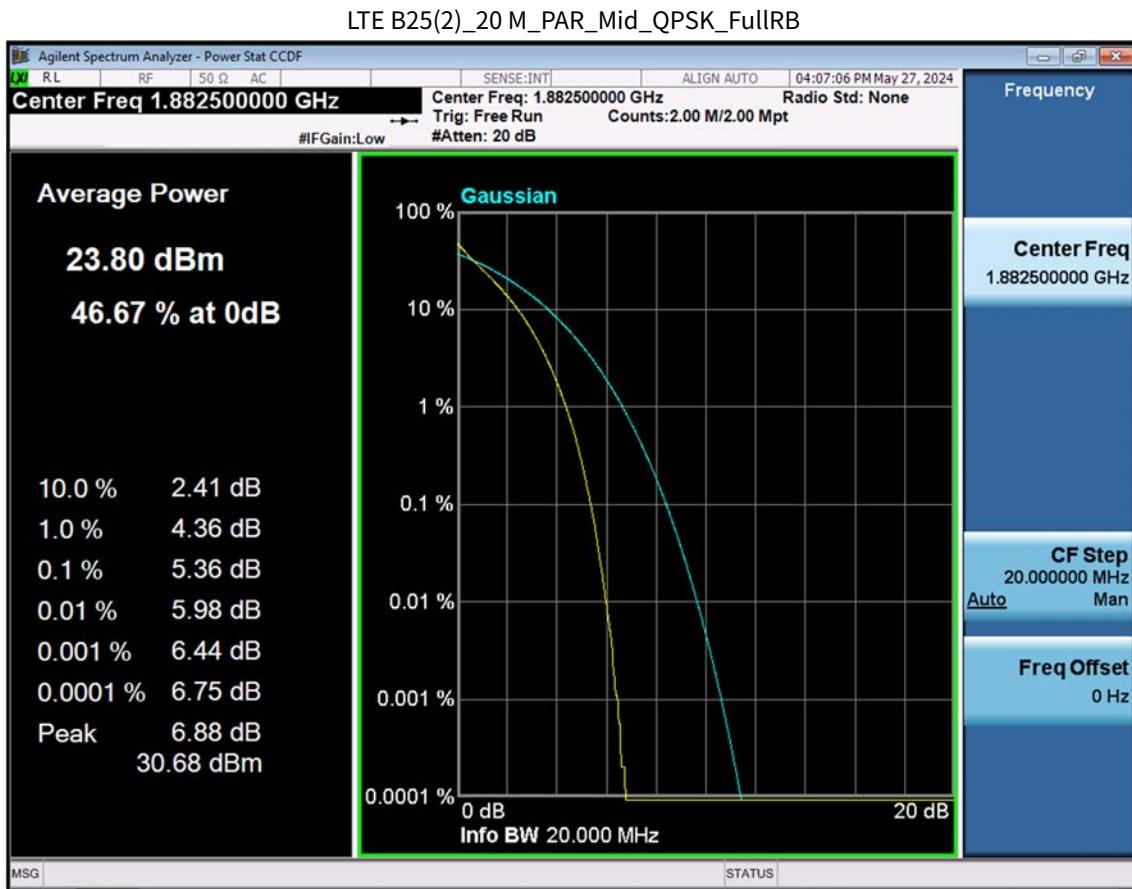


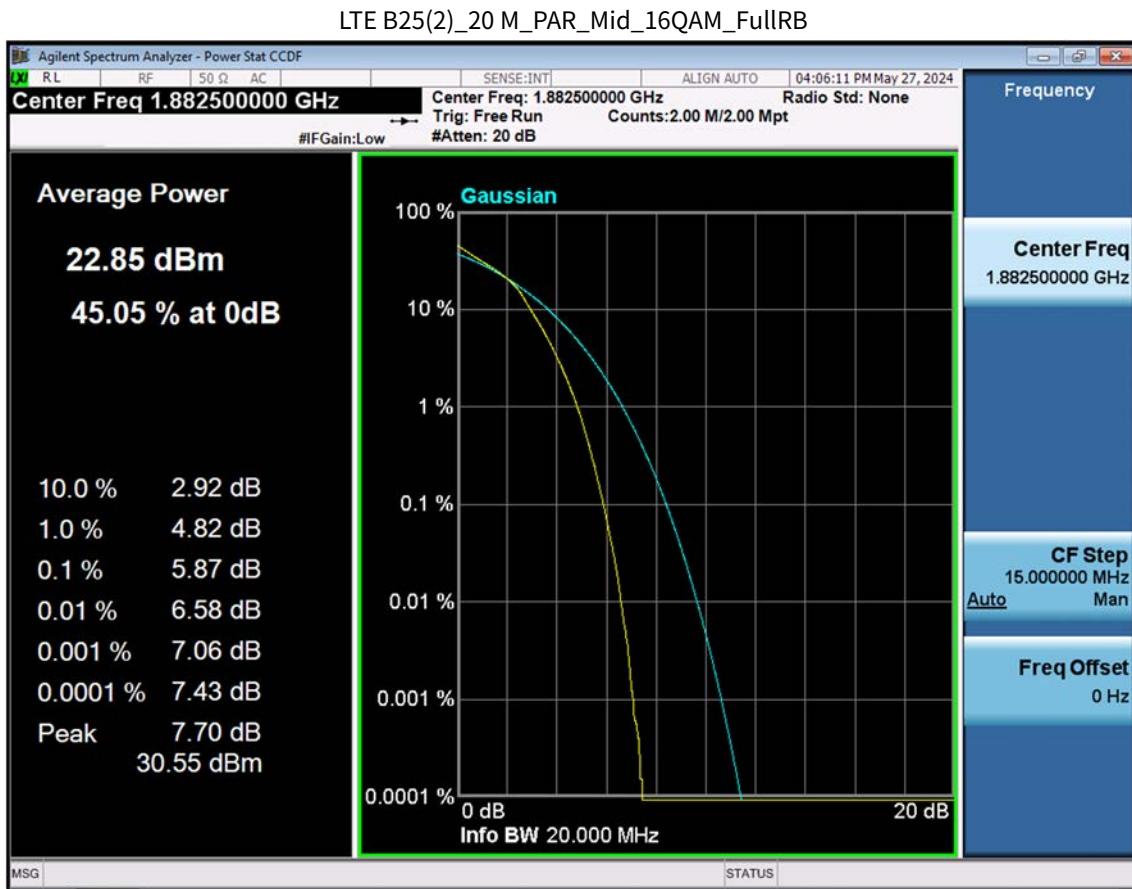




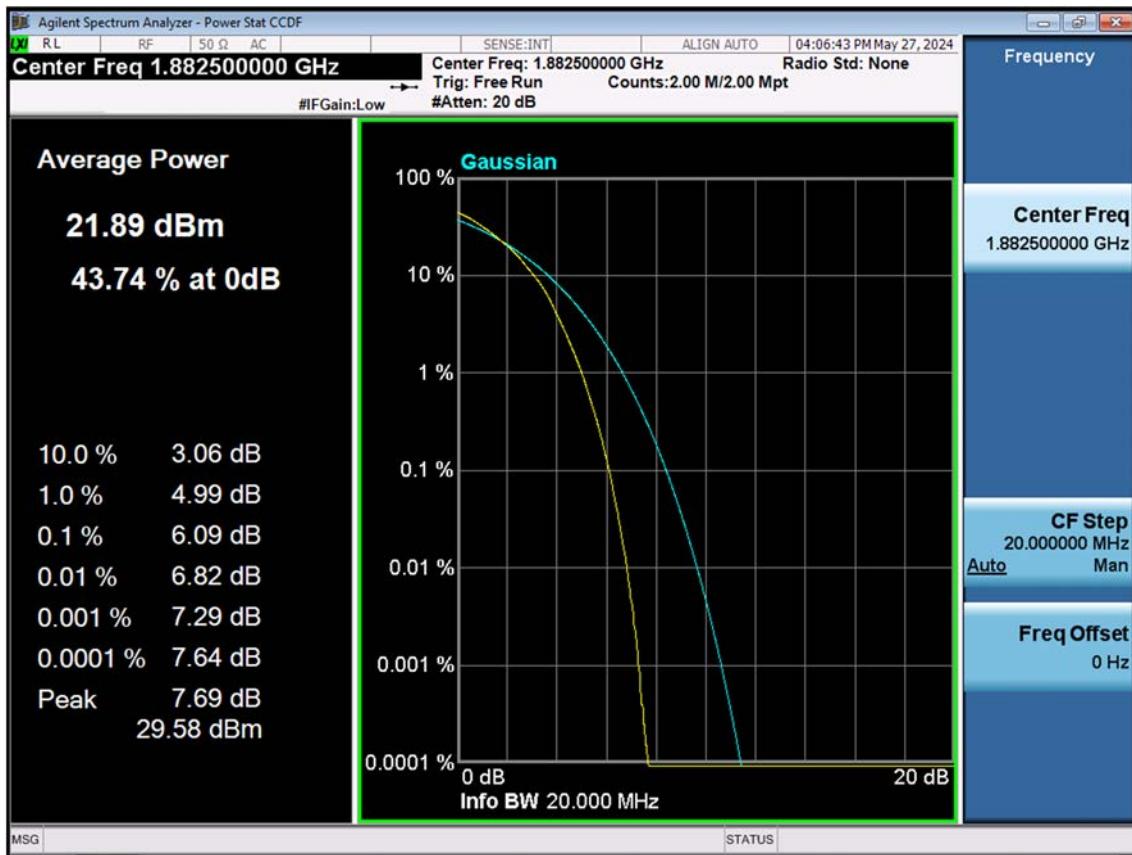


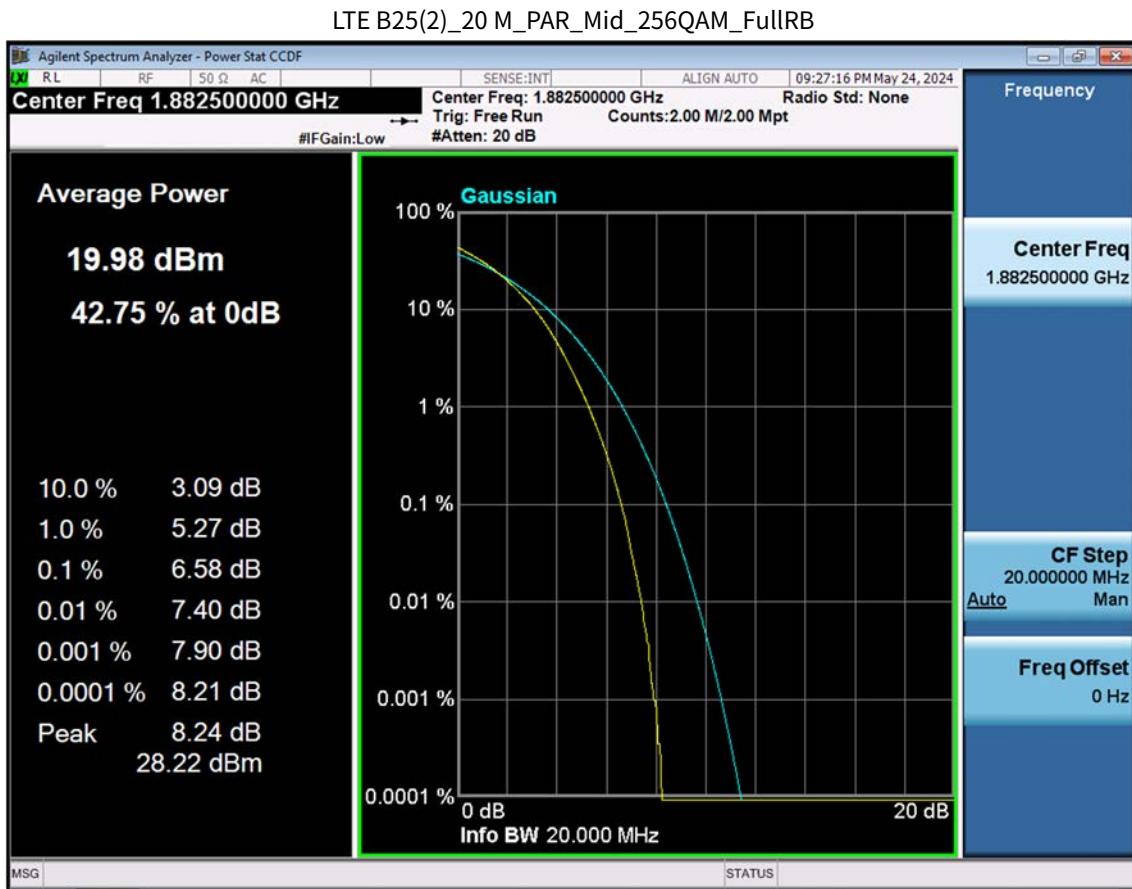




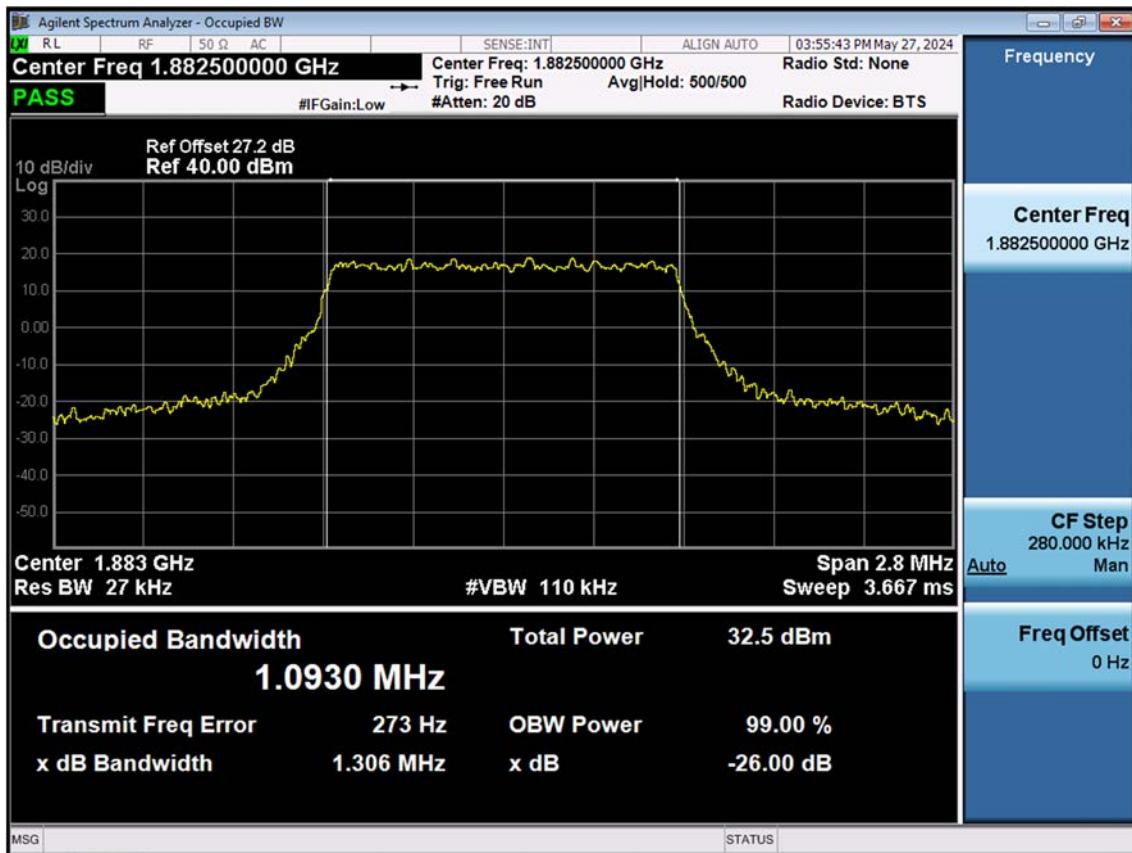


LTE B25(2)_20 M_PAR_Mid_64QAM_FullRB

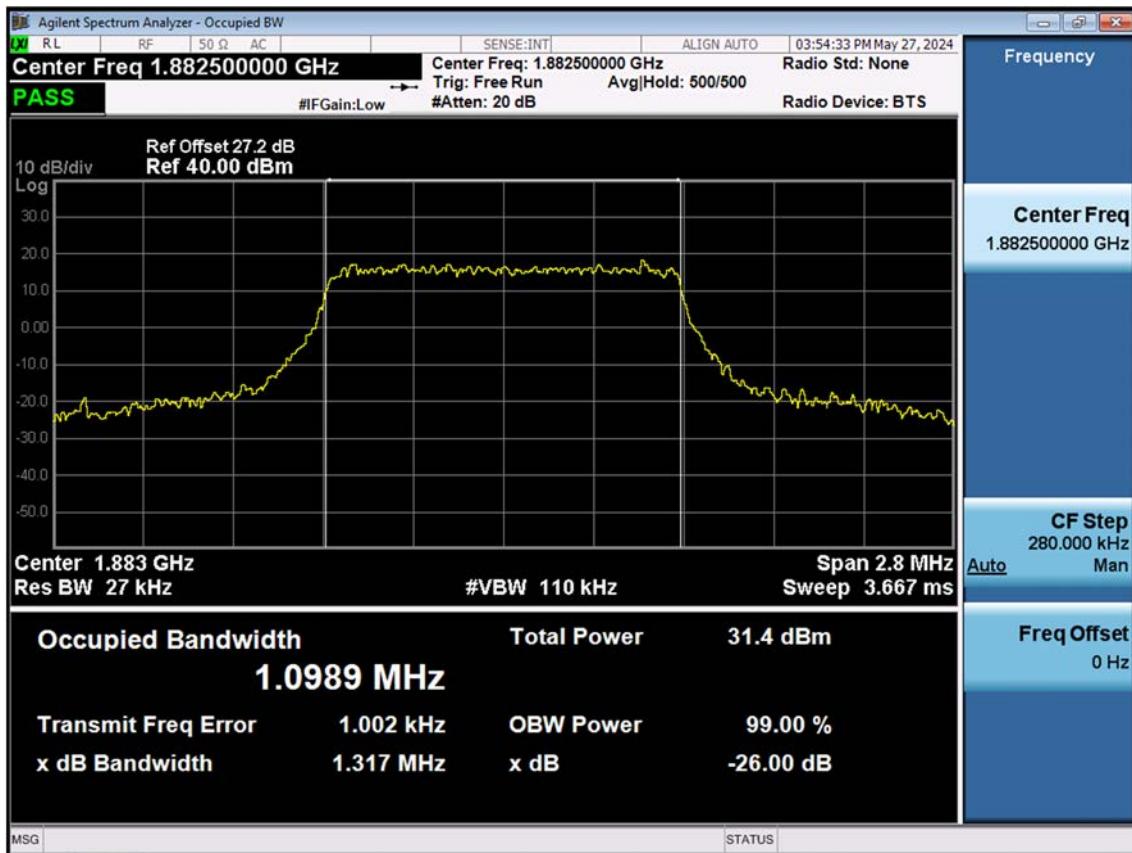




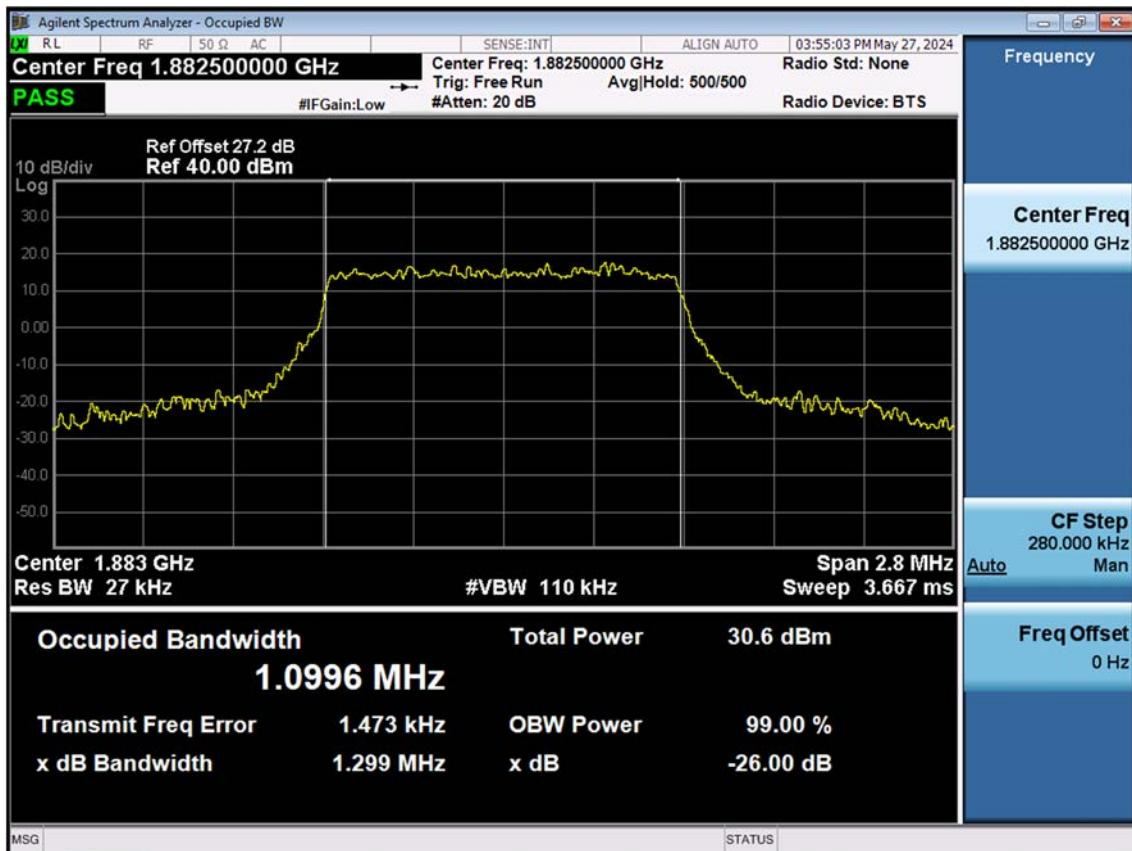
LTE B25(2)_1.4M_OBW_Mid_QPSK_FullRB



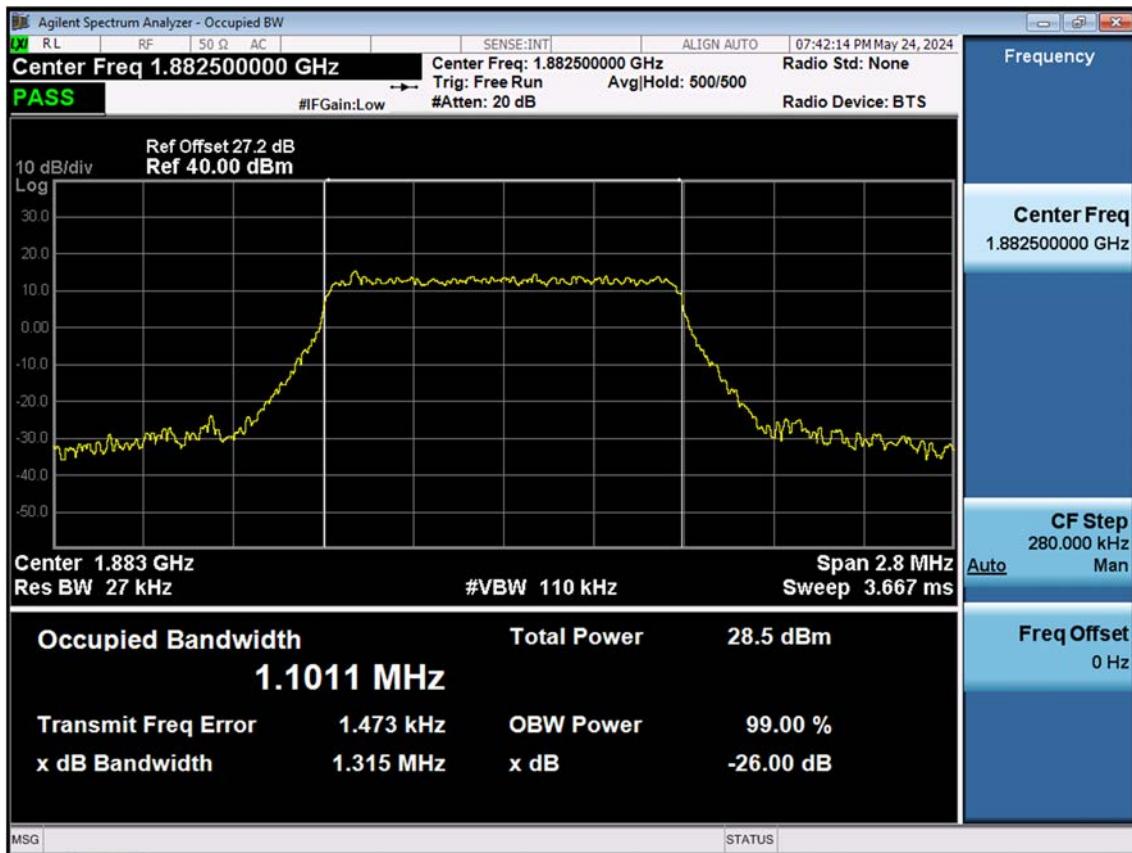
LTE B25(2)_1.4M_OBW_Mid_16QAM_FullRB



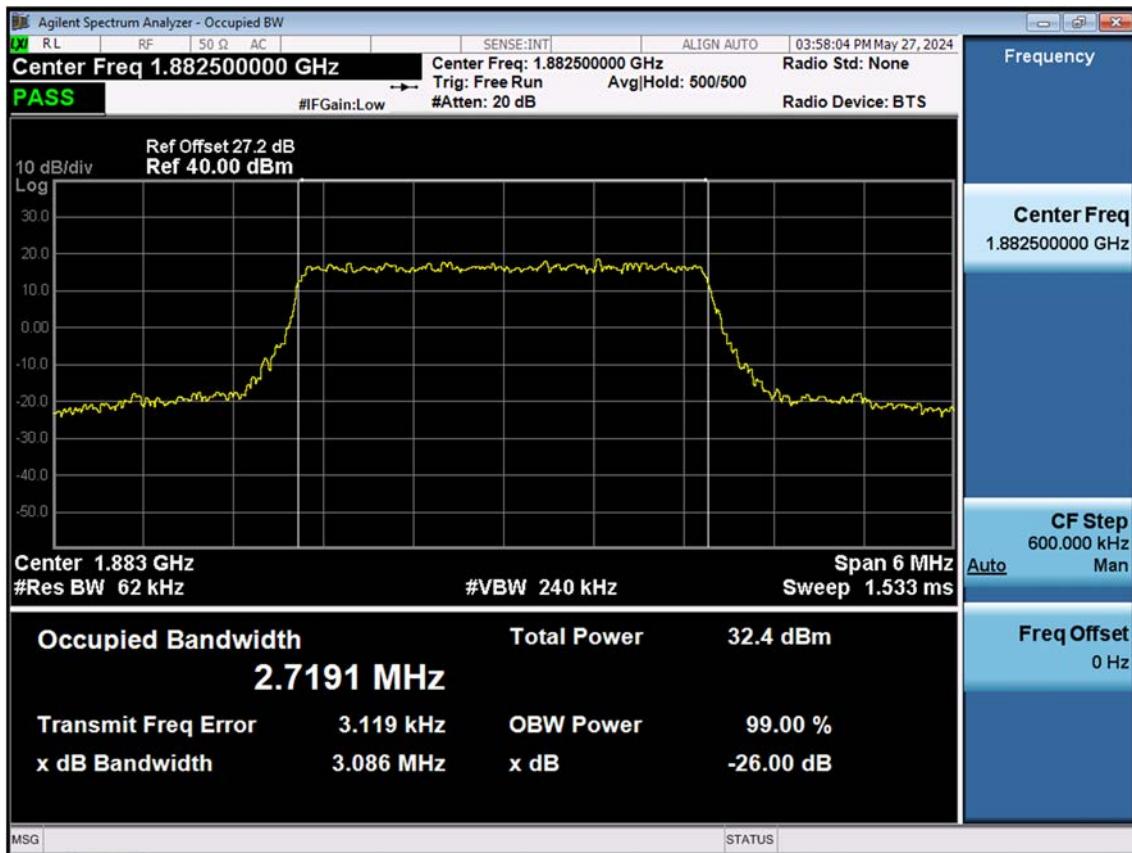
LTE B25(2)_1.4M_OBW_Mid_64QAM_FullRB



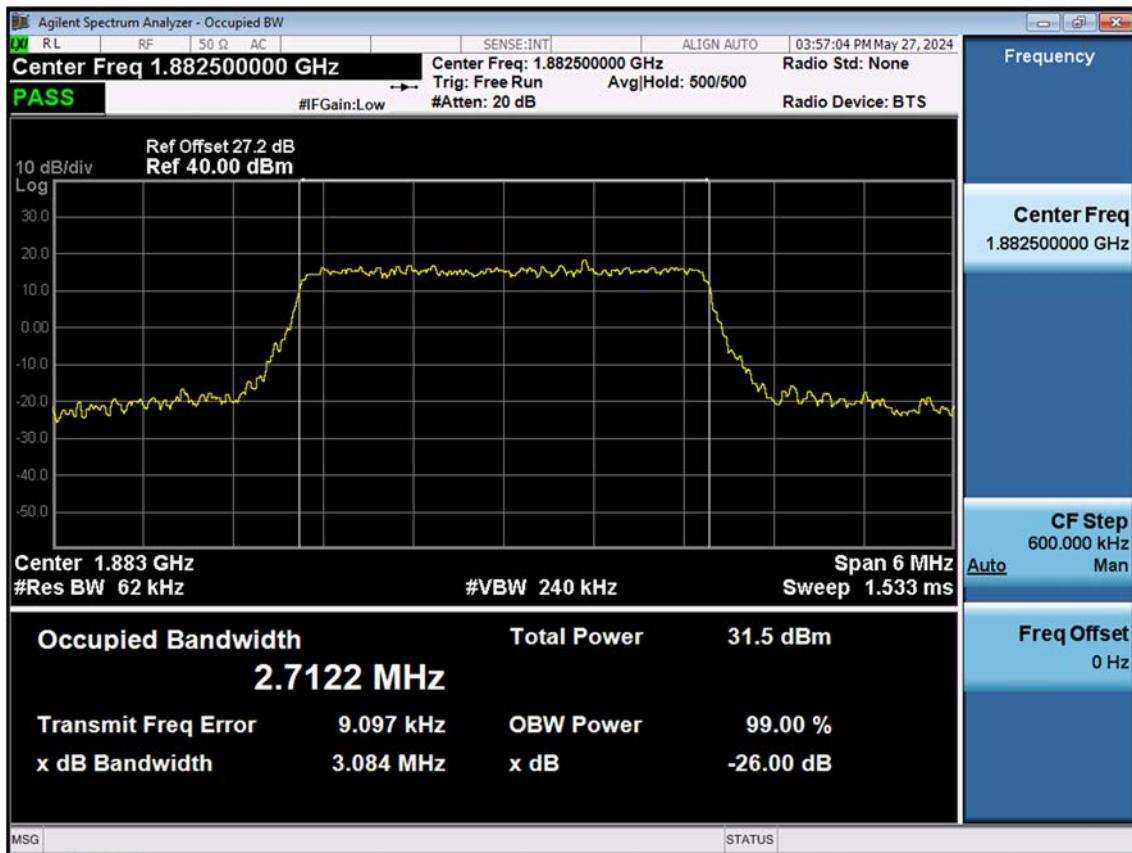
LTE B25(2)_1.4M_OBW_Mid_256QAM_FullRB



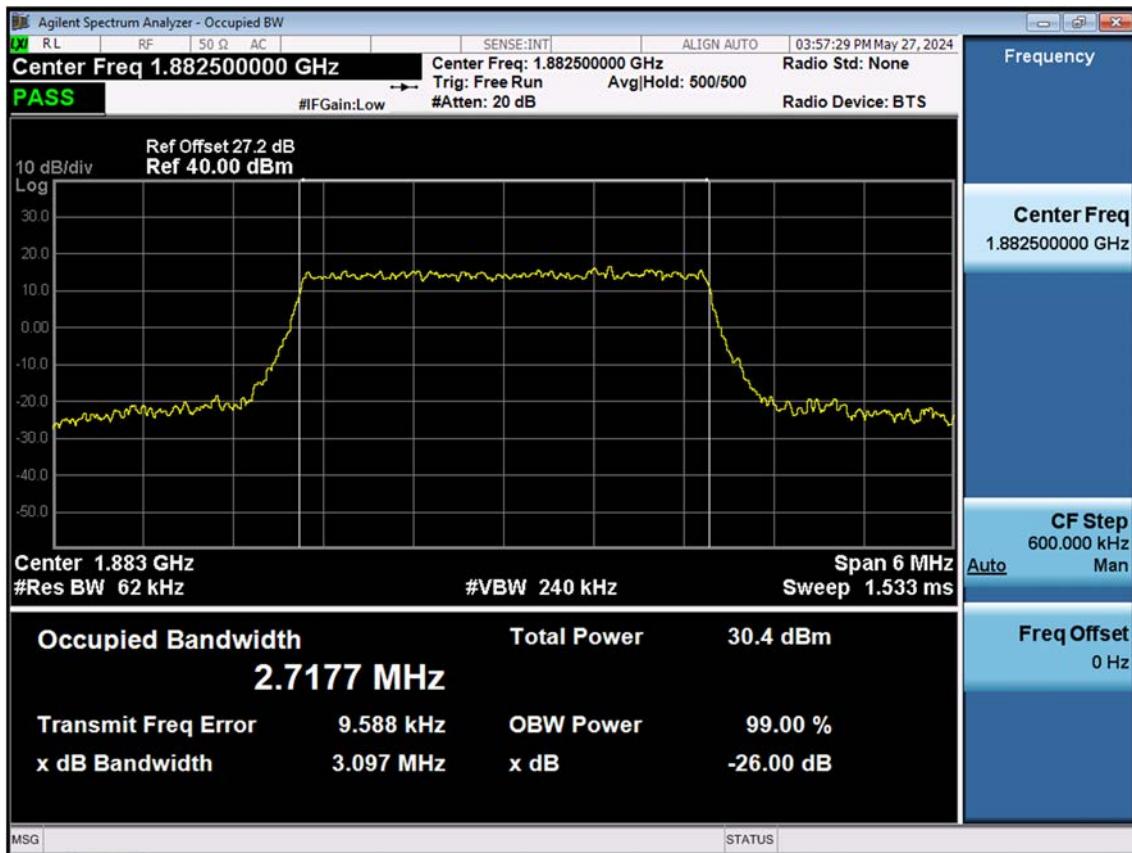
LTE B25(2)_3 M_OBW_Mid_QPSK_FullRB



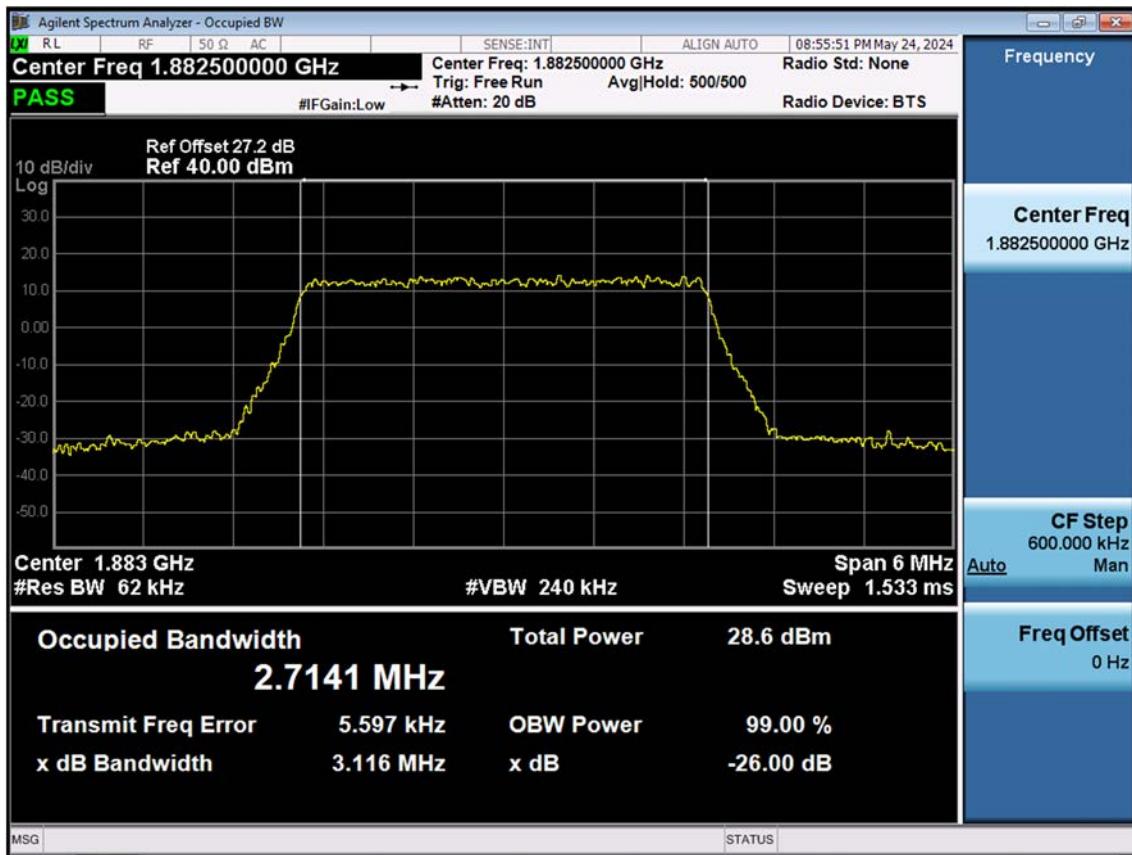
LTE B25(2)_3 M_OBW_Mid_16QAM_FullRB



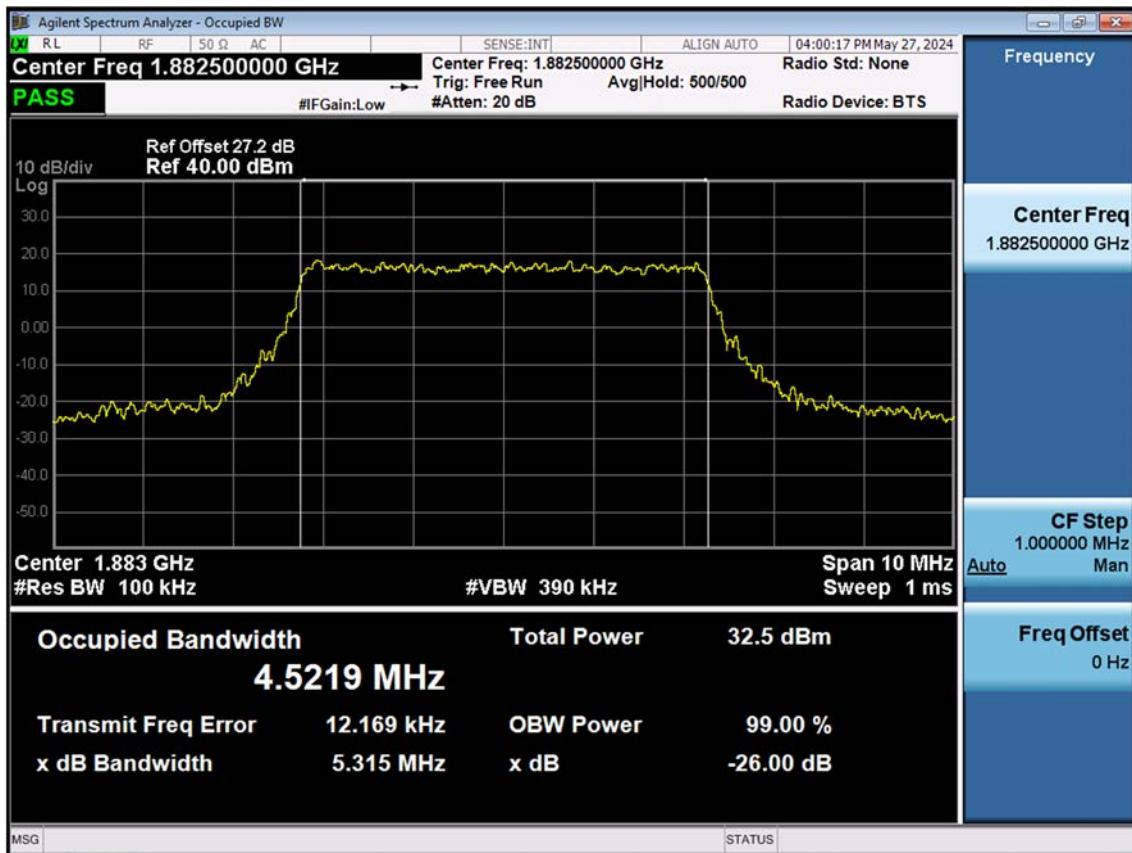
LTE B25(2)_3 M_OBW_Mid_64QAM_FullRB



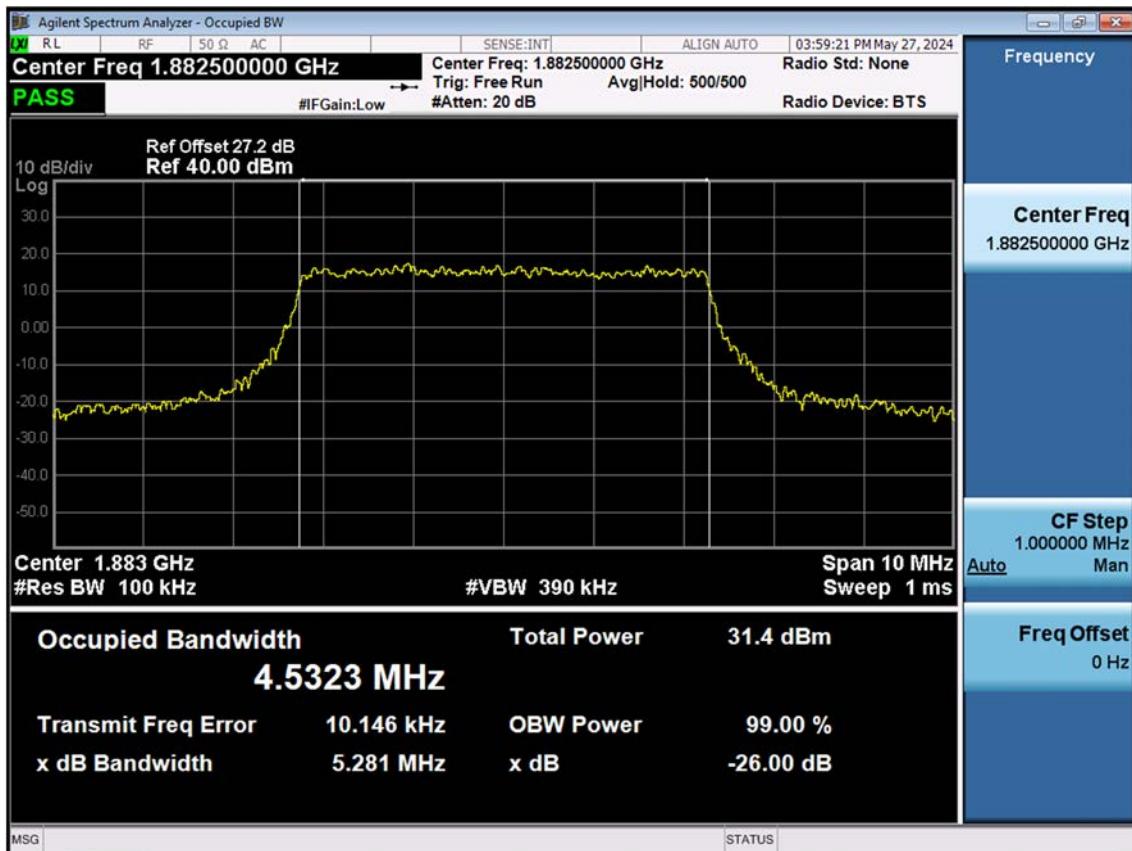
LTE B25(2)_3 M_OBW_Mid_256QAM_FullRB



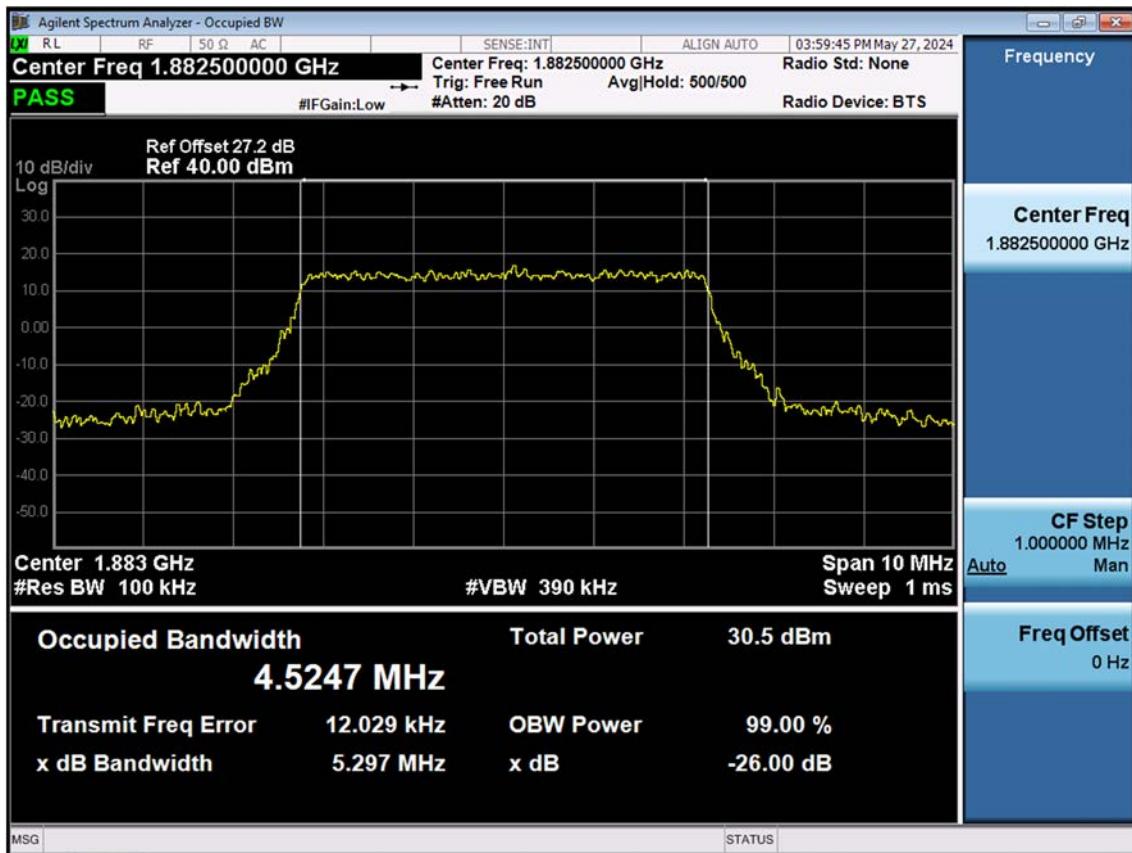
LTE B25(2)_5 M_OBW_Mid_QPSK_FullRB



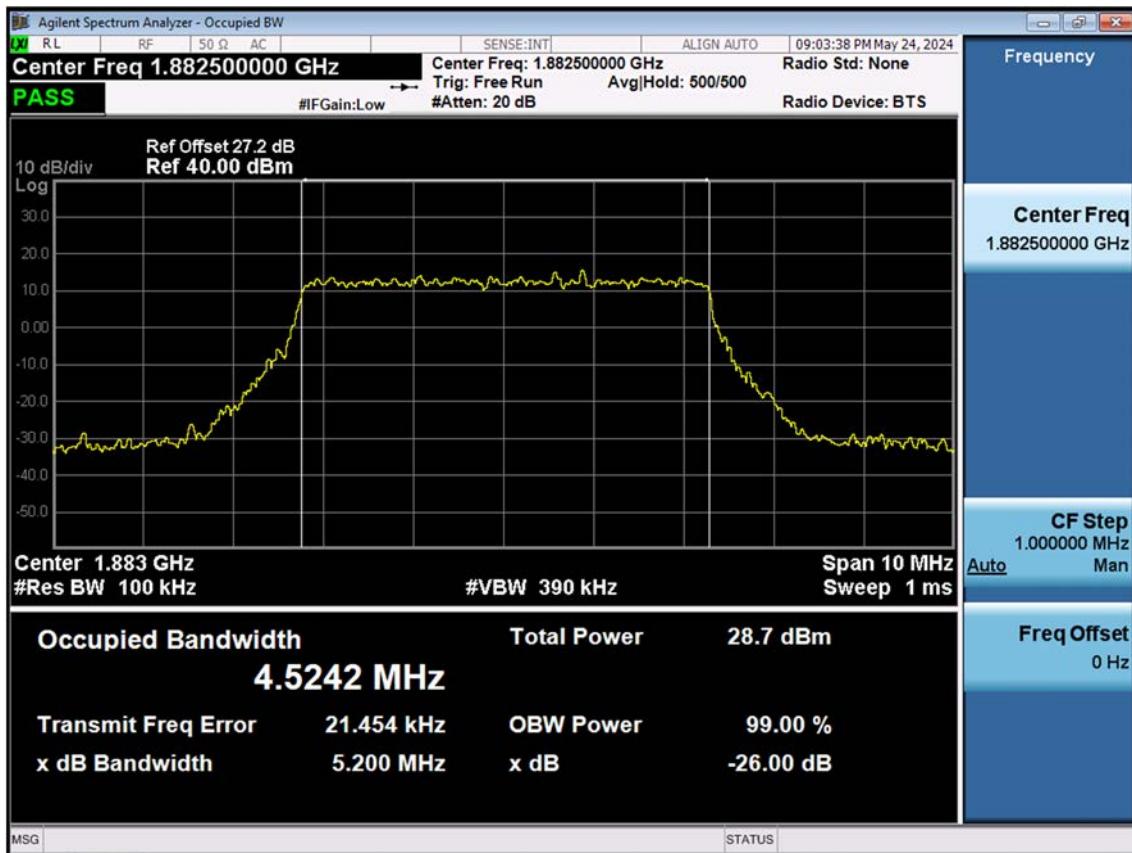
LTE B25(2)_5 M_OBW_Mid_16QAM_FullRB



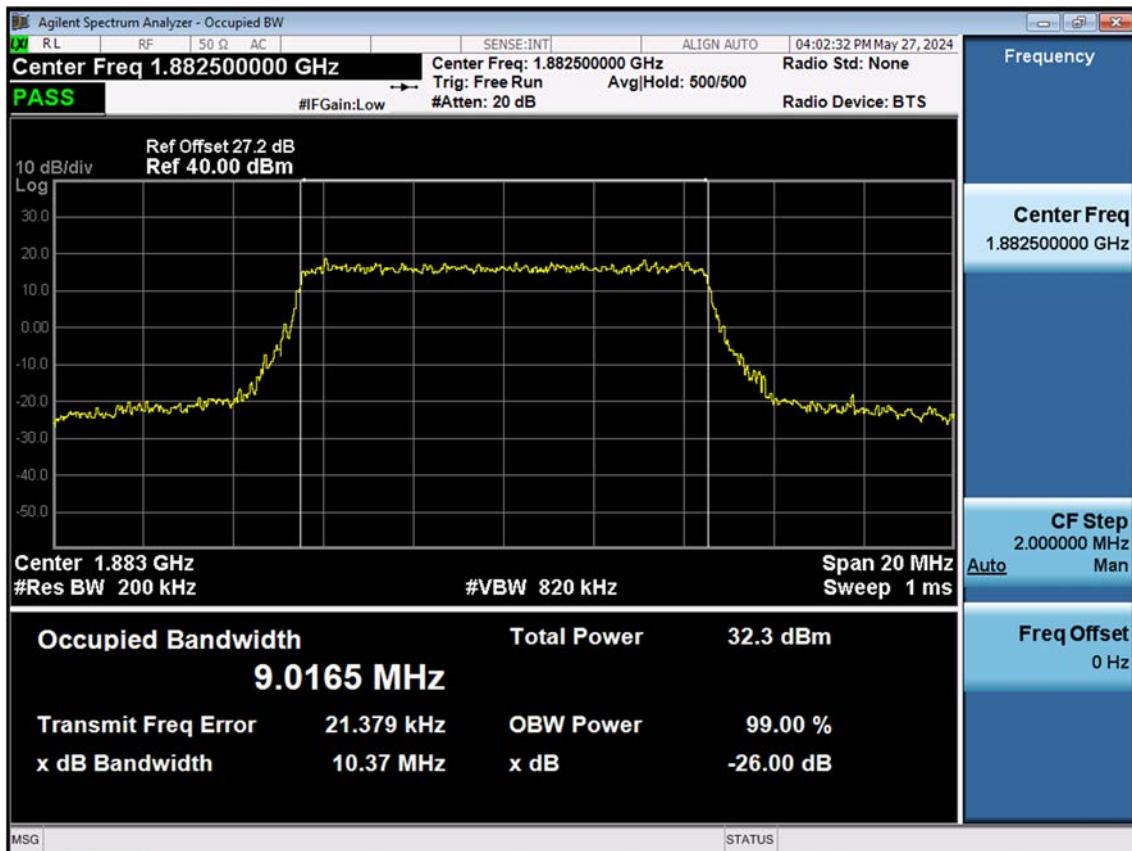
LTE B25(2)_5 M_OBW_Mid_64QAM_FullRB



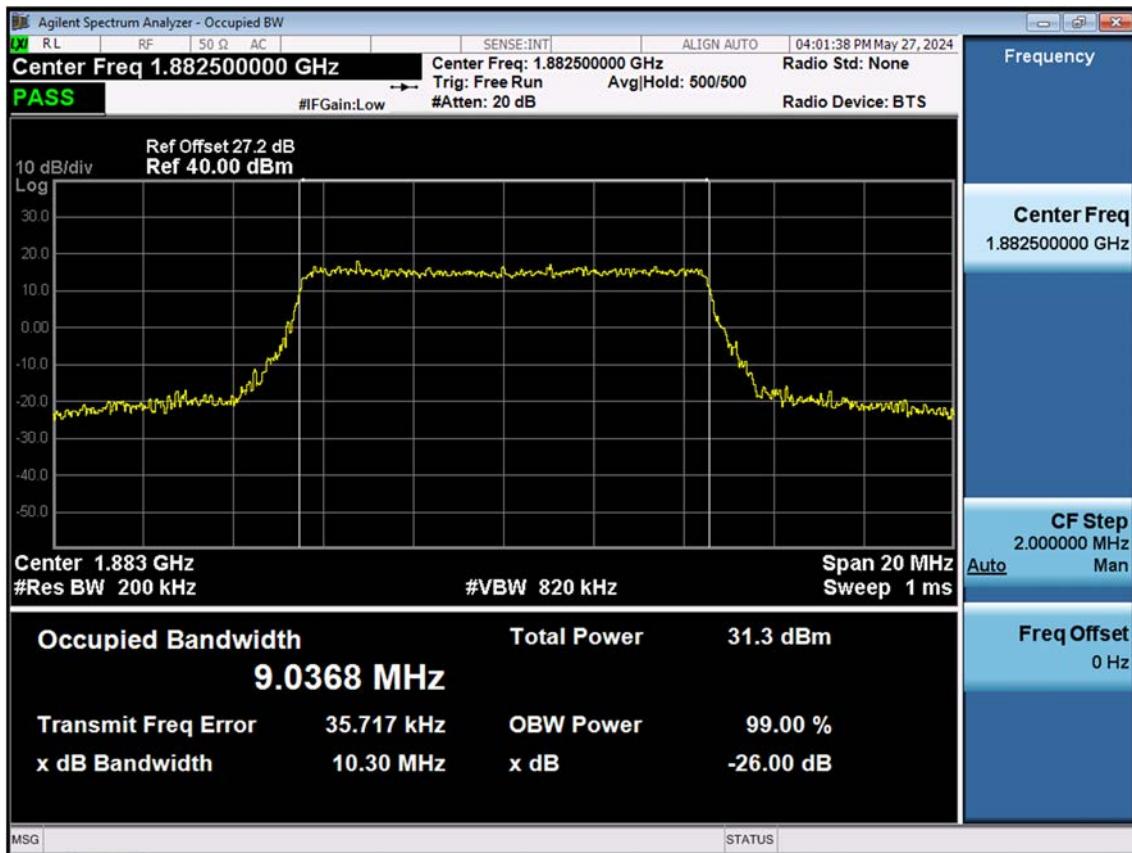
LTE B25(2)_5 M_OBW_Mid_256QAM_FullRB



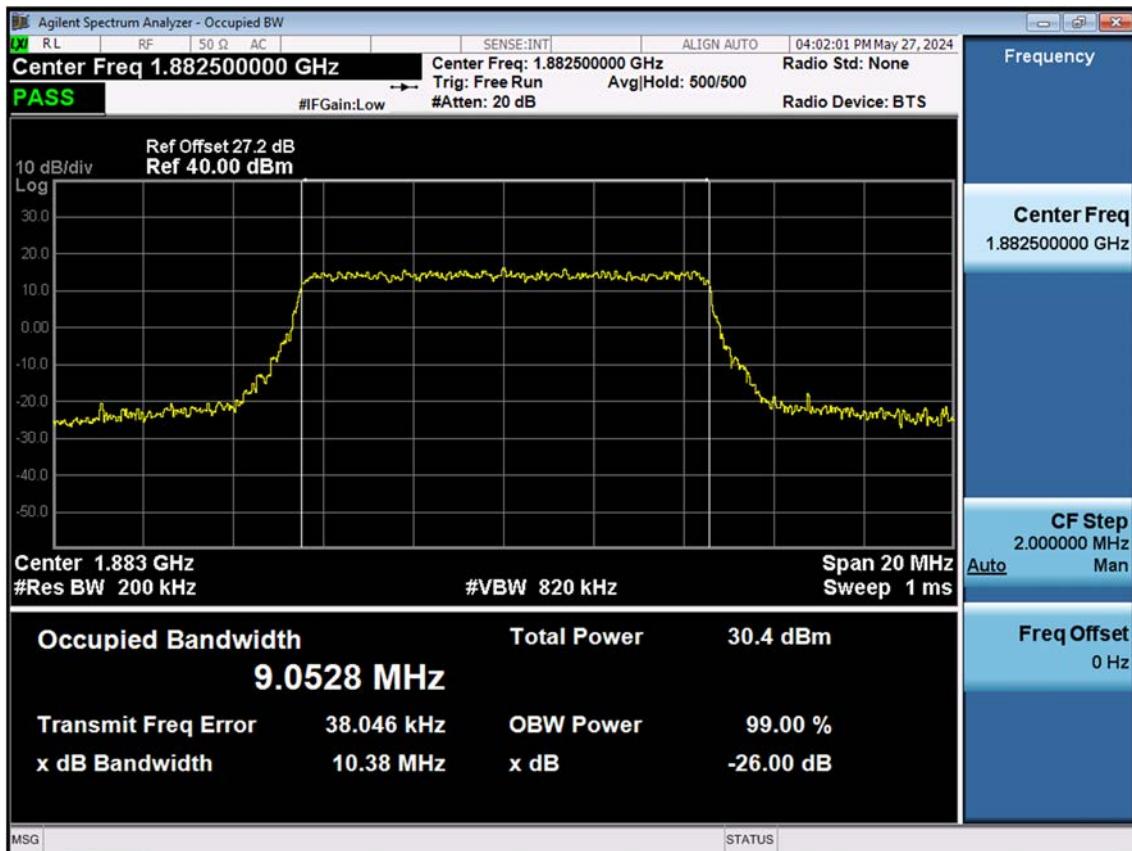
LTE B25(2)_10 M_OBW_Mid_QPSK_FullRB



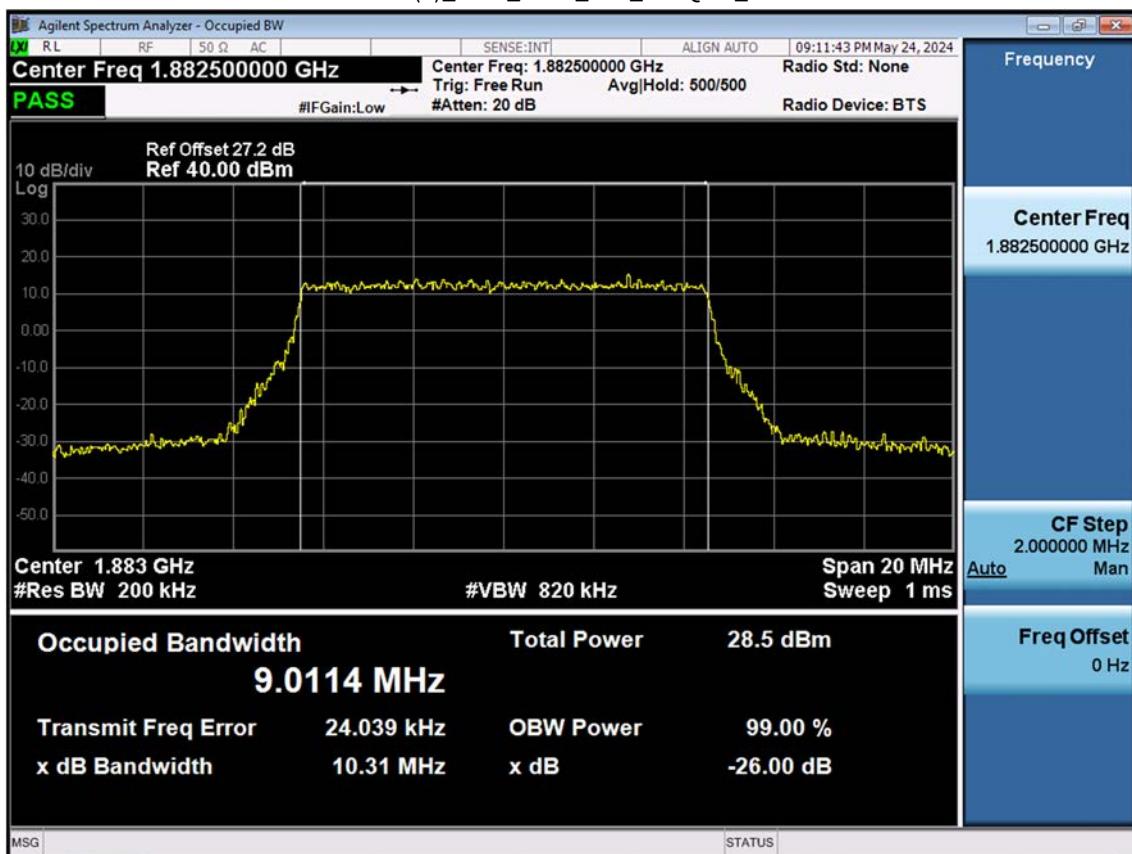
LTE B25(2)_10 M_OBW_Mid_16QAM_FullRB



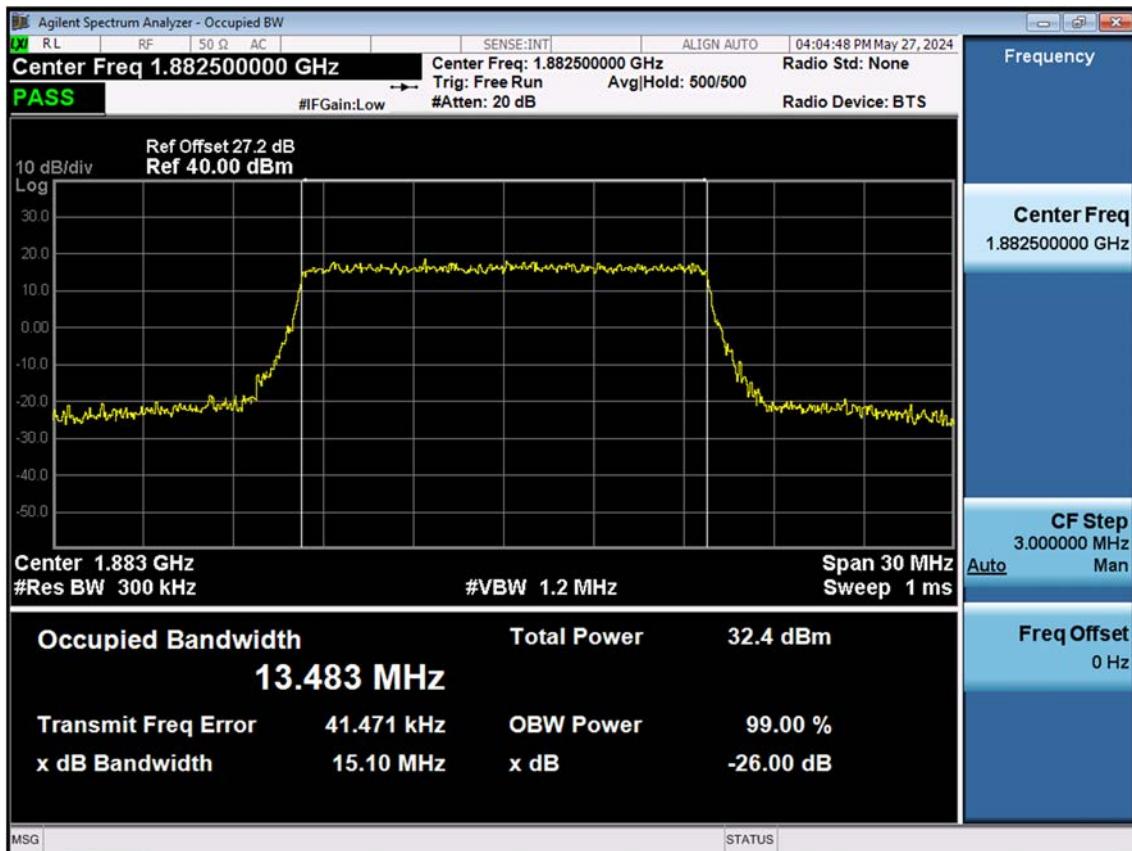
LTE B25(2)_10 M_OBW_Mid_64QAM_FullRB



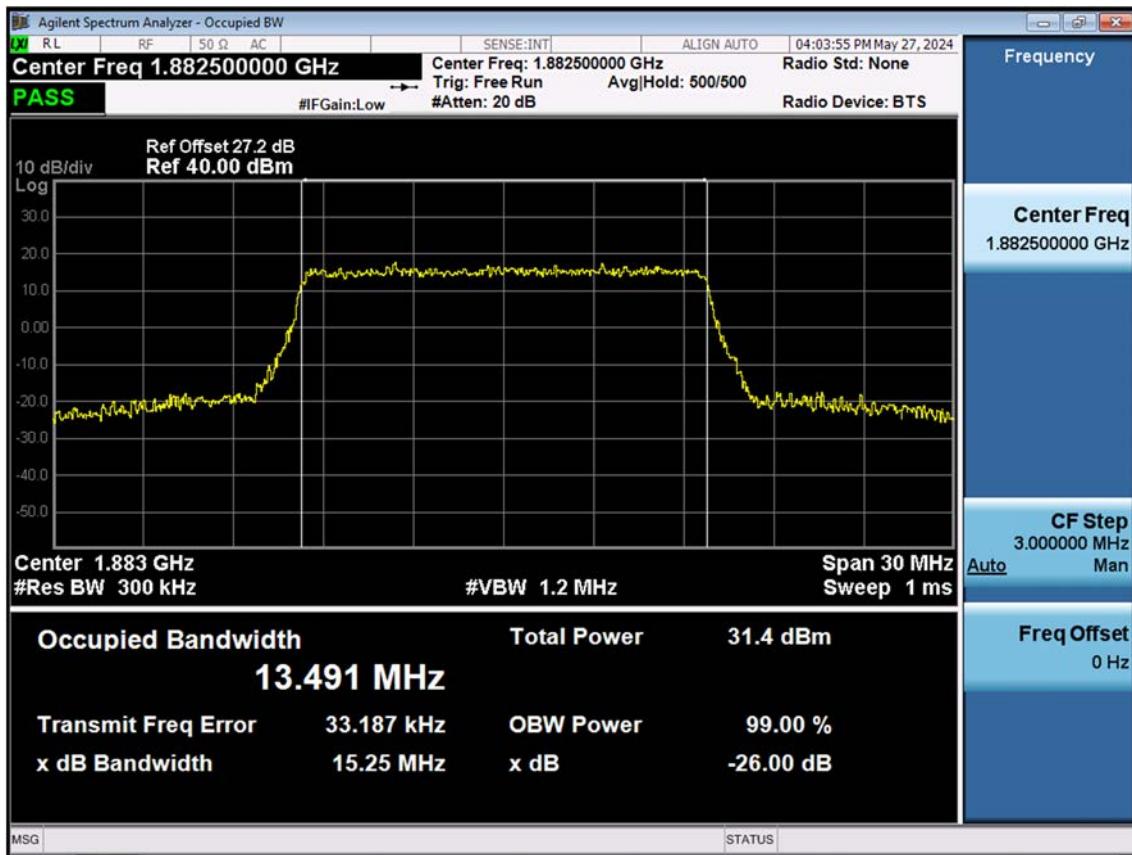
LTE B25(2)_10 M_OBW_Mid_256QAM_FullRB



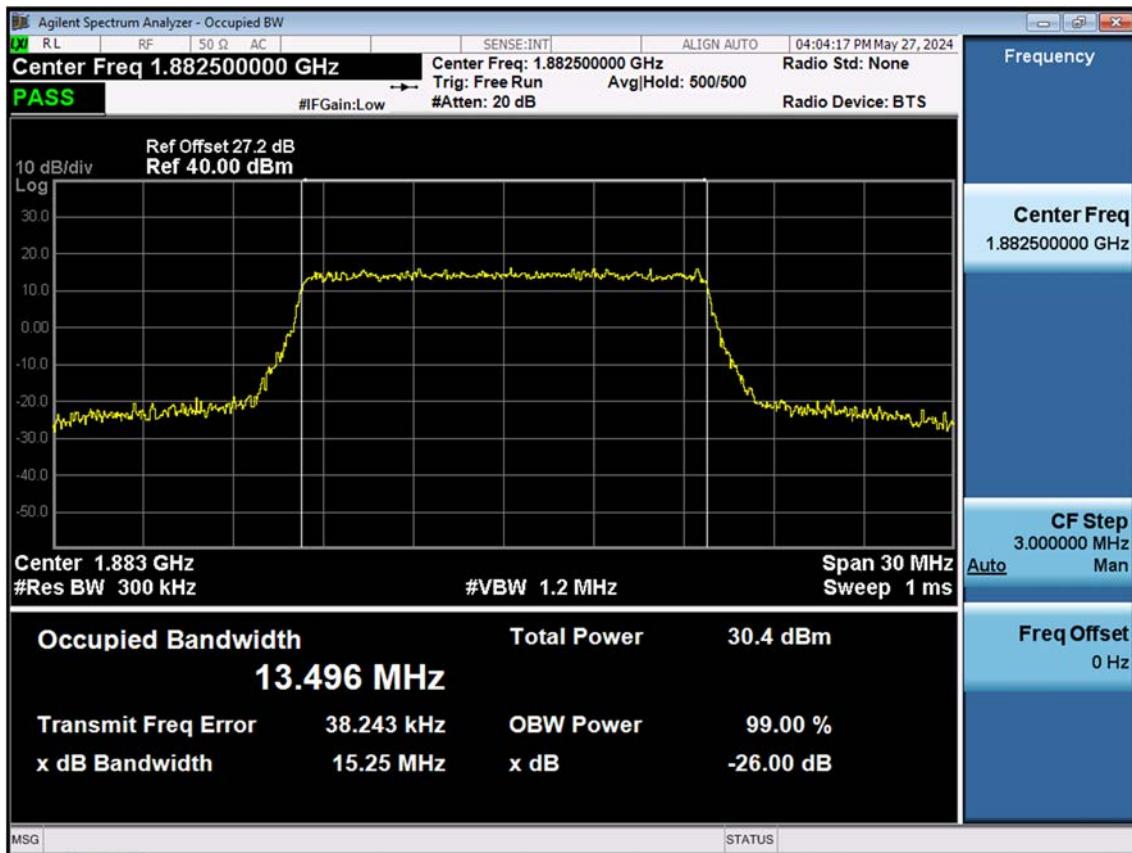
LTE B25(2)_15 M_OBW_Mid_QPSK_FullRB



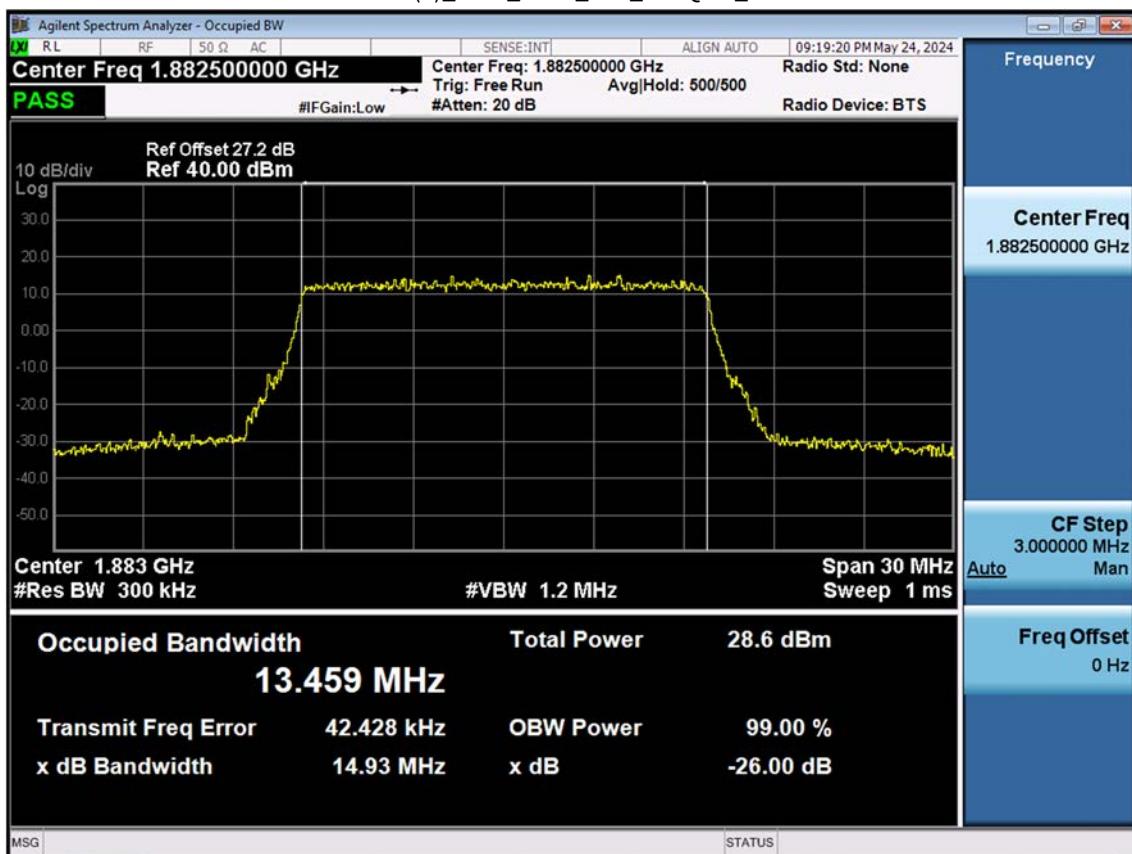
LTE B25(2)_15 M_OBW_Mid_16QAM_FullRB



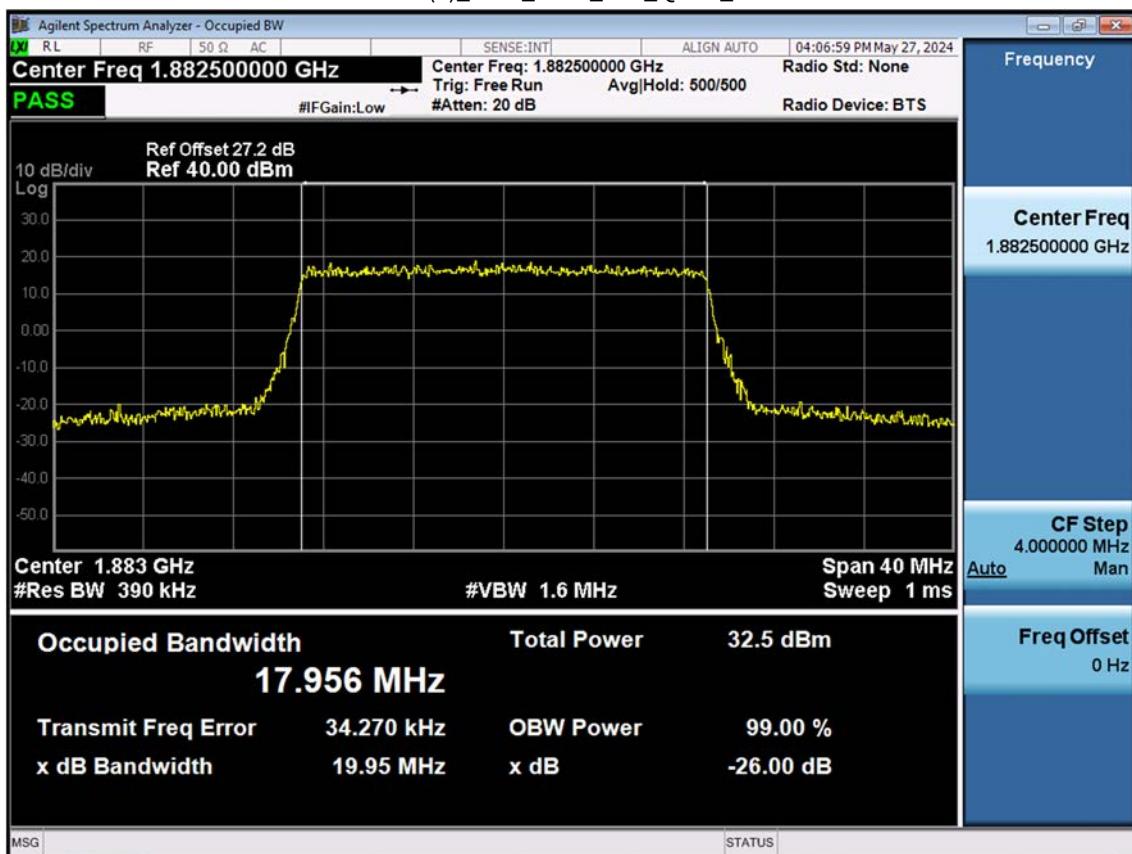
LTE B25(2)_15 M_OBW_Mid_64QAM_FullRB



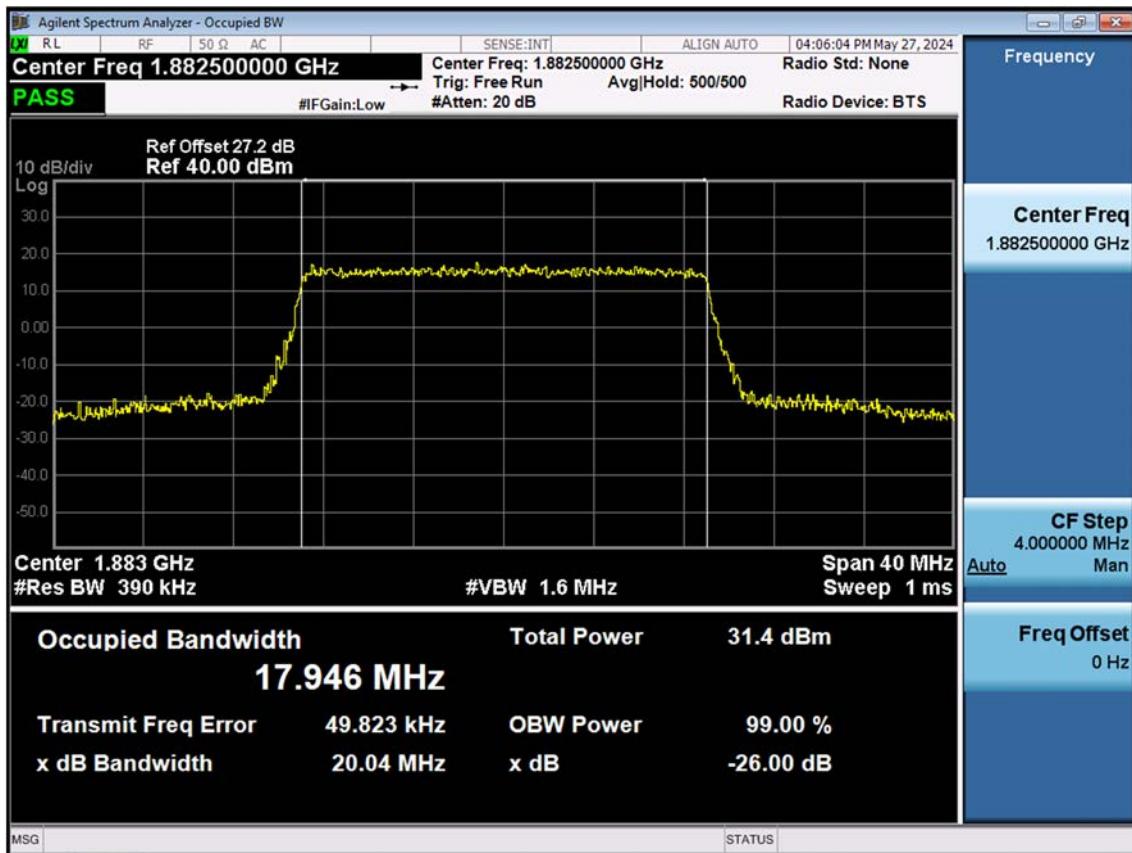
LTE B25(2)_15 M_OBW_Mid_256QAM_FullRB



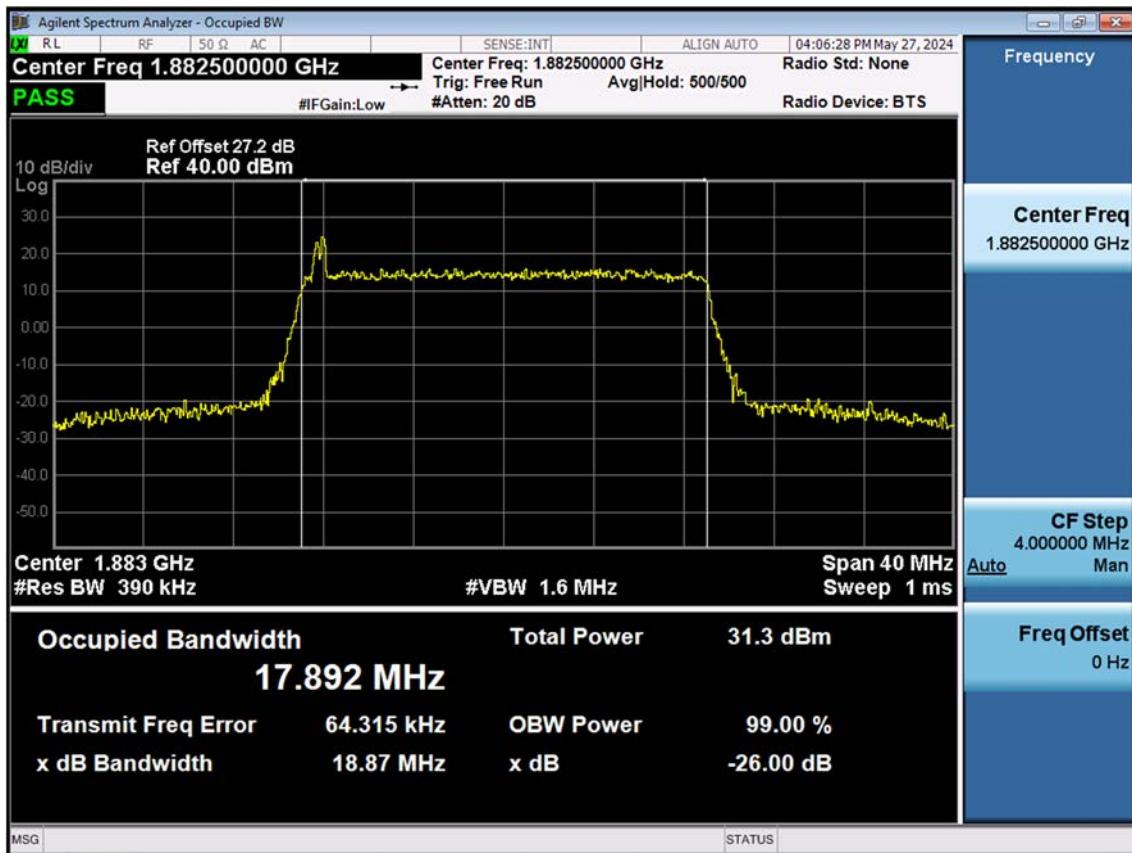
LTE B25(2)_20 M_OBW_Mid_QPSK_FullRB



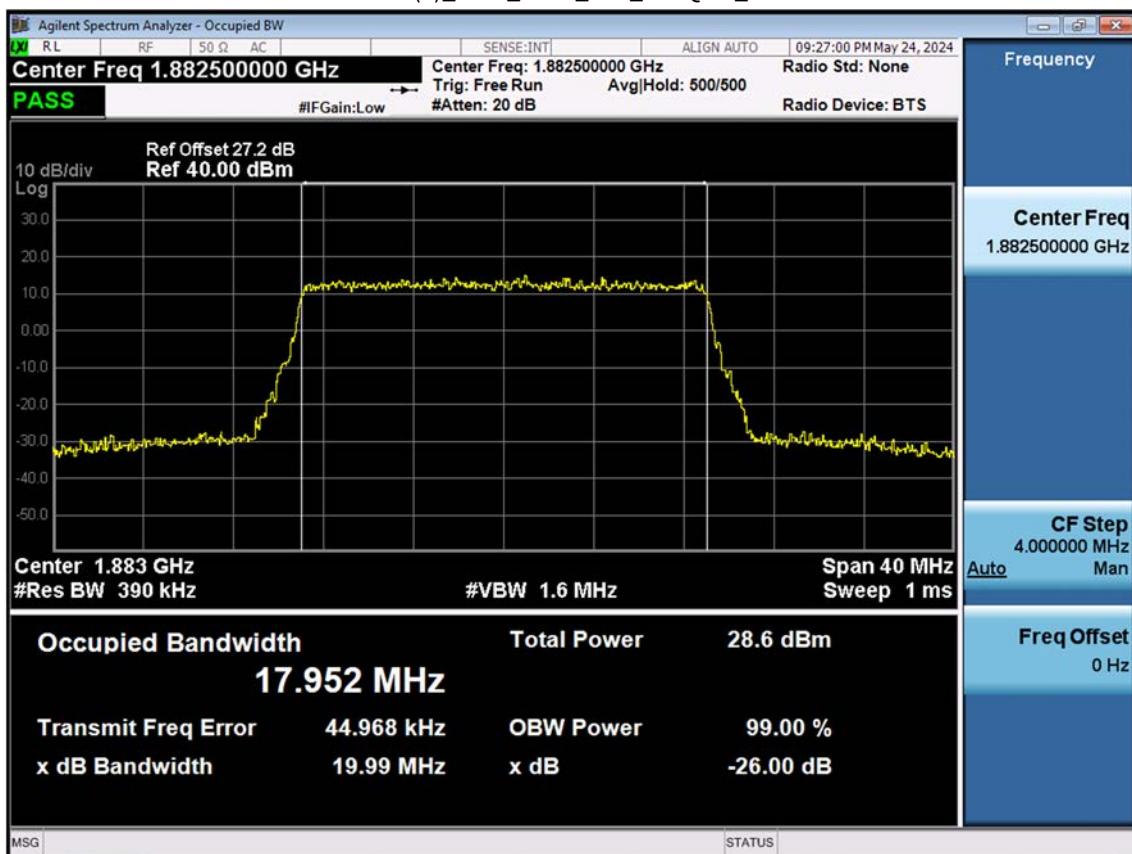
LTE B25(2)_20 M_OBW_Mid_16QAM_FullRB

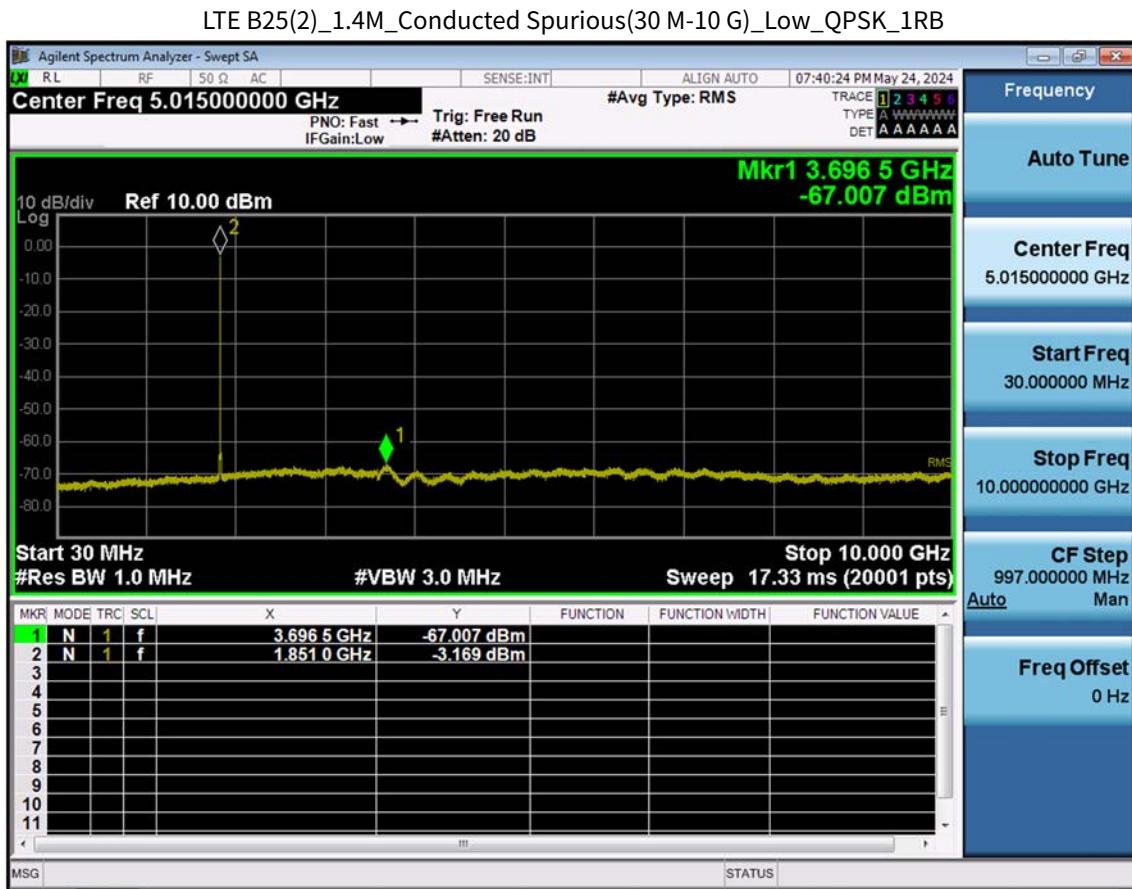


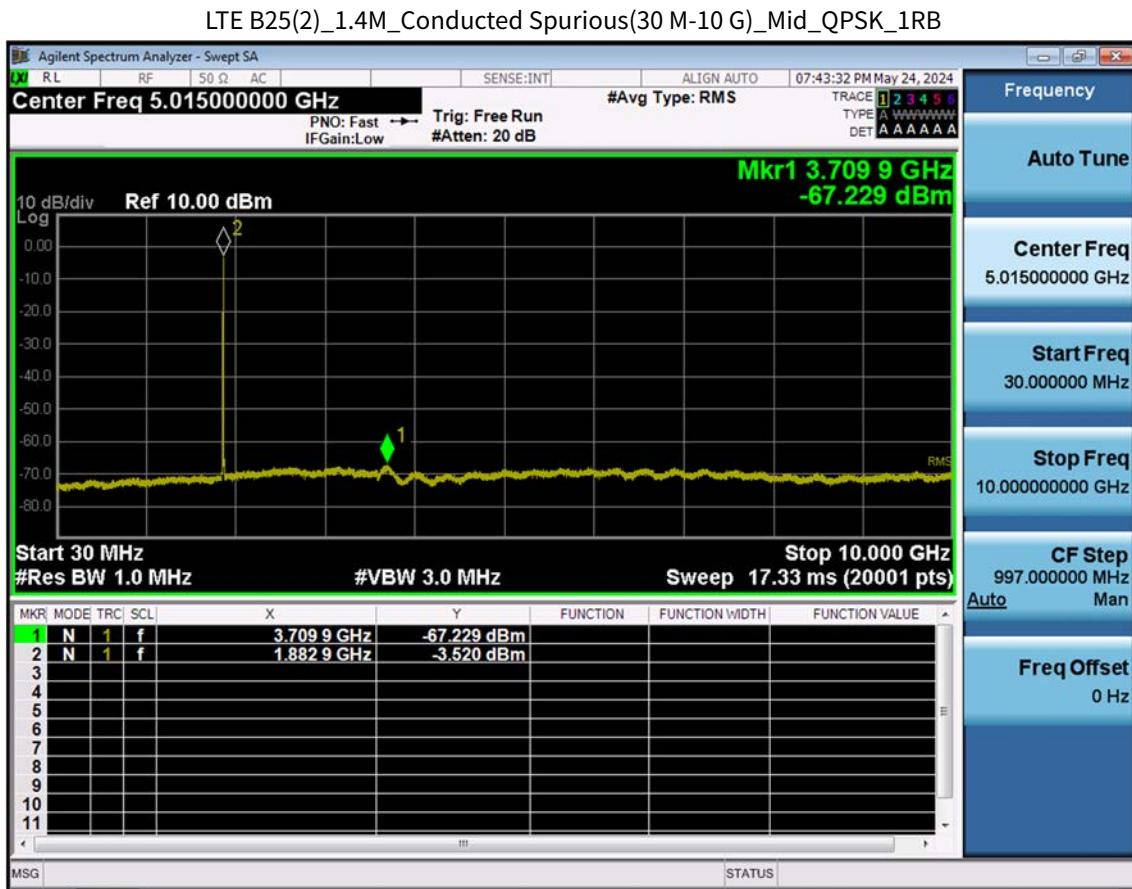
LTE B25(2)_20 M_OBW_Mid_64QAM_FullRB

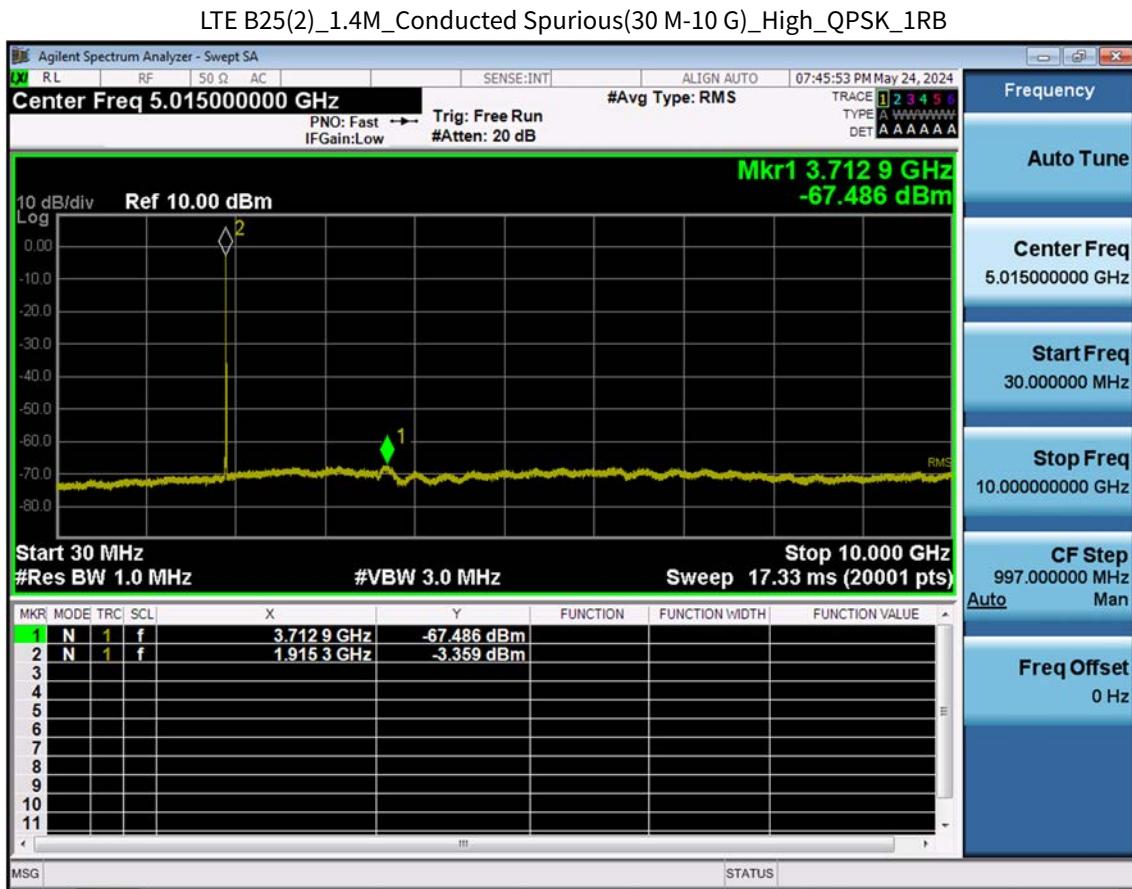


LTE B25(2)_20 M_OBW_Mid_256QAM_FullRB









LTE B25(2)_3 M_Conducted Spurious(30 M-10 G)_Low_QPSK_1RB

